

TEST REPORT

FCC LTE B2 Test for SM-A266M/DS
Certification

APPLICANT
SAMSUNG Electronics Co., Ltd.

REPORT NO.
HCT-RF-2501-FC038

DATE OF ISSUE
January 22, 2025

Tested by
Jae Ryang Do



Technical Manager
Jong Seok Lee



HCT CO., LTD.
Bongjai Huh
BongJai Huh / CEO

**HCT CO.,LTD.**

2-6, 73, 74, Seoicheon-ro 578beon-gil, Majang-myeon, Icheon-si, Gyeonggi-do, Republic of Korea
Tel. +82 31 645 6300 Fax. +82 31 645 6401

TEST REPORT

REPORT NO.

HCT-RF-2501-FC038

DATE OF ISSUE

January 22, 2025

Additional Model

SM-A266M

Applicant**SAMSUNG Electronics Co., Ltd.**

129, Samsung-ro, Yeongtong-gu, Suwon-si, Gyeonggi-do, 16677, Rep. of Korea

Product Name

Mobile Phone

Model Name

SM-A266M/DS

Date of Test

December 09, 2024~ January 17, 2025

FCC ID

A3LSMA266M

Location of Test

☒ Permanent Testing Lab ☐ On Site Testing

(Address: 74, Seoicheon-ro 578beon-gil, Majang-myeon, Icheon-si, Gyeonggi-do, Republic of Korea)

FCC Classification:

PCS Licensed Transmitter Held to Ear (PCE)

FCC Rule Part(s):

§ 24

Test Results

PASS

REVISION HISTORY

The revision history for this test report is shown in table.

Revision No.	Date of Issue	Description
0	January 22, 2025	Initial Release

Notice

Content

The measurements shown in this report were made in accordance with the procedures specified in CFR47 section § 2.947. I assume full responsibility for the accuracy and completeness of these measurements, and for the qualifications of all persons taking them.

HCT CO., LTD. Certifies that no party to this application has subject to a denial of Federal benefits that includes FCC benefits pursuant to section 5301 of the Anti-Drug Abuse Act of 1998, 21 U.S.C. 853(a)

The results shown in this test report only apply to the sample(s), as received, provided by the applicant, unless otherwise stated.

The test results have only been applied with the test methods required by the standard(s).

The laboratory is not accredited for the test results marked *.

Information provided by the applicant is marked **.

Test results provided by external providers are marked ***.

When confirmation of authenticity of this test report is required, please contact www.hct.co.kr

The test results in this test report are not associated with the ((KS Q) ISO/IEC 17025) accreditation by KOLAS (Korea Laboratory Accreditation Scheme) / A2LA (American Association for Laboratory Accreditation) that are under the ILAC (International Laboratory Accreditation Cooperation) Mutual Recognition Agreement (MRA).

CONTENTS

1. GENERAL INFORMATION.....	5
1.1. MAXIMUM OUTPUT POWER.....	6
2. INTRODUCTION.....	8
2.1. DESCRIPTION OF EUT.....	8
2.2. MEASURING INSTRUMENT CALIBRATION	8
2.3. TEST FACILITY.....	8
3. DESCRIPTION OF TESTS	9
3.1 TEST PROCEDURE	9
3.2 RADIATED POWER.....	10
3.3 RADIATED SPURIOUS EMISSIONS	11
3.4 PEAK- TO- AVERAGE RATIO	12
3.5 OCCUPIED BANDWIDTH.....	14
3.6 SPURIOUS AND HARMONIC EMISSIONS AT ANTENNA TERMINAL	15
3.7 BAND EDGE.....	16
3.8 FREQUENCY STABILITY / VARIATION OF AMBIENT TEMPERATURE	18
3.8 FREQUENCY STABILITY / VARIATION OF AMBIENT TEMPERATURE	19
3.9 WORST CASE(RADIATED TEST)	20
3.10 WORST CASE(CONDUCTED TEST)	21
4. LIST OF TEST EQUIPMENT	22
5. MEASUREMENT UNCERTAINTY	23
6. SUMMARY OF TEST RESULTS	24
7. SAMPLE CALCULATION	25
8. TEST DATA(Main 2 ANT).....	27
8.1 EQUIVALENT ISOTROPIC RADIATED POWER	27
8.2 RADIATED SPURIOUS EMISSIONS	30
8.3 PEAK-TO-AVERAGE RATIO	31
8.4 OCCUPIED BANDWIDTH	32
8.5 CONDUCTED SPURIOUS EMISSIONS.....	33
8.6 BAND EDGE.....	33
8.7 FREQUENCY STABILITY / VARIATION OF AMBIENT TEMPERATURE	34
9. TEST DATA(Sub 2 ANT)	52
9.1 EQUIVALENT ISOTROPIC RADIATED POWER	52
9.2 RADIATED SPURIOUS EMISSIONS	55
9.3 PEAK-TO-AVERAGE RATIO	56
9.4 OCCUPIED BANDWIDTH	57
9.5 CONDUCTED SPURIOUS EMISSIONS.....	58
9.6 BAND EDGE.....	58
9.7 FREQUENCY STABILITY / VARIATION OF AMBIENT TEMPERATURE	59
9.9 UPLINK CARRIER AGGREGATION	77
9.9.1 RADIATED SPURIOUS EMISSIONS	77
10. TEST PLOTS(Main 2 ANT).....	78
11. TEST PLOTS(Sub 2 ANT)	199
12. ANNEX A_ TEST SETUP PHOTO.....	320

MEASUREMENT REPORT

1. GENERAL INFORMATION

Applicant Name:	SAMSUNG Electronics Co., Ltd.
Address:	129, Samsung-ro, Yeongtong-gu, Suwon-si, Gyeonggi-do, 16677, Rep. of Korea
FCC ID:	A3LSMA266M
Application Type:	Certification
FCC Classification:	PCS Licensed Transmitter Held to Ear (PCE)
FCC Rule Part(s):	§ 24
EUT Type:	Mobile phone
Model(s):	SM-A266M/DS
Additional Model(s)	SM-A266M
Tx Frequency:	1850.7 MHz – 1909.3 MHz (LTE – Band2 (1.4 MHz)) 1851.5 MHz – 1908.5 MHz (LTE – Band2 (3 MHz)) 1852.5 MHz – 1907.5 MHz (LTE – Band2 (5 MHz)) 1855.0 MHz – 1905.0 MHz (LTE – Band2 (10 MHz)) 1857.5 MHz – 1902.5 MHz (LTE – Band2 (15 MHz)) 1860.0 MHz – 1900.0 MHz (LTE – Band2 (20 MHz))
Date(s) of Tests:	December 09, 2024~ January 17, 2025
Serial number:	Radiated : R3CXB0V4KLT Conducted : 855de5dce5297ece(Main 2), 8b3223c57d537ece(Sub 2)

1.1. MAXIMUM OUTPUT POWER

Main 2 ANT

Mode (MHz)	Tx Frequency (MHz)	Emission Designator	Modulation	EIRP	
				Max. Power (W)	Max. Power (dBm)
LTE – Band2 (1.4)	1850.7 - 1909.3	1M10G7D	QPSK	0.305	24.85
		1M10W7D	16QAM	0.271	24.33
		1M11W7D	64QAM	0.219	23.41
		1M10W7D	256QAM	0.109	20.39
LTE – Band2 (3)	1851.5 - 1908.5	2M71G7D	QPSK	0.308	24.88
		2M72W7D	16QAM	0.271	24.33
		2M71W7D	64QAM	0.223	23.49
		2M71W7D	256QAM	0.112	20.51
LTE – Band2 (5)	1852.5 - 1907.5	4M54G7D	QPSK	0.312	24.94
		4M52W7D	16QAM	0.285	24.55
		4M53W7D	64QAM	0.228	23.57
		4M51W7D	256QAM	0.114	20.55
LTE – Band2 (10)	1855.0 - 1905.0	9M01G7D	QPSK	0.303	24.81
		9M04W7D	16QAM	0.273	24.36
		9M01W7D	64QAM	0.214	23.31
		9M01W7D	256QAM	0.115	20.61
LTE – Band2 (15)	1857.5 - 1902.5	13M5G7D	QPSK	0.309	24.90
		13M5W7D	16QAM	0.256	24.08
		13M5W7D	64QAM	0.206	23.14
		13M5W7D	256QAM	0.109	20.39
LTE – Band2 (20)	1860.0 - 1900.0	18M0G7D	QPSK	0.290	24.63
		18M0W7D	16QAM	0.269	24.30
		18M0W7D	64QAM	0.217	23.37
		18M0W7D	256QAM	0.104	20.15

Sub 2 ANT

Mode (MHz)	Tx Frequency (MHz)	Emission Designator	Modulation	EIRP	
				Max. Power (W)	Max. Power (dBm)
LTE – Band2 (1.4)	1850.7 - 1909.3	1M10G7D	QPSK	0.166	22.19
		1M10W7D	16QAM	0.136	21.32
		1M10W7D	64QAM	0.107	20.30
		1M10W7D	256QAM	0.053	17.27
LTE – Band2 (3)	1851.5 - 1908.5	2M72G7D	QPSK	0.163	22.13
		2M71W7D	16QAM	0.136	21.35
		2M71W7D	64QAM	0.106	20.25
		2M71W7D	256QAM	0.054	17.32
LTE – Band2 (5)	1852.5 - 1907.5	4M54G7D	QPSK	0.168	22.25
		4M50W7D	16QAM	0.137	21.36
		4M51W7D	64QAM	0.111	20.46
		4M54W7D	256QAM	0.055	17.41
LTE – Band2 (10)	1855.0 - 1905.0	9M03G7D	QPSK	0.163	22.11
		9M03W7D	16QAM	0.135	21.30
		9M02W7D	64QAM	0.109	20.38
		9M03W7D	256QAM	0.054	17.31
LTE – Band2 (15)	1857.5 - 1902.5	13M5G7D	QPSK	0.165	22.18
		13M5W7D	16QAM	0.138	21.39
		13M5W7D	64QAM	0.109	20.36
		13M5W7D	256QAM	0.055	17.39
LTE – Band2 (20)	1860.0 - 1900.0	18M0G7D	QPSK	0.156	21.94
		18M0W7D	16QAM	0.130	21.15
		18M0W7D	64QAM	0.103	20.11
		18M0W7D	256QAM	0.052	17.14

2. INTRODUCTION

2.1. DESCRIPTION OF EUT

Please refer to the [2G3G] Test Report.

2.2. MEASURING INSTRUMENT CALIBRATION

The measuring equipment, which was utilized in performing the tests documented herein, has been calibrated in accordance with the manufacturer's recommendations for utilizing calibration equipment, which is traceable to recognized national standards.

2.3. TEST FACILITY

The Fully-anechoic chamber and conducted measurement facility used to collect the radiated data are located at the **74, Seoicheon-ro 578beon-gil, Majang-myeon, Icheon-si, Gyeonggi-do, Republic of Korea**

3. DESCRIPTION OF TESTS

3.1 TEST PROCEDURE

Test Description	Test Procedure Used
Occupied Bandwidth	- KDB 971168 D01 v03r01 – Section 4.3 - ANSI C63.26-2015 – Section 5.4.4
Band Edge	- KDB 971168 D01 v03r01 – Section 6.0 - ANSI C63.26-2015 – Section 5.7
Spurious and Harmonic Emissions at Antenna Terminal	- KDB 971168 D01 v03r01 – Section 6.0 - ANSI C63.26-2015 – Section 5.7
Conducted Output Power	- N/A (See SAR Report)
Peak- to- Average Ratio	- KDB 971168 D01 v03r01 – Section 5.7 - ANSI C63.26-2015 – Section 5.2.3.4
Frequency stability	- ANSI C63.26-2015 – Section 5.6
Radiated Power	- ANSI C63.26-2015 – Section 5.2.4.4 - KDB 971168 D01 v03r01 – Section 5.8
Radiated Spurious and Harmonic Emissions	- ANSI C63.26-2015 – Section 5.5.3 - KDB 971168 D01 v03r01 – Section 5.8

3.2 RADIATED POWER

Test Overview

Radiated tests are performed in the Fully-anechoic chamber.

The equipment under test is placed on a non-conductive table 3-meters away from the receive antenna.

Test Settings

1. Radiated power measurements are performed using the signal analyzer's "channel power" measurement capability for signals with continuous operation.
2. RBW = 1 – 5 % of the expected OBW, not to exceed 1 MHz
3. VBW $\geq$ 3 x RBW
4. Span = 1.5 times the OBW
5. No. of sweep points $>$ 2 x span / RBW
6. Detector = RMS
7. Trigger is set to "free run" for signals with continuous operation with the sweep times set to "auto".
8. The integration bandwidth was roughly set equal to the measured OBW of the signal for signals with continuous operation.
9. Trace mode = trace averaging (RMS) over 100 sweeps
10. The trace was allowed to stabilize

Test Note

1. The turntable is rotated through 360 degrees, and the receiving antenna scans in order to determine the level of the maximized emission.
2. A half wave dipole is then substituted in place of the EUT. For emissions above 1 GHz, a horn antenna is substituted in place of the EUT. The substitute antenna is driven by a signal generator and the previously recorded signal was duplicated.

The power is calculated by the following formula;

$$P_d \text{ (dBm)} = P_g \text{ (dBm)} - \text{cable loss (dB)} + \text{antenna gain (dB)}$$

Where: P_d is the dipole equivalent power and P_g is the generator output power into the substitution antenna.

3. The maximum value is calculated by adding the forward power to the calibrated source plus its appropriate gain value.
These steps are repeated with the receiving antenna in both vertical and horizontal polarization. the difference between the gain of the horn and an isotropic antenna are taken into consideration
4. The EUT was tested in three orthogonal planes(X, Y, Z) and in all possible test configurations and positioning.
5. All measurements are performed as RMS average measurements while the EUT is operating at its maximum duty cycle, at maximum power, and at the appropriate frequencies.

3.3 RADIATED SPURIOUS EMISSIONS

Test Overview

Radiated tests are performed in the Fully-anechoic chamber.

Radiated Spurious Emission Measurements at 3 meters by Substitution Method.

Test Settings

1. RBW = 100 kHz for emissions below 1 GHz and 1 MHz for emissions above 1 GHz
2. VBW $\geq 3 \times$ RBW
3. Span = 1.5 times the OBW
4. No. of sweep points $> 2 \times$ span / RBW
5. Detector = Peak
6. Trace mode = Max Hold
7. The trace was allowed to stabilize
8. Test channel : Low/ Middle/ High
9. Frequency range : We are performed all frequency to 10th harmonics from 9 kHz.

Test Note

1. Measurements value show only up to 3 maximum emissions noted, or would be lesser if no specific emissions from the EUT are recorded (ie: margin > 20 dB from the applicable limit) and considered that's already beyond the background noise floor.
2. The EUT was tested in three orthogonal planes(X, Y, Z) and in all possible test configurations and positioning.
The worst case emissions are reported with the EUT positioning, modulations, RB sizes and offsets, and channel bandwidth configurations shown in the test data
3. For spurious emissions above 1 GHz, a horn antenna is substituted in place of the EUT. The substitute antenna is driven by a signal generator and the previously recorded signal was duplicated.

The spurious emissions is calculated by the following formula;

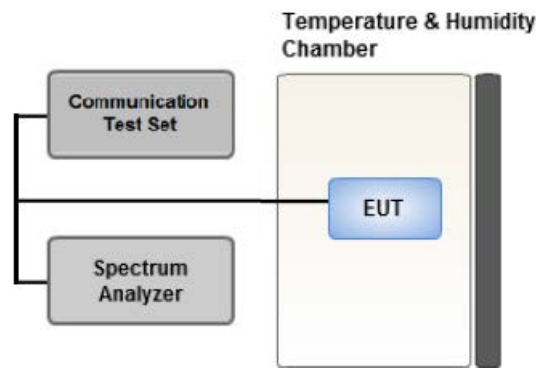
$$\text{Result}_{(\text{dBm})} = P_g_{(\text{dBm})} - \text{cable loss}_{(\text{dB})} + \text{antenna gain}_{(\text{dBi})}$$

Where: P_g is the generator output power into the substitution antenna.

If the fundamental frequency is below 1 GHz, RF output power has been converted to EIRP.

$$\text{EIRP}_{(\text{dBm})} = \text{ERP}_{(\text{dBm})} + 2.15$$

3.4 PEAK- TO- AVERAGE RATIO



Test setup

① CCDF Procedure for PAPR

Test Settings

1. Set resolution/measurement bandwidth $\geq$ signal's occupied bandwidth;
2. Set the number of counts to a value that stabilizes the measured CCDF curve;
3. Set the measurement interval as follows:
 - .- for continuous transmissions, set to 1 ms,
 - .- or burst transmissions, employ an external trigger that is synchronized with the EUT burst timing sequence, or use the internal burst trigger with a trigger level that allows the burst to stabilize and set the measurement interval to a time that is less than or equal to the burst duration.
4. Record the maximum PAPR level associated with a probability of 0.1 %.

② Alternate Procedure for PAPR

Use one of the procedures presented in 5.2(ANSI C63.26-2015) to measure the total peak power and record as P_{Pk} .

Use one of the applicable procedures presented 5.2(ANSI C63.26-2015) to measure the total average power and record as P_{Avg} . Determine the P.A.R. from:

$$P.A.R. (dB) = P_{Pk} (dBm) - P_{Avg} (dBm) \quad (P_{Avg} = \text{Average Power} + \text{Duty cycle Factor})$$

Test Settings(Peak Power)

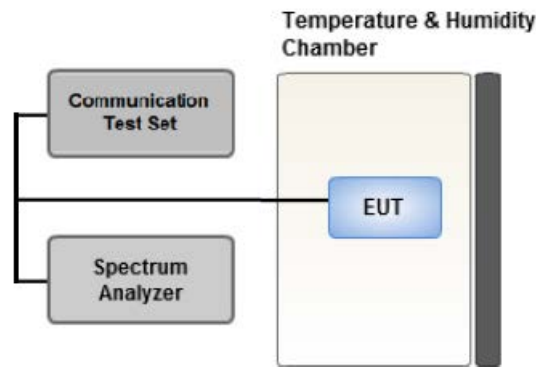
The measurement instrument must have a RBW that is greater than or equal to the OBW of the signal to be measured and a VBW $\geq 3 \times$ RBW.

1. Set the RBW $\geq$ OBW.
2. Set VBW $\geq 3 \times$ RBW.
3. Set span $\geq 2 \times$ OBW.
4. Sweep time $\geq 10 \times$ (number of points in sweep) $\times$ (transmission symbol period).
5. Detector = peak.
6. Trace mode = max hold.
7. Allow trace to fully stabilize.
8. Use the peak marker function to determine the peak amplitude level.

Test Settings(Average Power)

1. Set span to $2 \times$ to $3 \times$ the OBW.
2. Set RBW $\geq$ OBW.
3. Set VBW $\geq 3 \times$ RBW.
4. Set number of measurement points in sweep $\geq 2 \times$ span / RBW.
5. Sweep time:
Set $\geq [10 \times (\text{number of points in sweep}) \times (\text{transmission period})]$ for single sweep (automation-compatible) measurement. The transmission period is the (on + off) time.
6. Detector = power averaging (rms).
7. Set sweep trigger to "free run."
8. Trace average at least 100 traces in power averaging (rms) mode if sweep is set to auto-couple. (To accurately determine the average power over the on and off period of the transmitter, it can be necessary to increase the number of traces to be averaged above 100 or, if using a manually configured sweep time, increase the sweep time.)
9. Use the peak marker function to determine the maximum amplitude level.
10. Add $[10 \log (1/\text{duty cycle})]$ to the measured maximum power level to compute the average power during continuous transmission. For example, add $[10 \log (1/0.25)] = 6 \text{ dB}$ if the duty cycle is a constant 25 %.

3.5 OCCUPIED BANDWIDTH.



Test setup

The width of a frequency band such that, below the lower and above the upper frequency limits, the mean powers emitted are each equal to a specified percentage 0.5 % of the total mean power of a given emission.

The EUT makes a call to the communication simulator.

The conducted occupied bandwidth used the power splitter via EUT RF power connector between simulation base station and spectrum analyzer.

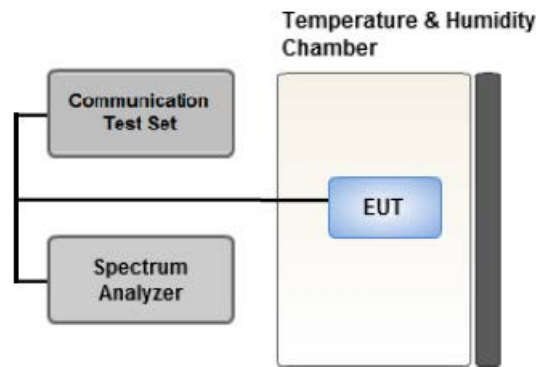
The communication simulator station system controlled a EUT to export maximum output power under transmission mode and specific channel frequency.

Use OBW measurement function of Spectrum analyzer to measure 99 % occupied bandwidth

Test Settings

1. The signal analyzer's automatic bandwidth measurement capability was used to perform the 99 % occupied bandwidth and the 26 dB bandwidth. The bandwidth measurement was not influenced by any intermediate power nulls in the fundamental emission.
2. RBW = 1 – 5 % of the expected OBW
3. VBW $\geq$ 3 x RBW
4. Detector = Peak
5. Trace mode = max hold
6. Sweep = auto couple
7. The trace was allowed to stabilize
8. If necessary, steps 2 – 7 were repeated after changing the RBW such that it would be within 1 – 5 % of the 99 % occupied bandwidth observed in Step 7

3.6 SPURIOUS AND HARMONIC EMISSIONS AT ANTENNA TERMINAL



Test setup

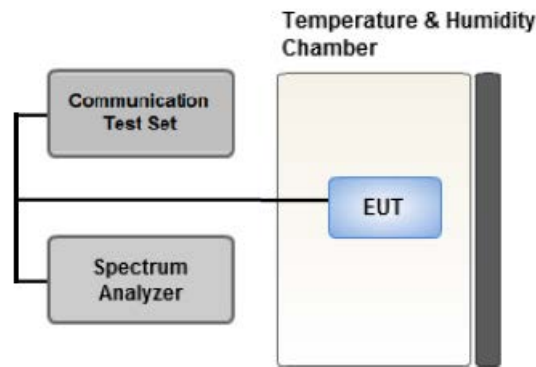
Test Overview

The level of the carrier and the various conducted spurious and harmonic frequencies is measured by means of a calibrated spectrum analyzer. The spectrum is scanned from the lowest frequency generated in the equipment up to a frequency including its 10th harmonic. All out of band emissions are measured with a spectrum analyzer connected to the antenna terminal of the EUT while the EUT is operating at its maximum duty cycle, at maximum power, and at the appropriate frequencies. All data rates were investigated to determine the worst case configuration. All modes of operation were investigated and the worst case configuration results are reported in this section.

Test Settings

1. RBW = 1 MHz
2. VBW $\geq$ 3 MHz
3. Detector = Peak
4. Trace Mode = Max Hold
5. Sweep time = auto
6. Number of points in sweep $\geq$ 2 x Span / RBW

3.7 BAND EDGE



Test setup

Test Overview

All out of band emissions are measured with a spectrum analyzer connected to the antenna terminal of the EUT while the EUT is operating at its maximum duty cycle, at maximum power, and at the appropriate frequencies. All data rates were investigated to determine the worst case configuration. All modes of operation were investigated and the worst case configuration results are reported in this section.

Test Settings

1. Start and stop frequency were set such that the band edge would be placed in the center of the plot
2. Span was set large enough so as to capture all out of band emissions near the band edge
3. RBW > 1 % of the emission bandwidth
4. VBW > 3 x RBW
5. Detector = RMS
6. Number of sweep points $\geq 2 \times \text{Span/RBW}$
7. Trace mode = trace average
8. Sweep time = auto couple
9. The trace was allowed to stabilize

Test Notes

According to FCC 22.917, 24.238, 27.53 specified that power of any emission outside of The authorized operating frequency ranges must be attenuated below the transmitting power (P) by a factor of at least $43 + 10 \log(P)$ dB. In

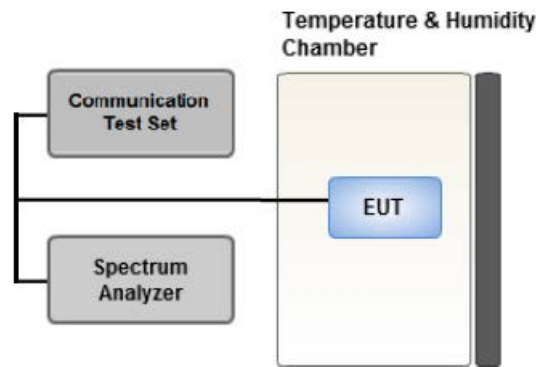
the 1 MHz bands immediately outside and adjacent to the frequency block a resolution bandwidth of at least one percent of the emission bandwidth of the fundamental emission of the transmitter may be employed.

All measurements were done at 2 channels(low and high operational frequency range.)

The band edge measurement used the power splitter via EUT RF power connector between simulation base station and spectrum analyzer.

Where Margin < 1 dB the emission level is either corrected by $10 \log(1 \text{ MHz/ RB})$ or the emission is integrated over a 1 MHz bandwidth to determine the final result. When using the integration method the integration window is either centered on the emission or, for emissions at the band edge, centered by an offset of 500 kHz from the block edge so that the integration window is the 1 MHz adjacent to the block edge.

3.8 FREQUENCY STABILITY / VARIATION OF AMBIENT TEMPERATURE



Test setup

Test Overview

Frequency stability testing is performed in accordance with the guidelines of ANSI C63.26-2015.

The frequency stability of the transmitter is measured by:

1. Temperature:

The temperature is varied from -30 °C to +50 °C in 10 °C increments using an environmental chamber.

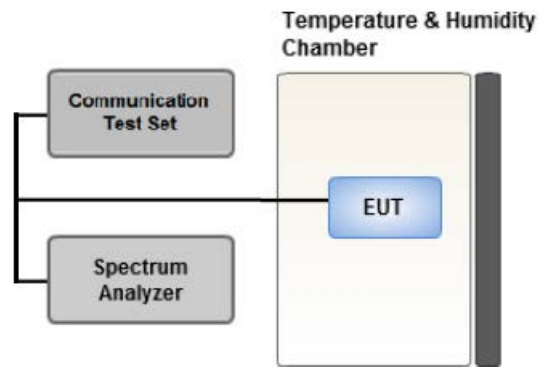
2. Primary Supply Voltage:

- Unless otherwise specified, vary primary supply voltage from 85 % to 115 % of the nominal value for other than hand carried battery equipment.
- For hand carried, battery powered equipment, reduce the primary ac or dc supply voltage to the battery operating end point, which shall be specified by the manufacturer.

Test Settings

1. The carrier frequency of the transmitter is measured at room temperature (20 °C to provide a reference).
2. The equipment is turned on in a “standby” condition for fifteen minutes before applying power to the transmitter.
Measurement of the carrier frequency of the transmitter is made within one minute after applying power to the transmitter.
3. Frequency measurements are made at 10 °C intervals ranging from -30 °C to +50 °C. A period of at least one half-hour is provided to allow stabilization of the equipment at each temperature level.

3.8 FREQUENCY STABILITY / VARIATION OF AMBIENT TEMPERATURE



Test setup

Test Overview

Frequency stability testing is performed in accordance with the guidelines of ANSI C63.26-2015.

The frequency stability of the transmitter is measured by:

1. Temperature:

The temperature is varied from -30 °C to +50 °C in 10 °C increments using an environmental chamber.

2. Primary Supply Voltage:

- Unless otherwise specified, vary primary supply voltage from 85 % to 115 % of the nominal value for other than hand carried battery equipment.
- For hand carried, battery powered equipment, reduce the primary ac or dc supply voltage to the battery operating end point, which shall be specified by the manufacturer.

Test Settings

1. The carrier frequency of the transmitter is measured at room temperature (20 °C to provide a reference).
2. The equipment is turned on in a “standby” condition for fifteen minutes before applying power to the transmitter.
Measurement of the carrier frequency of the transmitter is made within one minute after applying power to the transmitter.
3. Frequency measurements are made at 10 °C intervals ranging from -30 °C to +50 °C. A period of at least one half-hour is provided to allow stabilization of the equipment at each temperature level.

3.9 WORST CASE(RADIATED TEST)

- The EUT was tested in three orthogonal planes(X, Y, Z) and in all possible test configurations and positioning.
- All modes of operation were investigated and the worst case configuration results are reported.
Mode : Stand alone, Stand alone + External accessories (Earphone, AC adapter, etc.)
Worst case : Stand alone
- We were performed the RSE test in condition of co-location.
Mode : Stand alone, Simultaneous transmission scenarios
Worst case : Stand alone
- In the case of radiated spurious emissions, all bandwidth of operation was investigated and the worst case bandwidth results are reported. (Worst case : 5 MHz)
- The worst case is reported with the EUT positioning, modulations, and paging service configurations shown in the test data.
- Please refer to the table below.
- SM-A266M/DS & additional models were tested and the worst case results are reported.
(Worst case : SM-A266M/DS)

[Main 2 ANT Worst case]

Test Description	Modulation	RB size	RB offset	Axis
Effective Isotropic Radiated Power	QPSK, 16QAM, 64QAM, 256QAM	See Section 8.1		Z
Radiated Spurious and Harmonic Emissions	QPSK	See Section 8.2		Z

[Sub 2 ANT Worst case]

Test Description	Modulation	RB size	RB offset	Axis
Effective Isotropic Radiated Power	QPSK, 16QAM, 64QAM, 256QAM	See Section 9.1		Z
Radiated Spurious and Harmonic Emissions	QPSK	See Section 9.2		Z

3.10 WORST CASE(CONDUCTED TEST)

- All modes of operation were investigated and the worst case configuration results are reported.
 - SM-A266M/DS & additional models were tested and the worst case results are reported.
- (Worst case : SM-A266M/DS)

[Worst case]

Test Description	Modulation	Bandwidth (MHz)	Frequency	RB size	RB offset
Occupied Bandwidth	QPSK, 16QAM, 64QAM, 256QAM	1.4, 3, 5, 10, 15, 20	Mid	Full RB	0
Peak-To-Average Ratio	QPSK, 16QAM, 64QAM, 256QAM	1.4, 3, 5, 10, 15, 20	Mid	Full RB	0
Band Edge	QPSK	1.4	Low	1	0
			High	1	5
		3	Low	1	0
			High	1	14
		5	Low	1	0
			High	1	24
		10	Low	1	0
			High	1	49
		15	Low	1	0
			High	1	74
		20	Low	1	0
			High	1	99
		1.4, 3, 5, 10, 15, 20	Low, High	Full RB	0
Spurious and Harmonic Emissions at Antenna Terminal	QPSK	1.4, 3, 5, 10, 15, 20	Low, Mid, High	1	0

4. LIST OF TEST EQUIPMENT

Equipment	Model	Manufacturer	Serial No.	Due to Calibration	Calibration Interval
RF Switching System	Switch box(1.2 G HPF+LNA)	HCT CO., LTD.,	F1L1	11/11/2025	Annual
RF Switching System	Switch box(3.3 G HPF+LNA)	HCT CO., LTD.,	F1L2	11/11/2025	Annual
RF Switching System	Switch box(LNA)	HCT CO., LTD.,	F1L4	11/11/2025	Annual
RF Switching System	Switch box(6 G HPF+LNA)	HCT CO., LTD.,	F1L7	11/11/2025	Annual
Power Splitter(DC ~ 26.5 GHz)	11667B	Hewlett Packard	5001	04/17/2025	Annual
DC Power Supply	E3632A	Agilent	MY40010147	08/06/2025	Annual
Dipole Antenna	UHAP	Schwarzbeck	01274	03/10/2026	Biennial
Dipole Antenna	UHAP	Schwarzbeck	01288	08/07/2026	Biennial
Chamber	SU-642	ESPEC	93008124	02/19/2025	Annual
Horn Antenna(1 ~ 18 GHz)	BBHA 9120D	Schwarzbeck	147	08/17/2025	Biennial
Horn Antenna(1 ~ 18 GHz)	BBHA 9120D	Schwarzbeck	9120D-1298	09/11/2025	Biennial
Horn Antenna(15 ~ 40 GHz)	BBHA 9170	Schwarzbeck	BBHA9170342	09/20/2026	Biennial
Horn Antenna(15 ~ 40 GHz)	BBHA 9170	Schwarzbeck	BBHA9170124	03/28/2025	Biennial
Signal Analyzer(10 Hz ~ 26.5 GHz)	N9020A	Agilent	MY52090906	04/19/2025	Annual
ATTENUATOR(20 dB)	8493C	Hewlett Packard	17280	04/17/2025	Annual
Spectrum Analyzer(10 Hz ~ 40 GHz)	FSV40	REOHDE & SCHWARZ	100931	08/06/2025	Annual
Base Station	8960 (E5515C)	Agilent	MY48360800	08/05/2025	Annual
Loop Antenna(9 kHz ~ 30 MHz)	FMZB1513	Schwarzbeck	1513-333	03/07/2026	Biennial
Trilog Broadband Antenna	VULB9168	Schwarzbeck	895	08/28/2026	Biennial
Trilog Broadband Antenna	VULB9168	Schwarzbeck	1135	08/19/2026	Biennial
Wideband Radio Communication Tester	MT8821C	Anritsu Corp.	6262094331	11/13/2025	Annual
Wideband Radio Communication Tester	MT8820C	Anritsu Corp.	6201026545	11/20/2025	Annual
SIGNAL GENERATOR (100 kHz ~ 40 GHz)	SMB100A	REOHDE & SCHWARZ	177633	07/26/2025	Annual
Signal Analyzer(5 Hz ~ 40.0 GHz)	N9030B	KEYSIGHT	MY55480167	05/17/2025	Annual
Radio Communication Test Station	MT8000A	Anritsu Corp.	6272613402	08/28/2025	Annual
FCC LTE Mobile Conducted RF Automation Test Software	-	HCT CO., LTD.,	-	-	-

Note:

- Equipment listed above that has a calibration due date during the testing period, the testing is completed before equipment expiration date.
- Especially, all antenna for measurement is calibrated in accordance with the requirements of C63.5 (Version : 2017).

5. MEASUREMENT UNCERTAINTY

The measurement uncertainties shown below were calculated in accordance with the requirements of ANSI C63.4:2014.

All measurement uncertainty values are shown with a coverage factor of $k=2$ to indicate a 95 % level of confidence. The measurement data shown herein meets or exceeds the U_{CISPR} measurement uncertainty values specified in CISPR 16-4-2 and, thus, can be compared directly to specified limits to determine compliance.

Parameter	Expanded Uncertainty ($\pm$ kHz)
Occupied Bandwidth	95 (Confidence level about 95 %, $k=2$)
Frequency stability	28 (Confidence level about 95 %, $k=2$)

Parameter	Expanded Uncertainty ($\pm$ dB)
Block Edge	0.70 (Confidence level about 95 %, $k=2$)
Conducted Spurious Emissions	1.18 (Confidence level about 95 %, $k=2$)
Peak- to- Average Ratio	0.68 (Confidence level about 95 %, $k=2$)
Radiated Power	4.74 (Confidence level about 95 %, $k=2$)
Radiated Disturbance (9 kHz ~ 30 MHz)	4.36 (Confidence level about 95 %, $k=2$)
Radiated Disturbance (30 MHz ~ 1 GHz)	5.70 (Confidence level about 95 %, $k=2$)
Radiated Disturbance (1 GHz ~ 18 GHz)	5.52 (Confidence level about 95 %, $k=2$)
Radiated Disturbance (18 GHz ~ 40 GHz)	5.66 (Confidence level about 95 %, $k=2$)
Radiated Disturbance (Above 40 GHz)	5.58 (Confidence level about 95 %, $k=2$)

6. SUMMARY OF TEST RESULTS

6.1 Test Condition: Conducted Test

Test Description	FCC Part Section(s)	Test Limit	Test Result
Occupied Bandwidth	§ 2.1049	N/A	PASS
Band Edge / Spurious and Harmonic Emissions at Antenna Terminal.	§ 2.1051, § 24.238(a)	< 43 + 10log10 (P[Watts]) at Band Edge and for all out-of-band emissions	PASS
Conducted Output Power	§ 2.1046	N/A	<u>See Note1</u>
Peak- to- Average Ratio	§ 24.232(d)	< 13 dB	PASS
Frequency stability / variation of ambient temperature	§ 24.235	Emission must remain in band	PASS

Note:

1. See SAR Report

6.2 Test Condition: Radiated Test

Test Description	FCC Part Section(s)	Test Limit	Test Result
Equivalent Isotropic Radiated Power	§ 24.232(c)	< 2 Watts max. EIRP	PASS
Radiated Spurious and Harmonic Emissions	§ 2.1053, § 24.238(a)	< 43 + 10log10 (P[Watts]) for all out-of band emissions	PASS

7. SAMPLE CALCULATION

7.1 ERP Sample Calculation

Ch./ Freq.		Measured Level (dBm)	Substitute Level (dBm)	Ant. Gain (dBd)	C.L	Pol.	ERP	
channel	Freq.(MHz)						W	dBm
128	824.20	-21.37	38.40	-10.61	0.95	H	0.483	26.84

$$\text{ERP} = \text{Substitute LEVEL(dBm)} + \text{Ant. Gain} - \text{CL(Cable Loss)}$$

- 1) The EUT mounted on a non-conductive turntable is 2.5 meter above test site ground level.
- 2) During the test, the turn table is rotated until the maximum signal is found.
- 3) Record the field strength meter's level.
- 4) Replace the EUT with dipole/Horn antenna that is connected to a calibrated signal generator.
- 5) Increase the signal generator output till the field strength meter's level is equal to the item (3).
- 6) The signal generator output level with Ant. Gain and cable loss are the rating of effective radiated power.

7.2 EIRP Sample Calculation

Ch./ Freq.		Measured Level (dBm)	Substitute Level (dBm)	Ant. Gain (dBi)	C.L	Pol.	EIRP	
channel	Freq.(MHz)						W	dBm
20175	1,732.50	-15.75	18.45	9.90	1.76	H	0.456	26.59

$$\text{EIRP} = \text{Substitute LEVEL(dBm)} + \text{Ant. Gain} - \text{CL(Cable Loss)}$$

- 1) The EUT mounted on a non-conductive turntable is 2.5 meter above test site ground level.
- 2) During the test, the turn table is rotated until the maximum signal is found.
- 3) Record the field strength meter's level.
- 4) Replace the EUT with dipole/Horn antenna that is connected to a calibrated signal generator.
- 5) Increase the signal generator output till the field strength meter's level is equal to the item (3).
- 6) The signal generator output level with Ant. Gain and cable loss are the rating of equivalent isotropic radiated power.

7.3. Emission Designator

GSM Emission Designator

Emission Designator = 249KGXW

GSM BW = 249 kHz

G = Phase Modulation

X = Cases not otherwise covered

W = Combination (Audio/Data)

EDGE Emission Designator

Emission Designator = 249KG7W

GSM BW = 249 kHz

G = Phase Modulation

7 = Quantized/Digital Info

W = Combination (Audio/Data)

WCDMA Emission Designator

Emission Designator = 4M17F9W

WCDMA BW = 4.17 MHz

F = Frequency Modulation

9 = Composite Digital Info

W = Combination (Audio/Data)

QPSK Modulation

Emission Designator = 4M48G7D

LTE BW = 4.48 MHz

G = Phase Modulation

7 = Quantized/Digital Info

D = Data transmission; telemetry; telecommand

QAM Modulation

Emission Designator = 4M48W7D

LTE BW = 4.48 MHz

W = Amplitude/Angle Modulated

7 = Quantized/Digital Info

D = Data transmission; telemetry; telecommand

8. TEST DATA(Main 2 ANT)

8.1 EQUIVALENT ISOTROPIC RADIATED POWER

Freq (MHz)	Mod/ Bandwidth	Modulation	Measured	Substitute	Ant. Gain (dBi)	C.L	Pol	Limit	EIRP		RB	
			Level (dBm)	Level (dBm)				W	W	dBm	Size	Offset
1850.7	LTE B2/ 1.4 MHz	QPSK	-19.48	15.04	10.40	2.07	V	< 2.00	0.217	23.37	1	5
		16-QAM	-20.27	14.25	10.40	2.07	V		0.181	22.58		
		64-QAM	-21.29	13.23	10.40	2.07	V		0.143	21.56		
		256-QAM	-24.26	10.26	10.40	2.07	V		0.072	18.59		
1880.0		QPSK	-18.29	16.66	10.40	2.21	V		0.305	24.85	1	5
		16-QAM	-19.13	15.82	10.40	2.21	V		0.252	24.01		
		64-QAM	-20.10	14.85	10.40	2.21	V		0.201	23.04		
		256-QAM	-23.09	11.86	10.40	2.21	V		0.101	20.05		
1909.3		QPSK	-18.35	16.59	10.40	2.17	V		0.303	24.82	1	5
		16-QAM	-18.84	16.10	10.40	2.17	V		0.271	24.33		
		64-QAM	-19.76	15.18	10.40	2.17	V		0.219	23.41		
		256-QAM	-22.78	12.16	10.40	2.17	V		0.109	20.39		

Freq (MHz)	Mod/ Bandwidth	Modulation	Measured	Substitute	Ant. Gain (dBi)	C.L	Pol	Limit	EIRP		RB	
			Level (dBm)	Level (dBm)				W	W	dBm	Size	Offset
1851.5	LTE B2/ 3 MHz	QPSK	-19.56	14.96	10.40	2.07	V	< 2.00	0.213	23.29	1	0
		16-QAM	-20.18	14.34	10.40	2.07	V		0.185	22.67		
		64-QAM	-21.24	13.28	10.40	2.07	V		0.145	21.61		
		256-QAM	-24.19	10.33	10.40	2.07	V		0.073	18.66		
1880.0		QPSK	-18.39	16.56	10.40	2.21	V		0.299	24.75	1	14
		16-QAM	-19.05	15.90	10.40	2.21	V		0.256	24.09		
		64-QAM	-20.09	14.86	10.40	2.21	V		0.202	23.05		
		256-QAM	-23.12	11.83	10.40	2.21	V		0.100	20.02		
1908.5		QPSK	-18.29	16.65	10.40	2.17	V		0.308	24.88	1	0
		16-QAM	-18.84	16.10	10.40	2.17	V		0.271	24.33		
		64-QAM	-19.68	15.26	10.40	2.17	V		0.223	23.49		
		256-QAM	-22.66	12.28	10.40	2.17	V		0.112	20.51		

Freq (MHz)	Mod/ Bandwidth	Modulation	Measured Level (dBm)	Substitute Level (dBm)	Ant. Gain (dBi)	C.L	Pol	Limit	EIRP		RB	
								W	W	dBm	Size	Offset
1852.5	LTE B2/ 5 MHz	QPSK	-19.53	15.04	10.40	2.08	V	< 2.00	0.217	23.36	1	24
		16-QAM	-20.22	14.35	10.40	2.08	V		0.185	22.67		
		64-QAM	-21.18	13.39	10.40	2.08	V		0.148	21.71		
		256-QAM	-24.15	10.42	10.40	2.08	V		0.075	18.74		
1880.0		QPSK	-18.51	16.44	10.40	2.21	V		0.290	24.63	1	13
		16-QAM	-19.20	15.75	10.40	2.21	V		0.248	23.94		
		64-QAM	-20.12	14.83	10.40	2.21	V		0.200	23.02		
		256-QAM	-23.05	11.90	10.40	2.21	V		0.102	20.09		
1907.5		QPSK	-18.23	16.71	10.40	2.17	V		0.312	24.94	1	0
		16-QAM	-18.62	16.32	10.40	2.17	V		0.285	24.55		
		64-QAM	-19.60	15.34	10.40	2.17	V		0.228	23.57		
		256-QAM	-22.62	12.32	10.40	2.17	V		0.114	20.55		

Freq (MHz)	Mod/ Bandwidth	Modulation	Measured	Substitute	Ant. Gain (dBi)	C.L	Pol	Limit	EIRP		RB	
			Level (dBm)	Level (dBm)				W	W	dBm	Size	Offset
1855.0	LTE B2/ 10 MHz	QPSK	-19.54	15.03	10.40	2.08	V	< 2.00	0.216	23.35	1	0
		16-QAM	-20.37	14.20	10.40	2.08	V		0.179	22.52		
		64-QAM	-21.21	13.36	10.40	2.08	V		0.147	21.68		
		256-QAM	-24.23	10.34	10.40	2.08	V		0.073	18.66		
1880.0		QPSK	-18.55	16.40	10.40	2.21	V		0.288	24.59	1	25
		16-QAM	-19.12	15.83	10.40	2.21	V		0.252	24.02		
		64-QAM	-20.16	14.79	10.40	2.21	V		0.199	22.98		
		256-QAM	-22.94	12.01	10.40	2.21	V		0.105	20.20		
1905.0		QPSK	-18.32	16.60	10.40	2.19	V		0.303	24.81	1	0
		16-QAM	-18.77	16.15	10.40	2.19	V		0.273	24.36		
		64-QAM	-19.82	15.10	10.40	2.19	V		0.214	23.31		
		256-QAM	-22.52	12.40	10.40	2.19	V		0.115	20.61		

Freq (MHz)	Mod/ Bandwidth	Modulation	Measured Level (dBm)	Substitute Level (dBm)	Ant. Gain (dBi)	C.L	Pol	Limit	EIRP		RB	
								W	W	dBm	Size	Offset
1857.5	LTE B2/ 15 MHz	QPSK	-19.48	15.16	10.40	2.10	V	< 2.00	0.222	23.46	1	74
		16-QAM	-20.42	14.22	10.40	2.10	V		0.179	22.52		
		64-QAM	-21.13	13.51	10.40	2.10	V		0.152	21.81		
		256-QAM	-24.13	10.51	10.40	2.10	V		0.076	18.81		
1880.0		QPSK	-18.54	16.41	10.40	2.21	V		0.288	24.60	1	74
		16-QAM	-19.12	15.83	10.40	2.21	V		0.252	24.02		
		64-QAM	-20.02	14.93	10.40	2.21	V		0.205	23.12		
		256-QAM	-22.88	12.07	10.40	2.21	V		0.106	20.26		
1902.5		QPSK	-18.23	16.69	10.40	2.19	V		0.309	24.90	1	74
		16-QAM	-19.05	15.87	10.40	2.19	V		0.256	24.08		
		64-QAM	-19.99	14.93	10.40	2.19	V		0.206	23.14		
		256-QAM	-22.74	12.18	10.40	2.19	V		0.109	20.39		

Freq (MHz)	Mod/ Bandwidth	Modulation	Measured	Substitute	Ant. Gain (dBi)	C.L	Pol	Limit	EIRP		RB	
			Level (dBm)	Level (dBm)				W	W	dBm	Size	Offset
1860.0	LTE B2/ 20 MHz	QPSK	-19.35	15.29	10.40	2.10	V	< 2.00	0.229	23.59	1	99
		16-QAM	-20.14	14.50	10.40	2.10	V		0.191	22.80		
		64-QAM	-20.94	13.70	10.40	2.10	V		0.158	22.00		
		256-QAM	-23.86	10.78	10.40	2.10	V		0.081	19.08		
1880.0		QPSK	-18.55	16.40	10.40	2.21	V		0.288	24.59	1	50
		16-QAM	-19.50	15.45	10.40	2.21	V		0.231	23.64		
		64-QAM	-20.03	14.92	10.40	2.21	V		0.205	23.11		
		256-QAM	-23.18	11.77	10.40	2.21	V		0.099	19.96		
1900.0		QPSK	-18.45	16.43	10.40	2.20	V		0.290	24.63	1	99
		16-QAM	-18.78	16.10	10.40	2.20	V		0.269	24.30		
		64-QAM	-19.71	15.17	10.40	2.20	V		0.217	23.37		
		256-QAM	-22.93	11.95	10.40	2.20	V		0.104	20.15		

8.2 RADIATED SPURIOUS EMISSIONS

■ MODE: LTE B2
 ■ MODULATION SIGNAL: 5 MHz QPSK
 ■ DISTANCE: 3 meters
 ■ LIMIT: -13 dBm

Ch	Freq (MHz)	Measured Level (dBm)	Ant. Gain (dBi)	Substitute Level (dBm)	C.L	Pol	Result (dBm)	RB	
								Size	Offset
18625 (1852.5)	3 705.00	-43.04	12.28	-60.17	3.08	V	-50.97	1	24
	5 557.50	-42.89	13.04	-54.87	3.88	V	-45.71		
	7 410.00	-43.51	10.79	-46.32	4.57	V	-40.10		
18900 (1880.0)	3 760.00	-43.79	12.22	-59.40	3.12	V	-50.30	1	13
	5 640.00	-42.10	13.12	-54.54	3.92	H	-45.34		
	7 520.00	-43.00	10.82	-45.65	4.61	V	-39.44		
19175 (1907.5)	3 815.00	-43.13	12.16	-59.57	3.20	V	-50.61	1	0
	5 722.50	-43.78	13.05	-56.15	4.00	V	-47.10		
	7 630.00	-43.41	11.18	-46.21	4.66	H	-39.69		

8.3 PEAK-TO-AVERAGE RATIO

Band	Band Width	Frequency (MHz)	Modulation	Resource Block Size	Resource Block Offset	Data (dB)
2	1.4 MHz	1880.0	QPSK	6	0	5.63
			16-QAM			6.24
			64-QAM			6.48
			256-QAM			6.84
	3 MHz		QPSK	15		5.70
			16-QAM			6.26
			64-QAM			6.49
			256-QAM			6.69
	5 MHz		QPSK	25		5.63
			16-QAM			6.30
			64-QAM			6.52
			256-QAM			6.69
	10 MHz		QPSK	50		5.73
			16-QAM			6.24
			64-QAM			6.54
			256-QAM			6.74
	15 MHz		QPSK	75		5.61
			16-QAM			6.24
			64-QAM			6.49
			256-QAM			6.73
	20 MHz		QPSK	100		5.63
			16-QAM			6.26
			64-QAM			6.52
			256-QAM			6.78

Note:

1. Plots of the EUT's Peak- to- Average Ratio are shown Page 79 ~ 102.

8.4 OCCUPIED BANDWIDTH

Band	Band Width	Frequency (MHz)	Modulation	Resource Block Size	Resource Block Offset	Data (MHz)
2	1.4 MHz	1880.0	QPSK	6	0	1.0987
			16-QAM			1.0974
			64-QAM			1.1065
			256-QAM			1.0948
	3 MHz		QPSK	15		2.7089
			16-QAM			2.7162
			64-QAM			2.7140
			256-QAM			2.7105
	5 MHz		QPSK	25		4.5404
			16-QAM			4.5188
			64-QAM			4.5303
			256-QAM			4.5112
	10 MHz		QPSK	50		9.0118
			16-QAM			9.0375
			64-QAM			9.0144
			256-QAM			9.0087
	15 MHz		QPSK	75		13.465
			16-QAM			13.477
			64-QAM			13.492
			256-QAM			13.462
	20 MHz		QPSK	100		17.966
			16-QAM			17.945
			64-QAM			17.972
			256-QAM			17.972

Note:

1. Plots of the EUT's Occupied Bandwidth are shown Page 103 ~ 126.

8.5 CONDUCTED SPURIOUS EMISSIONS

Band	Band Width (MHz)	Frequency (MHz)	Frequency of Maximum Harmonic (GHz)	Factor (dB)	Measurement Maximum Data (dBm)	Result (dBm)	Limit (dBm)
2	1.4	1850.7	3.6990	27.976	-67.780	-39.804	-13.00
		1880.0	3.7189	27.976	-67.799	-39.823	
		1909.3	3.6890	27.976	-66.207	-38.231	
	3	1851.5	3.6990	27.976	-67.800	-39.824	
		1880.0	3.7189	27.976	-68.131	-40.155	
		1908.5	5.7229	28.591	-68.188	-39.597	
	5	1852.5	7.2283	28.591	-68.460	-39.869	
		1880.0	2.5823	27.976	-68.271	-40.295	
		1907.5	6.2214	28.591	-68.481	-39.890	
	10	1855.0	5.0649	28.591	-68.116	-39.525	
		1880.0	3.6790	27.976	-68.039	-40.063	
		1905.0	6.9193	28.591	-68.059	-39.468	
	15	1857.5	3.7289	27.976	-68.188	-40.212	
		1880.0	3.0409	27.976	-67.863	-39.887	
		1902.5	3.1506	27.976	-68.529	-40.553	
	20	1860.0	3.0609	27.976	-67.785	-39.809	
		1880.0	3.6890	27.976	-68.404	-40.428	
		1900.0	3.6890	27.976	-67.750	-39.774	

Note:

1. Plots of the EUT's Conducted Spurious Emissions are shown Page 127 ~ 162.
2. Conducted Spurious Emissions was Tested QPSK Modulation, Resource Block Size 1 and Resource Block Offset 0
3. Result (dBm) = Measurement Maximum Data (dBm) + Factor (dB)
4. Factor (dB) = Cable Loss + Attenuator + Power Splitter

Frequency Range (GHz)	Factor [dB]
0.03 – 1	25.270
1 – 5	27.976
5 – 10	28.591
10 – 15	29.116
15 – 20	29.489
Above 20(26.5)	30.131

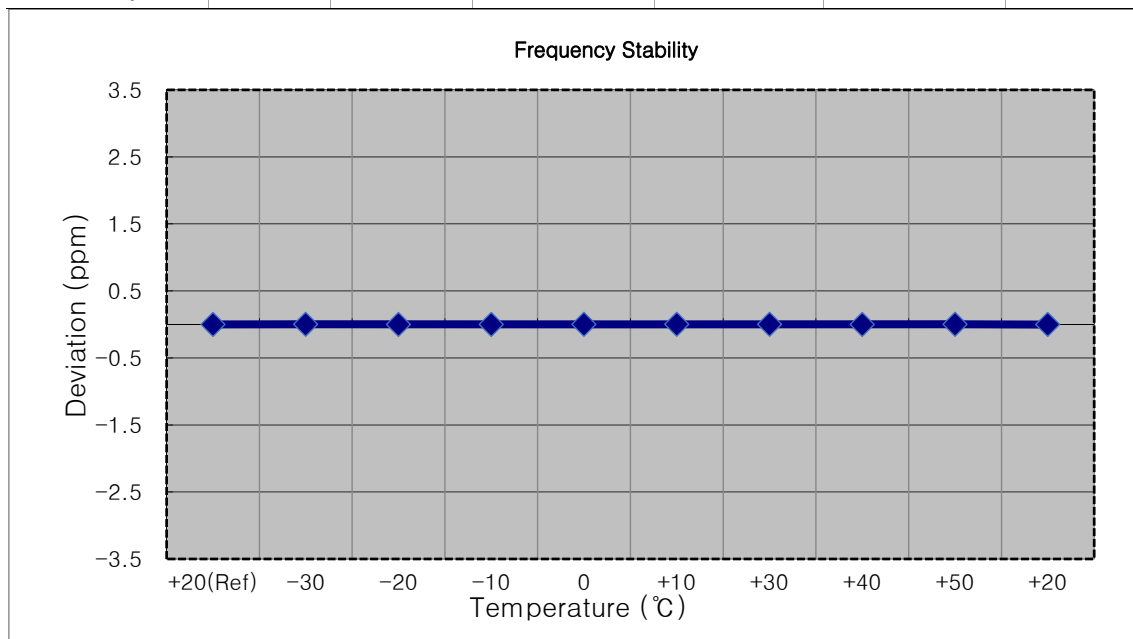
8.6 BAND EDGE

- Plots of the EUT's Band Edge are shown Page 163 ~ 198.

8.7 FREQUENCY STABILITY / VARIATION OF AMBIENT TEMPERATURE

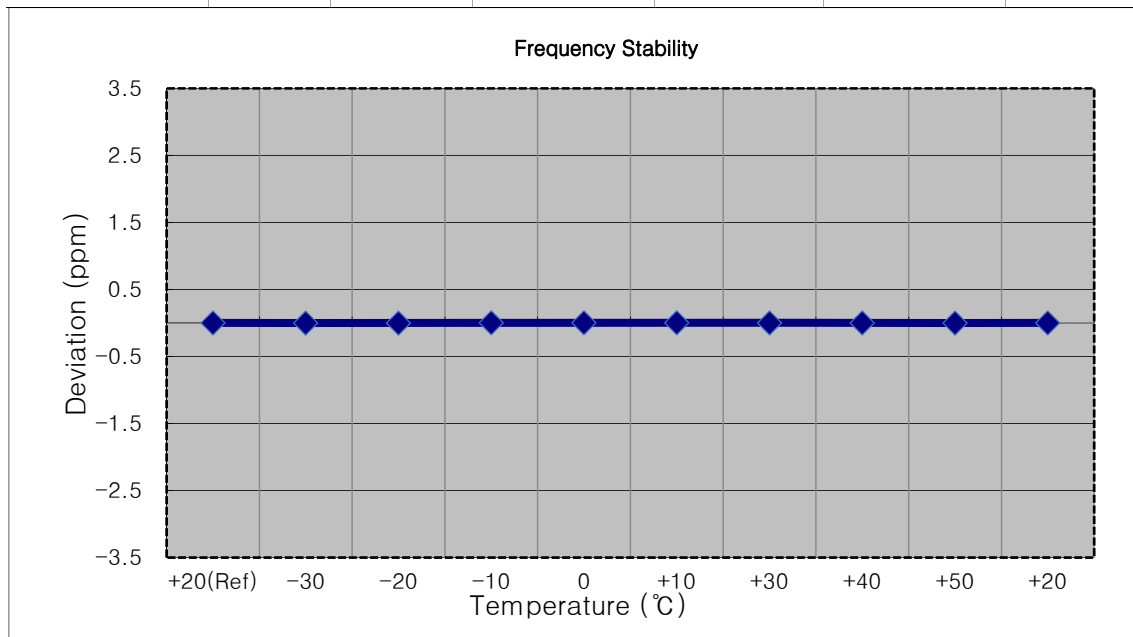
MODE:	<u>LTE B2</u>
OPERATING FREQUENCY:	<u>1850,700,000 Hz</u>
CHANNEL:	<u>18607 (1.4 MHz)</u>
REFERENCE VOLTAGE:	<u>4.200 VDC</u>
DEVIATION LIMIT:	<u>Emission must remain in band</u>

Voltage (%)	Power (VDC)	Temp. (°C)	Frequency (Hz)	Frequency Error (Hz)	Deviation (%)	ppm
100 %	4.200	+20(Ref)	1850 699 998	0.0	0.000 000	0.000
100 %		-30	1850 700 001	2.2	0.000 000	0.001
100 %		-20	1850 699 997	-1.9	0.000 000	-0.001
100 %		-10	1850 699 996	-2.1	0.000 000	-0.001
100 %		0	1850 700 002	3.3	0.000 000	0.002
100 %		+10	1850 700 002	3.7	0.000 000	0.002
100 %		+30	1850 700 000	1.6	0.000 000	0.001
100 %		+40	1850 699 997	-1.6	0.000 000	-0.001
100 %		+50	1850 700 002	3.4	0.000 000	0.002
Batt. Endpoint	3.400	+20	1850 699 996	-2.6	0.000 000	-0.001



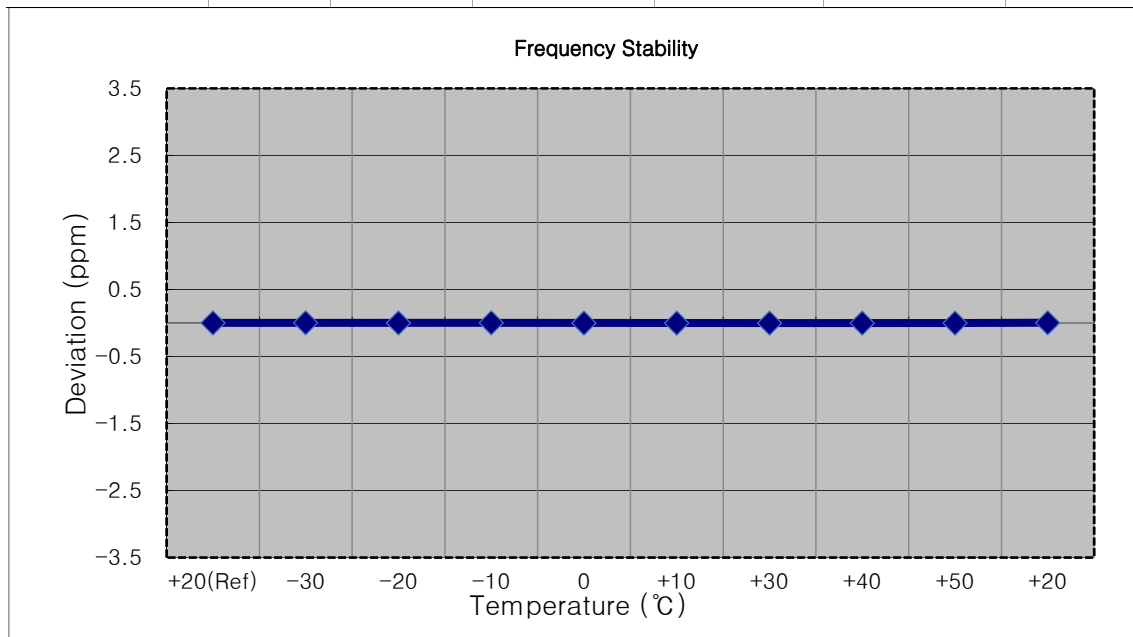
- ▣ MODE: LTE B2
- ▣ OPERATING FREQUENCY: 1851,500,000 Hz
- ▣ CHANNEL: 18615 (3 MHz)
- ▣ REFERENCE VOLTAGE: 4.200 VDC
- ▣ DEVIATION LIMIT: Emission must remain in band

Voltage (%)	Power (VDC)	Temp. (°C)	Frequency (Hz)	Frequency Error (Hz)	Deviation (%)	ppm
100 %	4.200	+20(Ref)	1851 500 003	0.0	0.000 000	0.000
100 %		-30	1851 500 001	-2.0	0.000 000	-0.001
100 %		-20	1851 499 999	-3.4	0.000 000	-0.002
100 %		-10	1851 500 007	4.5	0.000 000	0.002
100 %		0	1851 500 006	3.0	0.000 000	0.002
100 %		+10	1851 500 006	3.1	0.000 000	0.002
100 %		+30	1851 500 004	1.8	0.000 000	0.001
100 %		+40	1851 500 005	2.3	0.000 000	0.001
100 %		+50	1851 499 999	-3.7	0.000 000	-0.002
Batt. Endpoint	3.400	+20	1851 500 005	2.6	0.000 000	0.001



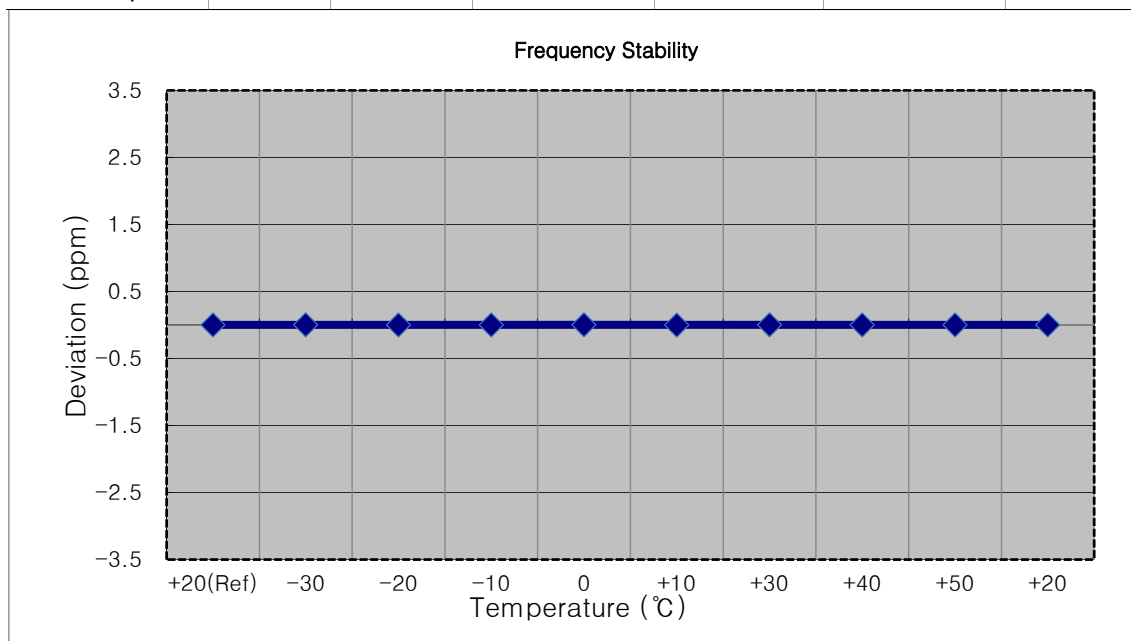
- ▣ MODE: LTE B2
- ▣ OPERATING FREQUENCY: 1852,500,000 Hz
- ▣ CHANNEL: 18625 (5 MHz)
- ▣ REFERENCE VOLTAGE: 4.200 VDC
- ▣ DEVIATION LIMIT: Emission must remain in band

Voltage (%)	Power (VDC)	Temp. (°C)	Frequency (Hz)	Frequency Error (Hz)	Deviation (%)	ppm
100 %	4.200	+20(Ref)	1852 500 003	0.0	0.000 000	0.000
100 %		-30	1852 500 006	3.5	0.000 000	0.002
100 %		-20	1852 500 005	2.1	0.000 000	0.001
100 %		-10	1852 500 006	3.0	0.000 000	0.002
100 %		0	1852 500 000	-3.0	0.000 000	-0.002
100 %		+10	1852 499 999	-3.5	0.000 000	-0.002
100 %		+30	1852 500 000	-2.5	0.000 000	-0.001
100 %		+40	1852 499 999	-3.2	0.000 000	-0.002
100 %		+50	1852 500 000	-2.9	0.000 000	-0.002
Batt. Endpoint	3.400	+20	1852 500 006	3.2	0.000 000	0.002



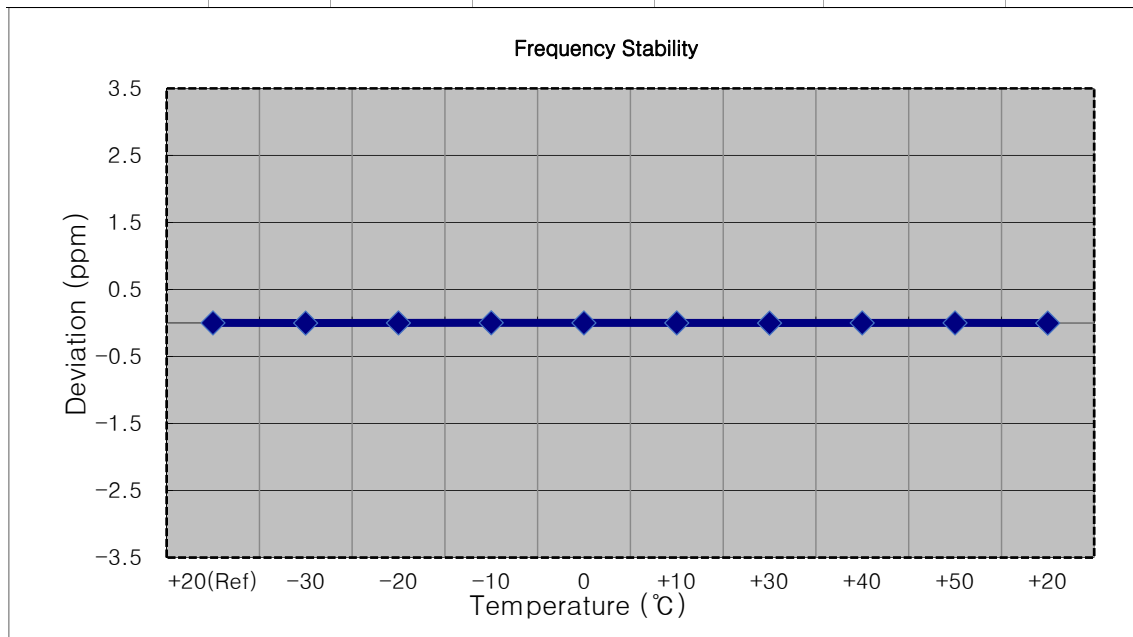
MODE:	<u>LTE B2</u>
OPERATING FREQUENCY:	<u>1855,000,000 Hz</u>
CHANNEL:	<u>18650 (10 MHz)</u>
REFERENCE VOLTAGE:	<u>4.200 VDC</u>
DEVIATION LIMIT:	<u>Emission must remain in band</u>

Voltage (%)	Power (VDC)	Temp. (°C)	Frequency (Hz)	Frequency Error (Hz)	Deviation (%)	ppm
100 %	4.200	+20(Ref)	1855 000 002	0.0	0.000 000	0.000
100 %		-30	1855 000 006	3.7	0.000 000	0.002
100 %		-20	1855 000 005	2.3	0.000 000	0.001
100 %		-10	1855 000 004	1.6	0.000 000	0.001
100 %		0	1855 000 005	2.8	0.000 000	0.002
100 %		+10	1855 000 000	-2.5	0.000 000	-0.001
100 %		+30	1855 000 005	2.9	0.000 000	0.002
100 %		+40	1855 000 004	2.1	0.000 000	0.001
100 %		+50	1855 000 005	2.6	0.000 000	0.001
Batt. Endpoint	3.400	+20	1855 000 004	2.2	0.000 000	0.001



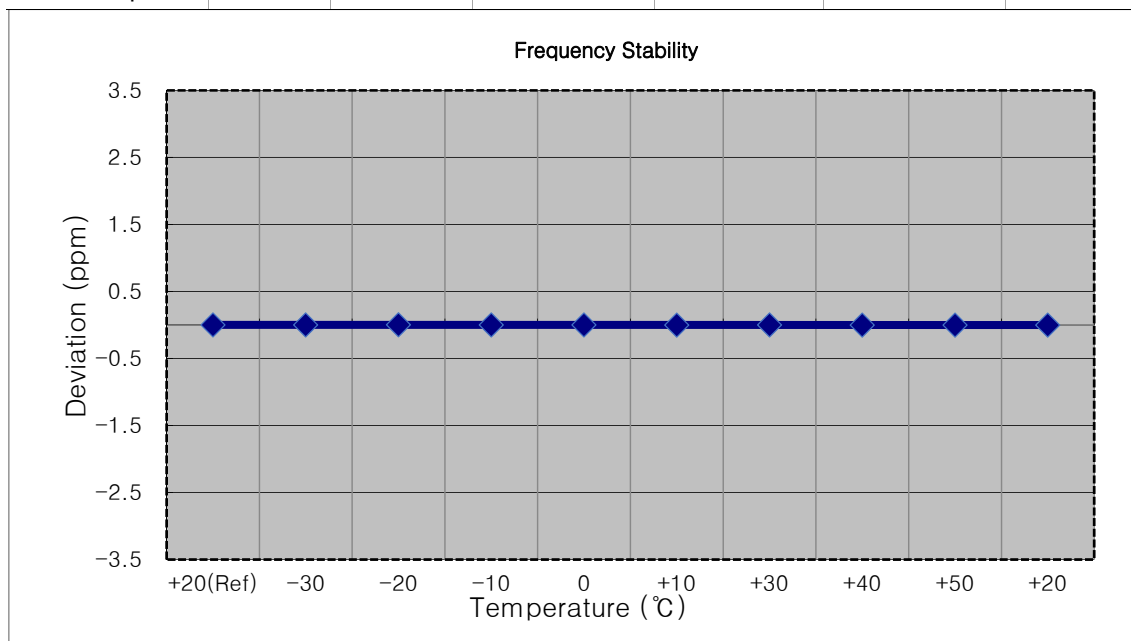
- ▣ MODE: LTE B2
- ▣ OPERATING FREQUENCY: 1857,500,000 Hz
- ▣ CHANNEL: 18675 (15 MHz)
- ▣ REFERENCE VOLTAGE: 4.200 VDC
- ▣ DEVIATION LIMIT: Emission must remain in band

Voltage (%)	Power (VDC)	Temp. (°C)	Frequency (Hz)	Frequency Error (Hz)	Deviation (%)	ppm
100 %	4.200	+20(Ref)	1857 500 002	0.0	0.000 000	0.000
100 %		-30	1857 500 000	-2.7	0.000 000	-0.001
100 %		-20	1857 500 005	2.7	0.000 000	0.001
100 %		-10	1857 500 005	3.0	0.000 000	0.002
100 %		0	1857 500 004	1.8	0.000 000	0.001
100 %		+10	1857 500 005	2.4	0.000 000	0.001
100 %		+30	1857 500 000	-2.0	0.000 000	-0.001
100 %		+40	1857 500 004	1.3	0.000 000	0.001
100 %		+50	1857 500 005	2.5	0.000 000	0.001
Batt. Endpoint	3.400	+20	1857 500 000	-2.0	0.000 000	-0.001



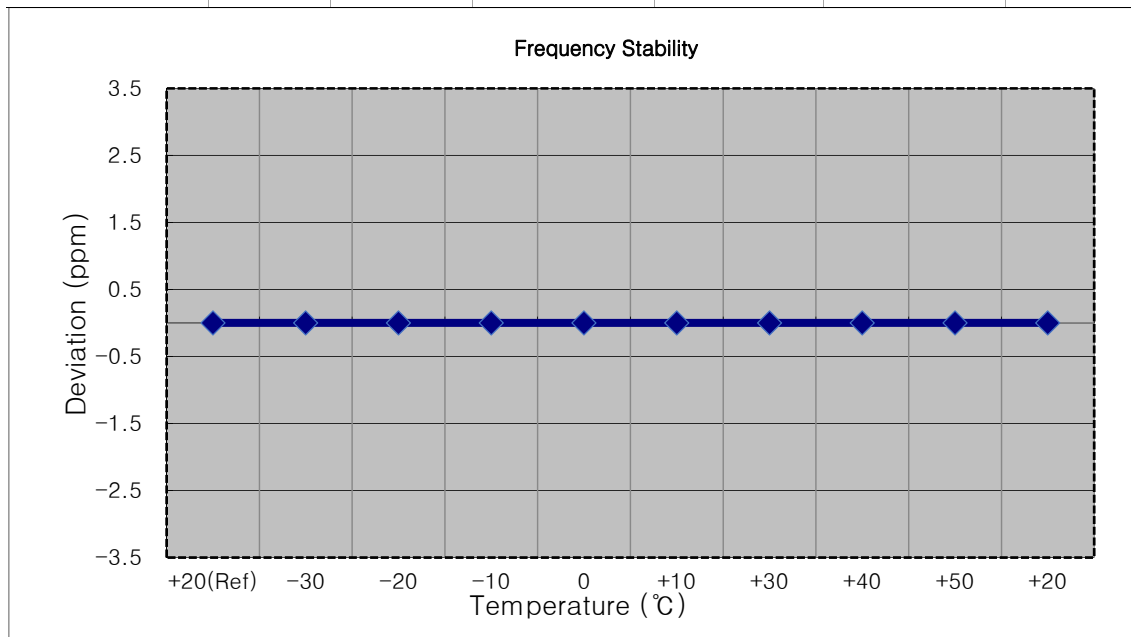
- ▣ MODE: LTE B2
- ▣ OPERATING FREQUENCY: 1860,000,000 Hz
- ▣ CHANNEL: 18700 (20 MHz)
- ▣ REFERENCE VOLTAGE: 4.200 VDC
- ▣ DEVIATION LIMIT: Emission must remain in band

Voltage (%)	Power (VDC)	Temp. (°C)	Frequency (Hz)	Frequency Error (Hz)	Deviation (%)	ppm
100 %	4.200	+20(Ref)	1860 000 002	0.0	0.000 000	0.000
100 %		-30	1860 000 004	1.5	0.000 000	0.001
100 %		-20	1860 000 006	3.2	0.000 000	0.002
100 %		-10	1860 000 005	2.4	0.000 000	0.001
100 %		0	1860 000 004	1.5	0.000 000	0.001
100 %		+10	1860 000 000	-2.9	0.000 000	-0.002
100 %		+30	1860 000 005	2.3	0.000 000	0.001
100 %		+40	1860 000 000	-2.2	0.000 000	-0.001
100 %		+50	1860 000 000	-2.5	0.000 000	-0.001
Batt. Endpoint	3.400	+20	1860 000 001	-1.9	0.000 000	-0.001



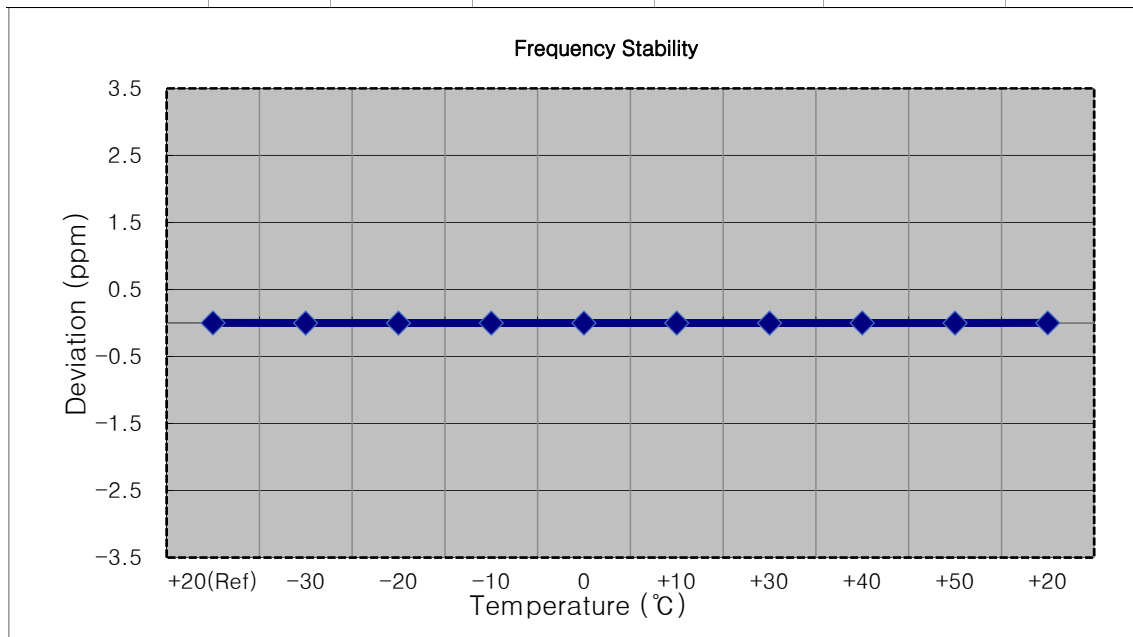
MODE:	<u>LTE B2</u>
OPERATING FREQUENCY:	<u>1880,000,000 Hz</u>
CHANNEL:	<u>18900 (1.4 MHz)</u>
REFERENCE VOLTAGE:	<u>4.200 VDC</u>
DEVIATION LIMIT:	<u>Emission must remain in band</u>

Voltage (%)	Power (VDC)	Temp. (°C)	Frequency (Hz)	Frequency Error (Hz)	Deviation (%)	ppm
100 %	4.200	+20(Ref)	1879 999 997	0.0	0.000 000	0.000
100 %		-30	1880 000 000	2.6	0.000 000	0.001
100 %		-20	1879 999 996	-1.5	0.000 000	-0.001
100 %		-10	1880 000 000	2.6	0.000 000	0.001
100 %		0	1879 999 996	-1.3	0.000 000	-0.001
100 %		+10	1879 999 999	1.7	0.000 000	0.001
100 %		+30	1879 999 999	1.5	0.000 000	0.001
100 %		+40	1880 000 000	2.3	0.000 000	0.001
100 %		+50	1880 000 000	2.2	0.000 000	0.001
Batt. Endpoint	3.400	+20	1879 999 999	1.8	0.000 000	0.001



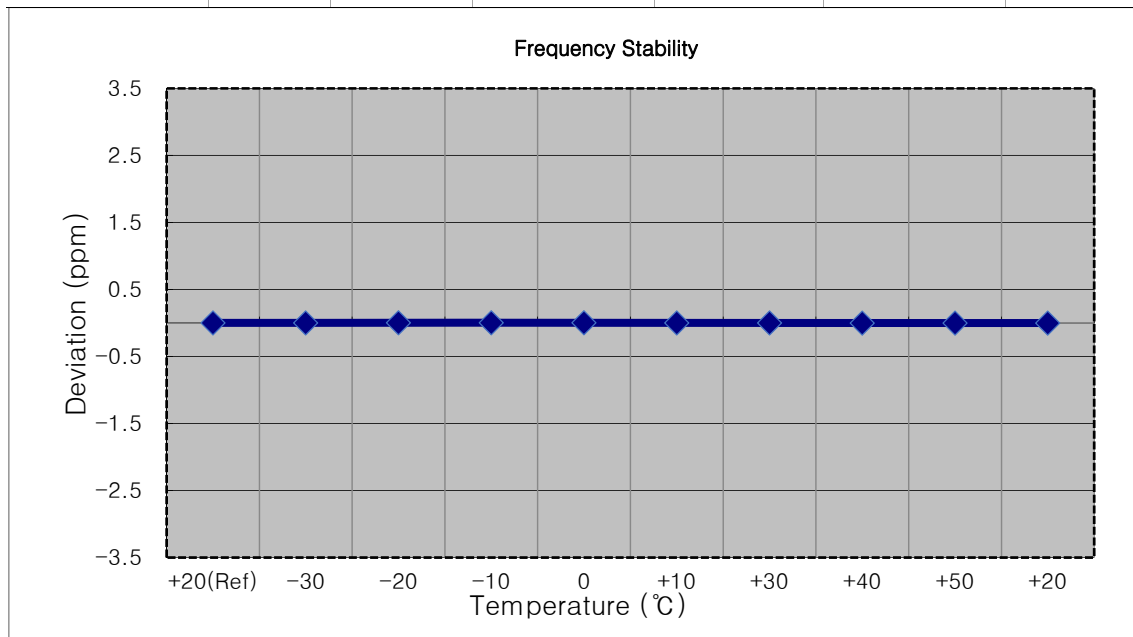
- ▣ MODE: LTE B2
- ▣ OPERATING FREQUENCY: 1880,000,000 Hz
- ▣ CHANNEL: 18900 (3 MHz)
- ▣ REFERENCE VOLTAGE: 4.200 VDC
- ▣ DEVIATION LIMIT: Emission must remain in band

Voltage (%)	Power (VDC)	Temp. (°C)	Frequency (Hz)	Frequency Error (Hz)	Deviation (%)	ppm
100 %	4.200	+20(Ref)	1880 000 002	0.0	0.000 000	0.000
100 %		-30	1879 999 999	-2.5	0.000 000	-0.001
100 %		-20	1879 999 999	-2.5	0.000 000	-0.001
100 %		-10	1879 999 999	-3.3	0.000 000	-0.002
100 %		0	1879 999 999	-2.7	0.000 000	-0.001
100 %		+10	1879 999 999	-3.0	0.000 000	-0.002
100 %		+30	1880 000 000	-2.1	0.000 000	-0.001
100 %		+40	1880 000 004	1.8	0.000 000	0.001
100 %		+50	1879 999 999	-2.6	0.000 000	-0.001
Batt. Endpoint	3.400	+20	1880 000 004	2.5	0.000 000	0.001



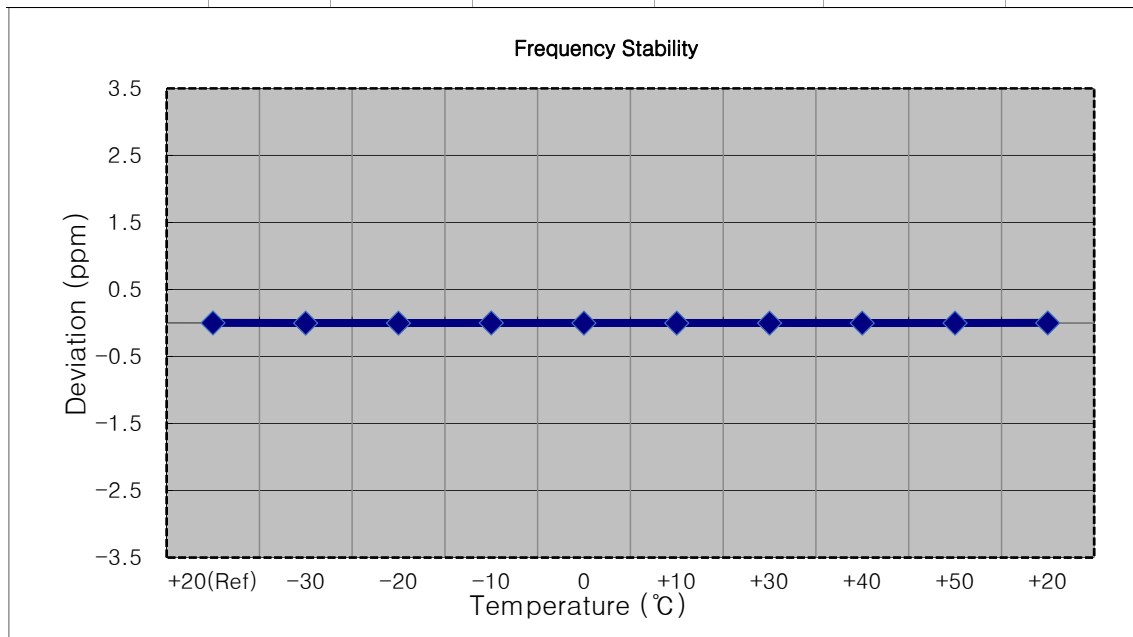
■ MODE: LTE B2
 ■ OPERATING FREQUENCY: 1880,000,000 Hz
 ■ CHANNEL: 18900 (5 MHz)
 ■ REFERENCE VOLTAGE: 4.200 VDC
 ■ DEVIATION LIMIT: Emission must remain in band

Voltage (%)	Power (VDC)	Temp. (°C)	Frequency (Hz)	Frequency Error (Hz)	Deviation (%)	ppm
100 %	4.200	+20(Ref)	1880 000 002	0.0	0.000 000	0.000
100 %		-30	1880 000 004	2.4	0.000 000	0.001
100 %		-20	1880 000 004	2.8	0.000 000	0.001
100 %		-10	1880 000 005	3.1	0.000 000	0.002
100 %		0	1880 000 005	3.8	0.000 000	0.002
100 %		+10	1880 000 000	-1.7	0.000 000	-0.001
100 %		+30	1880 000 003	1.5	0.000 000	0.001
100 %		+40	1879 999 998	-3.4	0.000 000	-0.002
100 %		+50	1879 999 999	-3.0	0.000 000	-0.002
Batt. Endpoint	3.400	+20	1879 999 999	-2.3	0.000 000	-0.001



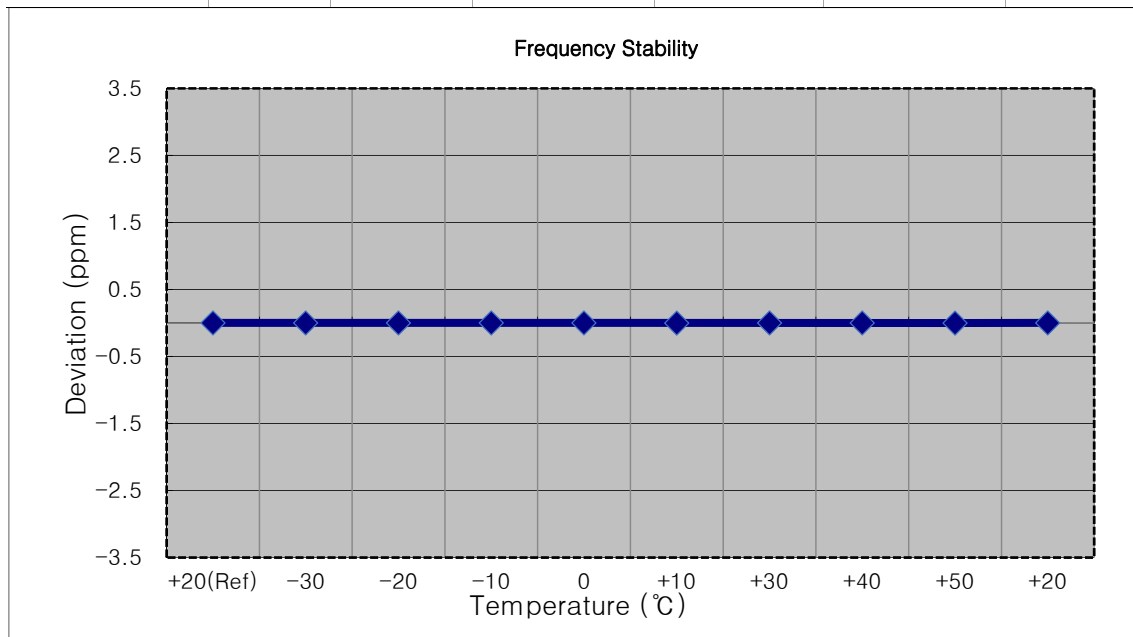
- ▣ MODE: LTE B2
- ▣ OPERATING FREQUENCY: 1880,000,000 Hz
- ▣ CHANNEL: 18900 (10 MHz)
- ▣ REFERENCE VOLTAGE: 4.200 VDC
- ▣ DEVIATION LIMIT: Emission must remain in band

Voltage (%)	Power (VDC)	Temp. (°C)	Frequency (Hz)	Frequency Error (Hz)	Deviation (%)	ppm
100 %	4.200	+20(Ref)	1880 000 001	0.0	0.000 000	0.000
100 %		-30	1879 999 998	-3.1	0.000 000	-0.002
100 %		-20	1879 999 998	-2.9	0.000 000	-0.002
100 %		-10	1880 000 003	1.9	0.000 000	0.001
100 %		0	1879 999 999	-1.8	0.000 000	-0.001
100 %		+10	1879 999 999	-2.4	0.000 000	-0.001
100 %		+30	1879 999 999	-2.1	0.000 000	-0.001
100 %		+40	1879 999 997	-3.7	0.000 000	-0.002
100 %		+50	1879 999 998	-2.7	0.000 000	-0.001
Batt. Endpoint	3.400	+20	1879 999 999	-1.7	0.000 000	-0.001



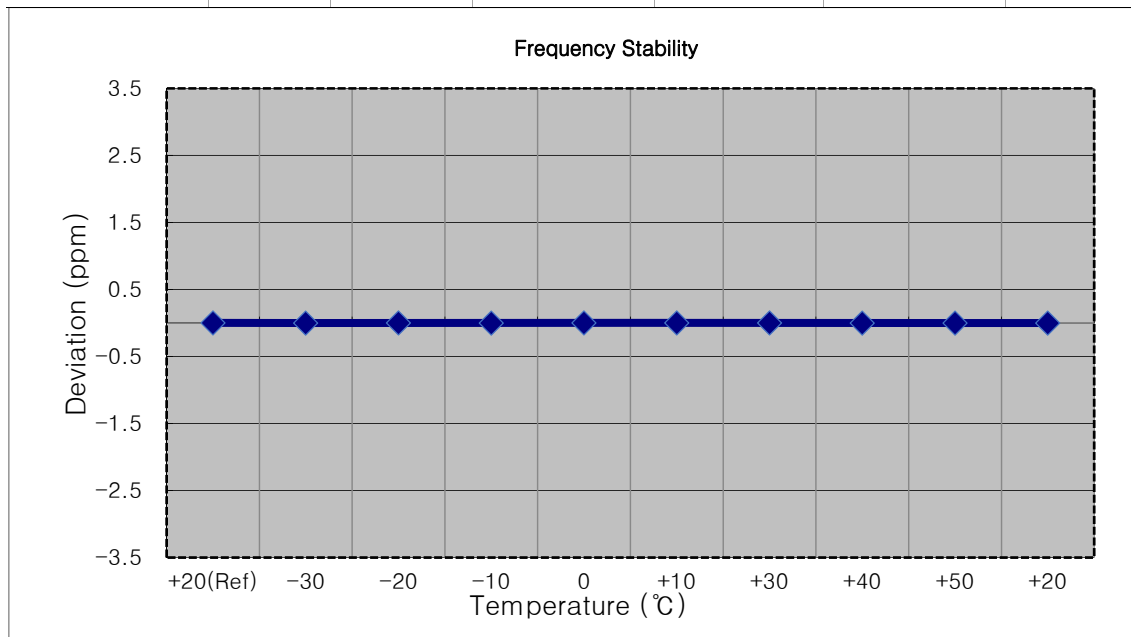
- ▣ MODE: LTE B2
- ▣ OPERATING FREQUENCY: 1880,000,000 Hz
- ▣ CHANNEL: 18900 (15 MHz)
- ▣ REFERENCE VOLTAGE: 4.200 VDC
- ▣ DEVIATION LIMIT: Emission must remain in band

Voltage (%)	Power (VDC)	Temp. (°C)	Frequency (Hz)	Frequency Error (Hz)	Deviation (%)	ppm
100 %	4.200	+20(Ref)	1879 999 997	0.0	0.000 000	0.000
100 %		-30	1879 999 998	1.2	0.000 000	0.001
100 %		-20	1879 999 999	1.9	0.000 000	0.001
100 %		-10	1879 999 999	2.2	0.000 000	0.001
100 %		0	1879 999 999	2.2	0.000 000	0.001
100 %		+10	1879 999 995	-2.3	0.000 000	-0.001
100 %		+30	1880 000 000	2.5	0.000 000	0.001
100 %		+40	1879 999 999	1.7	0.000 000	0.001
100 %		+50	1879 999 995	-2.5	0.000 000	-0.001
Batt. Endpoint	3.400	+20	1879 999 999	2.0	0.000 000	0.001



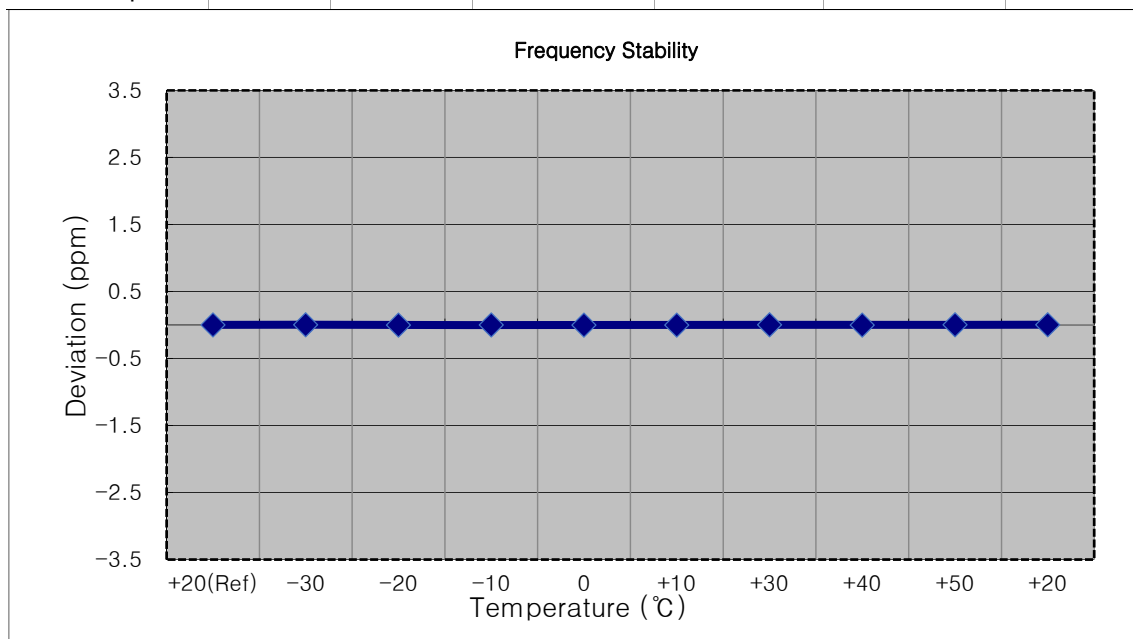
MODE:	<u>LTE B2</u>
OPERATING FREQUENCY:	<u>1880,000,000 Hz</u>
CHANNEL:	<u>18900 (20 MHz)</u>
REFERENCE VOLTAGE:	<u>4.200 VDC</u>
DEVIATION LIMIT:	<u>Emission must remain in band</u>

Voltage (%)	Power (VDC)	Temp. (°C)	Frequency (Hz)	Frequency Error (Hz)	Deviation (%)	ppm
100 %	4.200	+20(Ref)	1880 000 002	0.0	0.000 000	0.000
100 %		-30	1879 999 999	-2.7	0.000 000	-0.001
100 %		-20	1880 000 003	1.4	0.000 000	0.001
100 %		-10	1879 999 999	-2.5	0.000 000	-0.001
100 %		0	1880 000 001	-1.4	0.000 000	-0.001
100 %		+10	1880 000 003	1.5	0.000 000	0.001
100 %		+30	1880 000 004	1.6	0.000 000	0.001
100 %		+40	1879 999 999	-2.5	0.000 000	-0.001
100 %		+50	1880 000 000	-2.4	0.000 000	-0.001
Batt. Endpoint	3.400	+20	1880 000 000	-1.8	0.000 000	-0.001



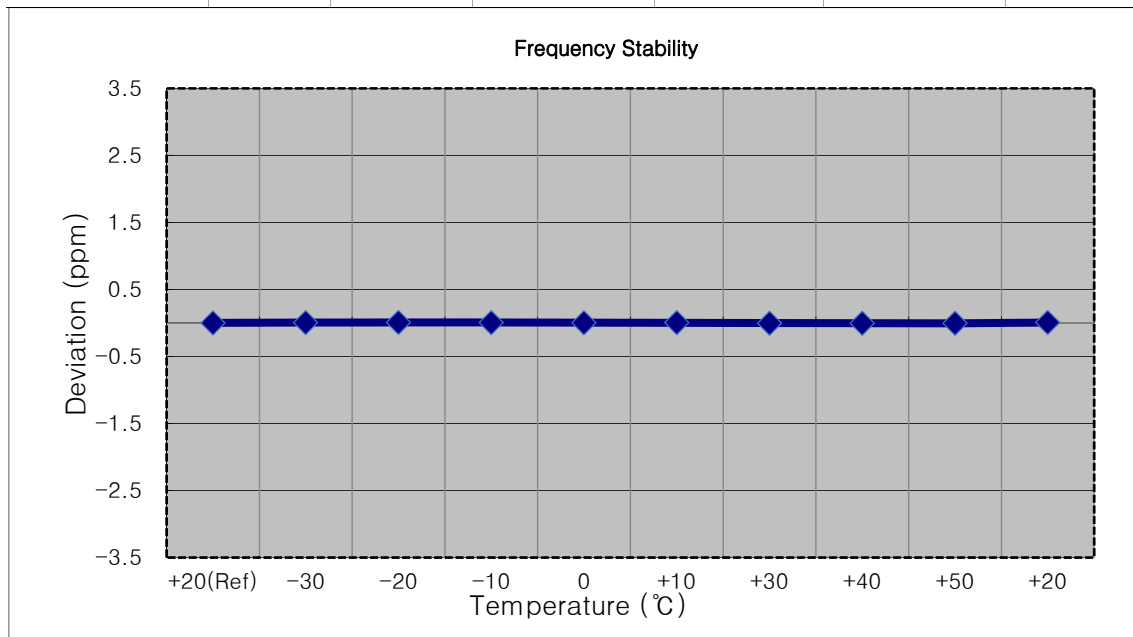
- ▣ MODE: LTE B2
- ▣ OPERATING FREQUENCY: 1909,300,000 Hz
- ▣ CHANNEL: 19193 (1.4 MHz)
- ▣ REFERENCE VOLTAGE: 4.200 VDC
- ▣ DEVIATION LIMIT: Emission must remain in band

Voltage (%)	Power (VDC)	Temp. (°C)	Frequency (Hz)	Frequency Error (Hz)	Deviation (%)	ppm
100 %	4.200	+20(Ref)	1909 299 997	0.0	0.000 000	0.000
100 %		-30	1909 300 001	3.7	0.000 000	0.002
100 %		-20	1909 299 993	-4.4	0.000 000	-0.002
100 %		-10	1909 299 999	1.8	0.000 000	0.001
100 %		0	1909 299 993	-4.1	0.000 000	-0.002
100 %		+10	1909 299 993	-4.0	0.000 000	-0.002
100 %		+30	1909 300 000	3.4	0.000 000	0.002
100 %		+40	1909 299 993	-4.1	0.000 000	-0.002
100 %		+50	1909 300 002	4.9	0.000 000	0.003
Batt. Endpoint	3.400	+20	1909 300 001	3.5	0.000 000	0.002



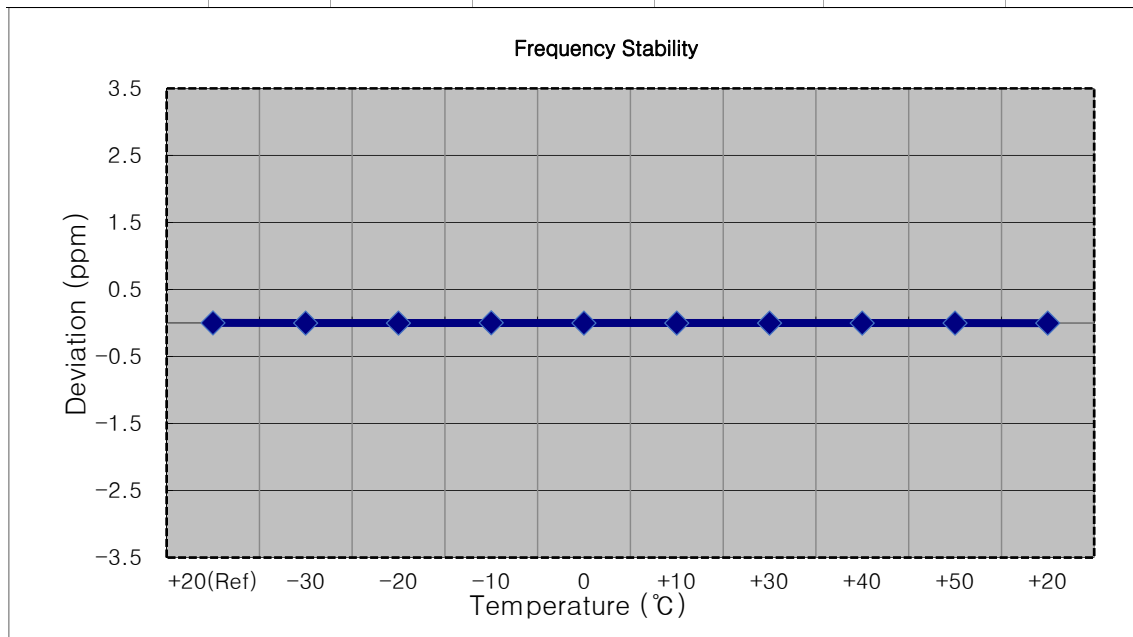
MODE:	<u>LTE B2</u>
OPERATING FREQUENCY:	<u>1908,500,000 Hz</u>
CHANNEL:	<u>19185 (3 MHz)</u>
REFERENCE VOLTAGE:	<u>4.200 VDC</u>
DEVIATION LIMIT:	<u>Emission must remain in band</u>

Voltage (%)	Power (VDC)	Temp. (°C)	Frequency (Hz)	Frequency Error (Hz)	Deviation (%)	ppm
100 %	4.200	+20(Ref)	1908 499 992	0.0	0.000 000	0.000
100 %		-30	1908 500 001	8.7	0.000 000	0.005
100 %		-20	1908 500 004	12.0	0.000 001	0.006
100 %		-10	1908 500 003	10.6	0.000 001	0.006
100 %		0	1908 499 997	5.2	0.000 000	0.003
100 %		+10	1908 500 001	8.7	0.000 000	0.005
100 %		+30	1908 499 984	-7.6	0.000 000	-0.004
100 %		+40	1908 499 984	-7.6	0.000 000	-0.004
100 %		+50	1908 499 982	-9.7	-0.000 001	-0.005
Batt. Endpoint	3.400	+20	1908 500 004	12.5	0.000 001	0.007



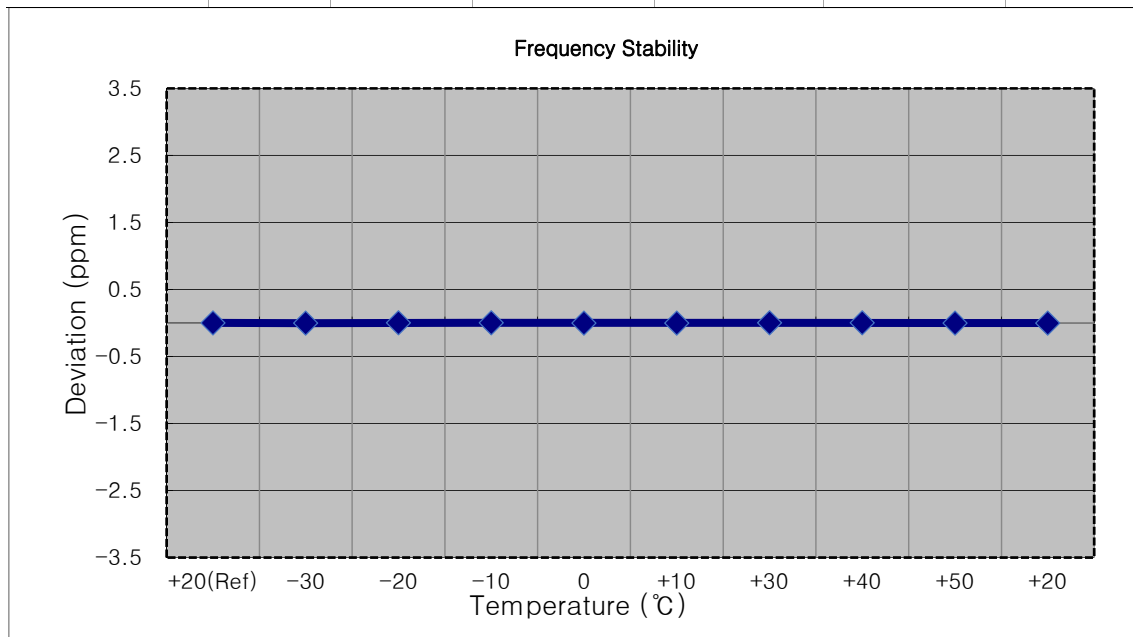
- ▣ MODE: LTE B2
- ▣ OPERATING FREQUENCY: 1907,500,000 Hz
- ▣ CHANNEL: 19175 (5 MHz)
- ▣ REFERENCE VOLTAGE: 4.200 VDC
- ▣ DEVIATION LIMIT: Emission must remain in band

Voltage (%)	Power (VDC)	Temp. (°C)	Frequency (Hz)	Frequency Error (Hz)	Deviation (%)	ppm
100 %	4.200	+20(Ref)	1907 499 996	0.0	0.000 000	0.000
100 %		-30	1907 499 993	-3.1	0.000 000	-0.002
100 %		-20	1907 499 992	-3.4	0.000 000	-0.002
100 %		-10	1907 499 999	3.6	0.000 000	0.002
100 %		0	1907 499 991	-4.6	0.000 000	-0.002
100 %		+10	1907 499 992	-4.1	0.000 000	-0.002
100 %		+30	1907 499 991	-4.3	0.000 000	-0.002
100 %		+40	1907 499 993	-3.2	0.000 000	-0.002
100 %		+50	1907 499 992	-3.9	0.000 000	-0.002
Batt. Endpoint	3.400	+20	1907 499 991	-5.0	0.000 000	-0.003



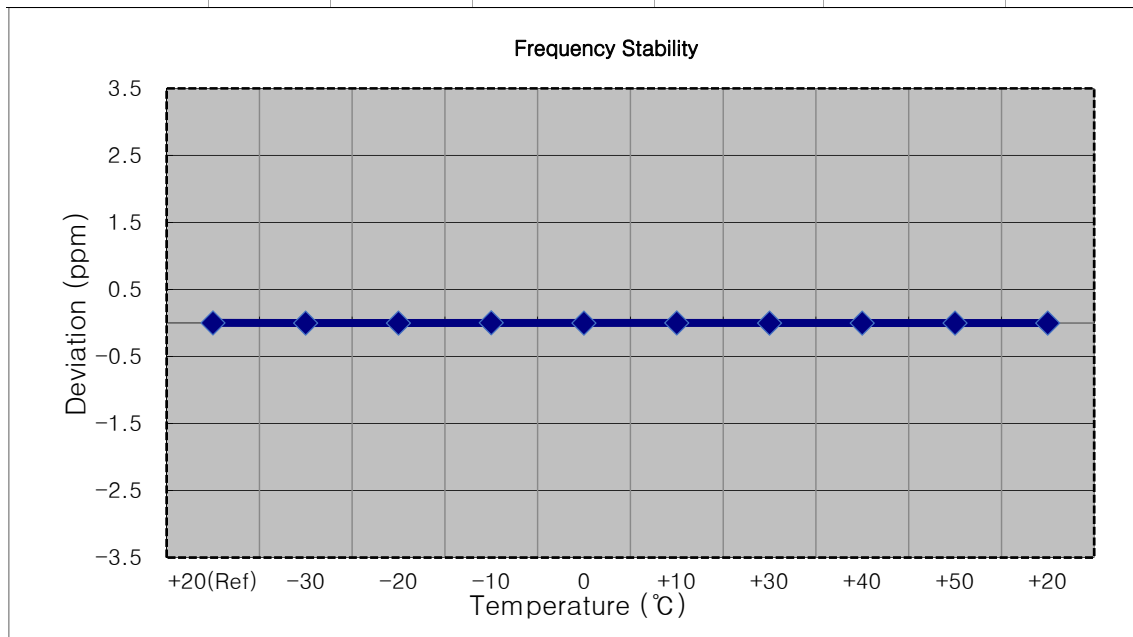
- ▣ MODE: LTE B2
- ▣ OPERATING FREQUENCY: 1905,000,000 Hz
- ▣ CHANNEL: 19150 (10 MHz)
- ▣ REFERENCE VOLTAGE: 4.200 VDC
- ▣ DEVIATION LIMIT: Emission must remain in band

Voltage (%)	Power (VDC)	Temp. (°C)	Frequency (Hz)	Frequency Error (Hz)	Deviation (%)	ppm
100 %	4.200	+20(Ref)	1905 000 003	0.0	0.000 000	0.000
100 %		-30	1904 999 999	-4.6	0.000 000	-0.002
100 %		-20	1905 000 008	5.1	0.000 000	0.003
100 %		-10	1905 000 007	3.5	0.000 000	0.002
100 %		0	1904 999 999	-4.3	0.000 000	-0.002
100 %		+10	1905 000 000	-3.3	0.000 000	-0.002
100 %		+30	1905 000 006	3.3	0.000 000	0.002
100 %		+40	1905 000 007	4.0	0.000 000	0.002
100 %		+50	1905 000 001	-2.1	0.000 000	-0.001
Batt. Endpoint	3.400	+20	1904 999 999	-4.1	0.000 000	-0.002



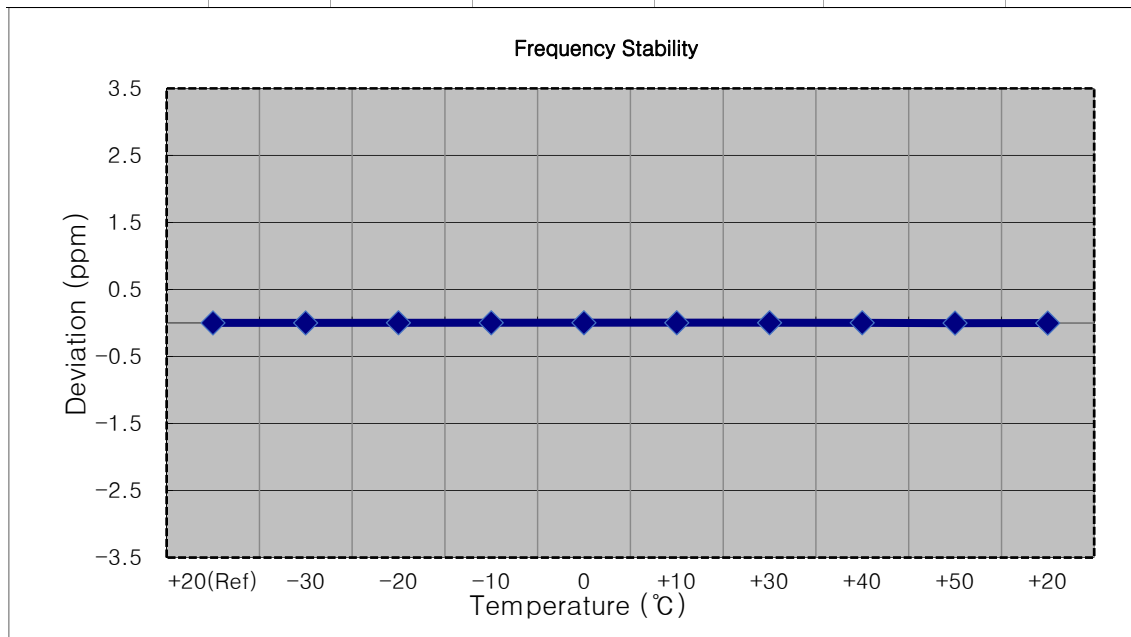
MODE:	<u>LTE B2</u>
OPERATING FREQUENCY:	<u>1902,500,000 Hz</u>
CHANNEL:	<u>19125 (15 MHz)</u>
REFERENCE VOLTAGE:	<u>4.200 VDC</u>
DEVIATION LIMIT:	<u>Emission must remain in band</u>

Voltage (%)	Power (VDC)	Temp. (°C)	Frequency (Hz)	Frequency Error (Hz)	Deviation (%)	ppm
100 %	4.200	+20(Ref)	1902 500 003	0.0	0.000 000	0.000
100 %		-30	1902 500 001	-2.7	0.000 000	-0.001
100 %		-20	1902 500 000	-3.3	0.000 000	-0.002
100 %		-10	1902 500 007	3.8	0.000 000	0.002
100 %		0	1902 500 000	-3.2	0.000 000	-0.002
100 %		+10	1902 500 005	1.8	0.000 000	0.001
100 %		+30	1902 500 001	-2.3	0.000 000	-0.001
100 %		+40	1902 500 000	-3.2	0.000 000	-0.002
100 %		+50	1902 500 000	-3.7	0.000 000	-0.002
Batt. Endpoint	3.400	+20	1902 500 001	-2.7	0.000 000	-0.001



MODE:	<u>LTE B2</u>
OPERATING FREQUENCY:	<u>1900,000,000 Hz</u>
CHANNEL:	<u>19100 (20 MHz)</u>
REFERENCE VOLTAGE:	<u>4.200 VDC</u>
DEVIATION LIMIT:	<u>Emission must remain in band</u>

Voltage (%)	Power (VDC)	Temp. (°C)	Frequency (Hz)	Frequency Error (Hz)	Deviation (%)	ppm
100 %	4.200	+20(Ref)	1900 000 003	0.0	0.000 000	0.000
100 %		-30	1900 000 005	2.0	0.000 000	0.001
100 %		-20	1900 000 006	3.0	0.000 000	0.002
100 %		-10	1900 000 006	2.8	0.000 000	0.001
100 %		0	1900 000 009	5.5	0.000 000	0.003
100 %		+10	1900 000 007	3.5	0.000 000	0.002
100 %		+30	1900 000 007	3.3	0.000 000	0.002
100 %		+40	1900 000 006	3.0	0.000 000	0.002
100 %		+50	1899 999 999	-4.2	0.000 000	-0.002
Batt. Endpoint	3.400	+20	1900 000 001	-2.2	0.000 000	-0.001



9. TEST DATA(Sub 2 ANT)

9.1 EQUIVALENT ISOTROPIC RADIATED POWER

Freq (MHz)	Mod/ Bandwidth	Modulation	Measured	Substitute	Ant. Gain (dBi)	C.L	Pol	Limit	EIRP		RB	
			Level (dBm)	Level (dBm)				W	W	dBm	Size	Offset
1850.7	LTE B2/ 1.4 MHz	QPSK	-21.88	13.02	10.15	2.07	V	< 2.00	0.129	21.10	1	5
		16-QAM	-22.68	12.22	10.15	2.07	V		0.107	20.30		
		64-QAM	-23.77	11.13	10.15	2.07	V		0.083	19.21		
		256-QAM	-26.76	8.14	10.15	2.07	V		0.042	16.22		
1880.0		QPSK	-21.16	14.21	10.11	2.21	V		0.163	22.11	1	0
		16-QAM	-22.04	13.33	10.11	2.21	V		0.133	21.23		
		64-QAM	-23.02	12.35	10.11	2.21	V		0.106	20.25		
		256-QAM	-26.01	9.36	10.11	2.21	V		0.053	17.26		
1909.3		QPSK	-21.15	14.33	10.03	2.17	V		0.166	22.19	1	0
		16-QAM	-22.02	13.46	10.03	2.17	V		0.136	21.32		
		64-QAM	-23.04	12.44	10.03	2.17	V		0.107	20.30		
		256-QAM	-26.07	9.41	10.03	2.17	V		0.053	17.27		

Freq (MHz)	Mod/ Bandwidth	Modulation	Measured	Substitute	Ant. Gain (dBi)	C.L	Pol	Limit	EIRP		RB	
			Level (dBm)	Level (dBm)				W	W	dBm	Size	Offset
1851.5	LTE B2/ 3 MHz	QPSK	-21.89	13.01	10.15	2.07	V	< 2.00	0.129	21.09	1	14
		16-QAM	-22.71	12.19	10.15	2.07	V		0.106	20.27		
		64-QAM	-23.68	11.22	10.15	2.07	V		0.085	19.30		
		256-QAM	-26.67	8.23	10.15	2.07	V		0.043	16.31		
1880.0		QPSK	-21.35	14.02	10.11	2.21	V		0.156	21.92	1	0
		16-QAM	-22.10	13.27	10.11	2.21	V		0.131	21.17		
		64-QAM	-23.19	12.18	10.11	2.21	V		0.102	20.08		
		256-QAM	-26.14	9.23	10.11	2.21	V		0.052	17.13		
1908.5		QPSK	-21.21	14.27	10.03	2.17	V		0.163	22.13	1	0
		16-QAM	-21.99	13.49	10.03	2.17	V		0.136	21.35		
		64-QAM	-23.09	12.39	10.03	2.17	V		0.106	20.25		
		256-QAM	-26.02	9.46	10.03	2.17	V		0.054	17.32		

Freq (MHz)	Mod/ Bandwidth	Modulation	Measured Level (dBm)	Substitute Level (dBm)	Ant. Gain (dBi)	C.L	Pol	Limit	EIRP		RB	
								W	W	dBm	Size	Offset
1852.5	LTE B2/ 5 MHz	QPSK	-21.79	13.21	10.15	2.08	V	< 2.00	0.134	21.28	1	24
		16-QAM	-22.56	12.44	10.15	2.08	V		0.112	20.51		
		64-QAM	-23.61	11.39	10.15	2.08	V		0.088	19.46		
		256-QAM	-26.59	8.41	10.15	2.08	V		0.044	16.48		
1880.0		QPSK	-21.44	13.93	10.11	2.21	V		0.152	21.83	1	0
		16-QAM	-22.23	13.14	10.11	2.21	V		0.127	21.04		
		64-QAM	-23.30	12.07	10.11	2.21	V		0.099	19.97		
		256-QAM	-26.24	9.13	10.11	2.21	V		0.050	17.03		
1907.5		QPSK	-21.09	14.39	10.03	2.17	V		0.168	22.25	1	0
		16-QAM	-21.98	13.50	10.03	2.17	V		0.137	21.36		
		64-QAM	-22.88	12.60	10.03	2.17	V		0.111	20.46		
		256-QAM	-25.93	9.55	10.03	2.17	V		0.055	17.41		

Freq (MHz)	Mod/ Bandwidth	Modulation	Measured	Substitute	Ant. Gain (dBi)	C.L	Pol	Limit	EIRP		RB	
			Level (dBm)	Level (dBm)				W	W	dBm	Size	Offset
1855.0	LTE B2/ 10 MHz	QPSK	-21.65	13.35	10.15	2.08	V	<2.00	0.139	21.42	1	49
		16-QAM	-22.48	12.52	10.15	2.08	V		0.115	20.59		
		64-QAM	-23.44	11.56	10.15	2.08	V		0.092	19.63		
		256-QAM	-26.46	8.54	10.15	2.08	V		0.046	16.61		
1880.0		QPSK	-21.21	14.16	10.11	2.21	V		0.161	22.06	1	0
		16-QAM	-22.02	13.35	10.11	2.21	V		0.133	21.25		
		64-QAM	-22.97	12.40	10.11	2.21	V		0.107	20.30		
		256-QAM	-26.01	9.36	10.11	2.21	V		0.053	17.26		
1905.0		QPSK	-21.25	14.25	10.05	2.19	V		0.163	22.11	1	0
		16-QAM	-22.06	13.44	10.05	2.19	V		0.135	21.30		
		64-QAM	-22.98	12.52	10.05	2.19	V		0.109	20.38		
		256-QAM	-26.05	9.45	10.05	2.19	V		0.054	17.31		

Freq (MHz)	Mod/ Bandwidth	Modulation	Measured Level (dBm)	Substitute Level (dBm)	Ant. Gain (dBi)	C.L	Pol	Limit	EIRP		RB	
								W	W	dBm	Size	Offset
1857.5	LTE B2/ 15 MHz	QPSK	-21.57	13.55	10.14	2.10	V	<2.00	0.144	21.59	1	74
		16-QAM	-22.38	12.74	10.14	2.10	V		0.120	20.78		
		64-QAM	-23.32	11.80	10.14	2.10	V		0.096	19.84		
		256-QAM	-26.37	8.75	10.14	2.10	V		0.048	16.79		
1880.0		QPSK	-21.42	13.95	10.11	2.21	V		0.153	21.85	1	0
		16-QAM	-22.22	13.15	10.11	2.21	V		0.127	21.05		
		64-QAM	-23.25	12.12	10.11	2.21	V		0.100	20.02		
		256-QAM	-26.24	9.13	10.11	2.21	V		0.050	17.03		
1902.5		QPSK	-21.18	14.32	10.05	2.19	V		0.165	22.18	1	0
		16-QAM	-21.97	13.53	10.05	2.19	V		0.138	21.39		
		64-QAM	-23.00	12.50	10.05	2.19	V		0.109	20.36		
		256-QAM	-25.97	9.53	10.05	2.19	V		0.055	17.39		

Freq (MHz)	Mod/ Bandwidth	Modulation	Measured	Substitute	Ant. Gain (dBi)	C.L	Pol	Limit	EIRP		RB	
			Level (dBm)	Level (dBm)				W	W	dBm	Size	Offset
1860.0	LTE B2/ 20 MHz	QPSK	-21.70	13.42	10.14	2.10	V	<2.00	0.140	21.46	1	99
		16-QAM	-22.51	12.61	10.14	2.10	V		0.116	20.65		
		64-QAM	-23.55	11.57	10.14	2.10	V		0.091	19.61		
		256-QAM	-26.55	8.57	10.14	2.10	V		0.046	16.61		
1880.0		QPSK	-21.55	13.82	10.11	2.21	V		0.149	21.72	1	0
		16-QAM	-22.38	12.99	10.11	2.21	V		0.123	20.89		
		64-QAM	-23.35	12.02	10.11	2.21	V		0.098	19.92		
		256-QAM	-26.40	8.97	10.11	2.21	V		0.049	16.87		
1900.0		QPSK	-21.43	14.06	10.08	2.20	V		0.156	21.94	1	0
		16-QAM	-22.22	13.27	10.08	2.20	V		0.130	21.15		
		64-QAM	-23.26	12.23	10.08	2.20	V		0.103	20.11		
		256-QAM	-26.23	9.26	10.08	2.20	V		0.052	17.14		

9.2 RADIATED SPURIOUS EMISSIONS

■ MODE: LTE B2
 ■ MODULATION SIGNAL: 5 MHz QPSK
 ■ DISTANCE: 3 meters
 ■ LIMIT: -13 dBm

Ch	Freq (MHz)	Measured Level (dBm)	Ant. Gain (dBi)	Substitute Level (dBm)	C.L	Pol	Result (dBm)	RB	
								Size	Offset
18625 (1852.5)	3 705.00	-55.36	11.82	-62.86	3.08	V	-54.12	1	24
	5 557.50	-56.52	12.07	-58.13	3.88	V	-49.94		
	7 410.00	-54.73	11.09	-50.79	4.57	V	-44.27		
18900 (1880.0)	3 760.00	-55.32	11.61	-61.81	3.12	V	-53.32	1	0
	5 640.00	-56.00	12.03	-57.06	3.92	V	-48.95		
	7 520.00	-57.26	11.49	-53.57	4.61	V	-46.69		
19175 (1907.5)	3 815.00	-54.73	11.34	-61.03	3.20	V	-52.89	1	0
	5 722.50	-55.90	11.82	-56.69	4.00	V	-48.87		
	7 630.00	-55.65	11.56	-51.69	4.66	V	-44.79		

9.3 PEAK-TO-AVERAGE RATIO

Band	Band Width	Frequency (MHz)	Modulation	Resource Block Size	Resource Block Offset	Data (dB)
2	1.4 MHz	1880.0	QPSK	6	0	5.20
			16-QAM			5.94
			64-QAM			6.35
			256-QAM			6.40
	3 MHz		QPSK	15		5.34
			16-QAM			6.01
			64-QAM			6.36
			256-QAM			6.53
	5 MHz		QPSK	25		5.28
			16-QAM			6.00
			64-QAM			6.40
			256-QAM			6.56
	10 MHz		QPSK	50		5.36
			16-QAM			6.04
			64-QAM			6.44
			256-QAM			6.57
	15 MHz		QPSK	75		5.33
			16-QAM			6.03
			64-QAM			6.40
			256-QAM			6.59
	20 MHz		QPSK	100		5.33
			16-QAM			6.04
			64-QAM			6.45
			256-QAM			6.66

Note:

1. Plots of the EUT's Peak- to- Average Ratio are shown Page 200 ~ 223.

9.4 OCCUPIED BANDWIDTH

Band	Band Width	Frequency (MHz)	Modulation	Resource Block Size	Resource Block Offset	Data (MHz)
2	1.4 MHz	1880.0	QPSK	6	0	1.1000
			16-QAM			1.0966
			64-QAM			1.0980
			256-QAM			1.0957
	3 MHz		QPSK	15		2.7192
			16-QAM			2.7068
			64-QAM			2.7093
			256-QAM			2.7129
	5 MHz		QPSK	25		4.5357
			16-QAM			4.5041
			64-QAM			4.5114
			256-QAM			4.5386
	10 MHz		QPSK	50		9.0259
			16-QAM			9.0267
			64-QAM			9.0193
			256-QAM			9.0312
	15 MHz		QPSK	75		13.494
			16-QAM			13.513
			64-QAM			13.514
			256-QAM			13.483
	20 MHz		QPSK	100		17.999
			16-QAM			17.983
			64-QAM			17.976
			256-QAM			17.996

Note:

1. Plots of the EUT's Occupied Bandwidth are shown Page 224 ~ 247.

9.5 CONDUCTED SPURIOUS EMISSIONS

Band	Band Width (MHz)	Frequency (MHz)	Frequency of Maximum Harmonic (GHz)	Factor (dB)	Measurement Maximum Data (dBm)	Result (dBm)	Limit (dBm)
2	1.4	1850.7	6.5803	28.591	-68.143	-39.552	-13.00
		1880.0	3.6591	27.976	-67.955	-39.979	
		1909.3	5.6930	28.591	-68.446	-39.855	
	3	1851.5	0.8874	25.270	-67.316	-42.046	
		1880.0	0.8874	25.270	-65.927	-40.657	
		1908.5	3.6691	27.976	-67.784	-39.808	
	5	1852.5	3.0310	27.976	-67.113	-39.137	
		1880.0	0.8874	25.270	-65.875	-40.605	
		1907.5	3.6491	27.976	-67.400	-39.424	
	10	1855.0	0.8874	25.270	-66.487	-41.217	
		1880.0	3.0409	27.976	-67.593	-39.617	
		1905.0	0.8874	25.270	-67.244	-41.974	
	15	1857.5	0.8874	25.270	-67.441	-42.171	
		1880.0	0.8974	25.270	-67.441	-42.171	
		1902.5	0.8874	25.270	-65.542	-40.272	
	20	1860.0	0.8874	25.270	-65.656	-40.386	
		1880.0	0.7179	25.270	-63.370	-38.100	
		1900.0	0.8874	25.270	-66.310	-41.040	

Note:

1. Plots of the EUT's Conducted Spurious Emissions are shown Page 248 ~ 283.
2. Conducted Spurious Emissions was Tested QPSK Modulation, Resource Block Size 1 and Resource Block Offset 0
3. Result (dBm) = Measurement Maximum Data (dBm) + Factor (dB)
4. Factor (dB) = Cable Loss + Attenuator + Power Splitter

Frequency Range (GHz)	Factor [dB]
0.03 – 1	25.270
1 – 5	27.976
5 – 10	28.591
10 – 15	29.116
15 – 20	29.489
Above 20(26.5)	30.131

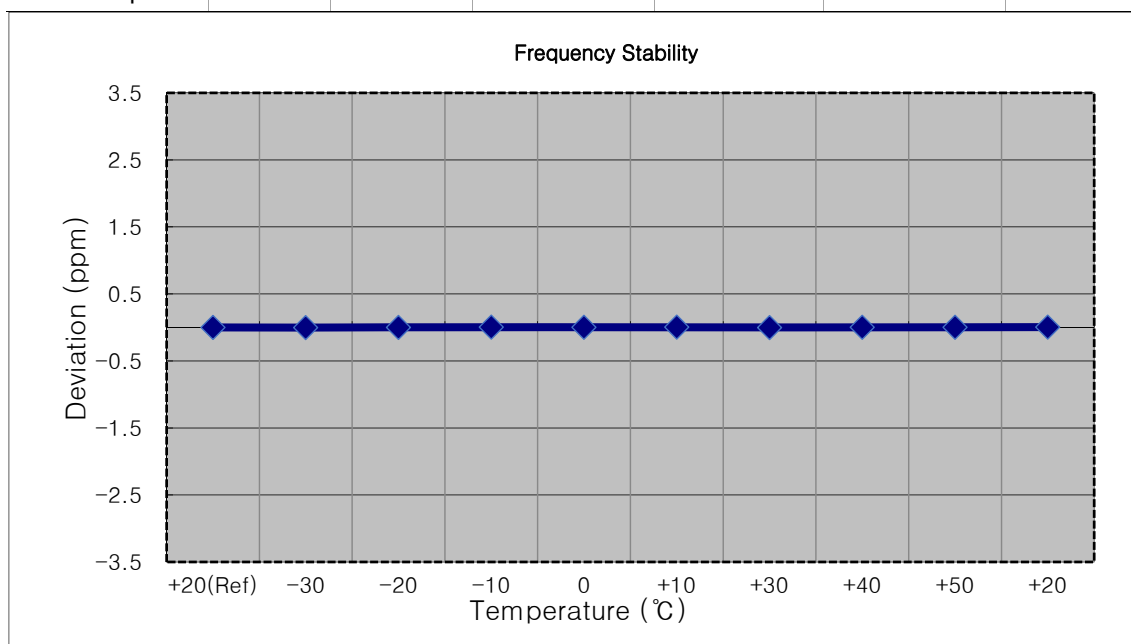
9.6 BAND EDGE

- Plots of the EUT's Band Edge are shown Page 284 ~ 319.

9.7 FREQUENCY STABILITY / VARIATION OF AMBIENT TEMPERATURE

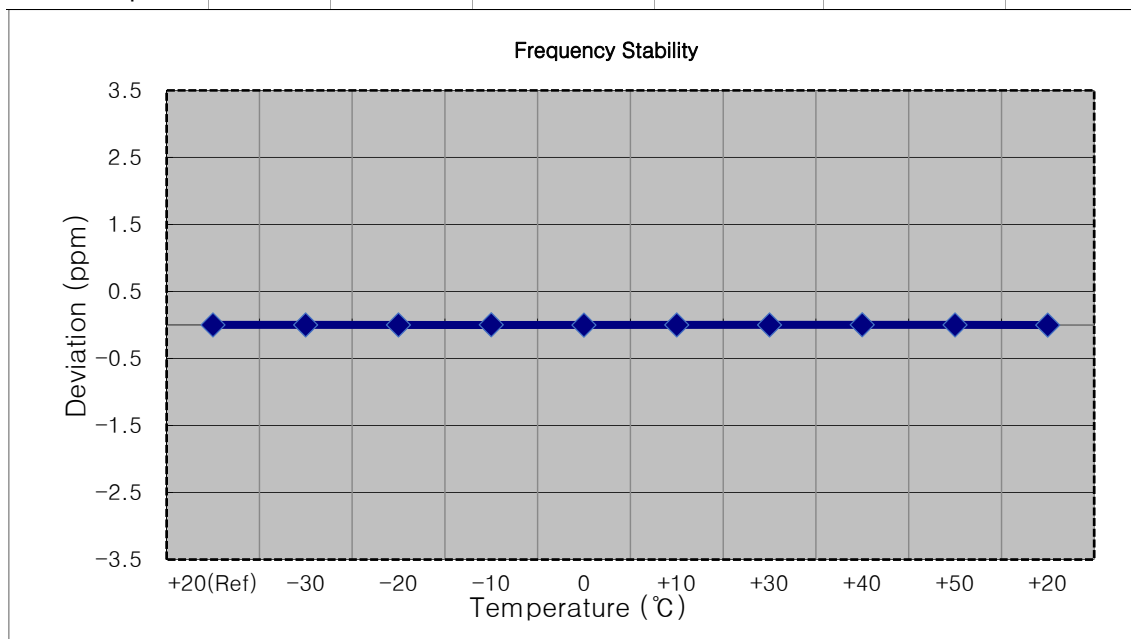
MODE:	LTE B2
OPERATING FREQUENCY:	1850,700,000 Hz
CHANNEL:	18607 (1.4 MHz)
REFERENCE VOLTAGE:	4.200 VDC
DEVIATION LIMIT:	Emission must remain in band

Voltage (%)	Power (VDC)	Temp. (°C)	Frequency (Hz)	Frequency Error (Hz)	Deviation (%)	ppm
100 %	4.200	+20(Ref)	1850 699 997	0.0	0.000 000	0.000
100 %		-30	1850 699 991	-5.9	0.000 000	-0.003
100 %		-20	1850 699 994	-2.9	0.000 000	-0.002
100 %		-10	1850 700 004	6.9	0.000 000	0.004
100 %		0	1850 700 000	3.2	0.000 000	0.002
100 %		+10	1850 700 004	7.2	0.000 000	0.004
100 %		+30	1850 699 991	-5.7	0.000 000	-0.003
100 %		+40	1850 699 999	2.6	0.000 000	0.001
100 %		+50	1850 699 999	2.1	0.000 000	0.001
Batt. Endpoint	3.400	+20	1850 700 003	5.9	0.000 000	0.003



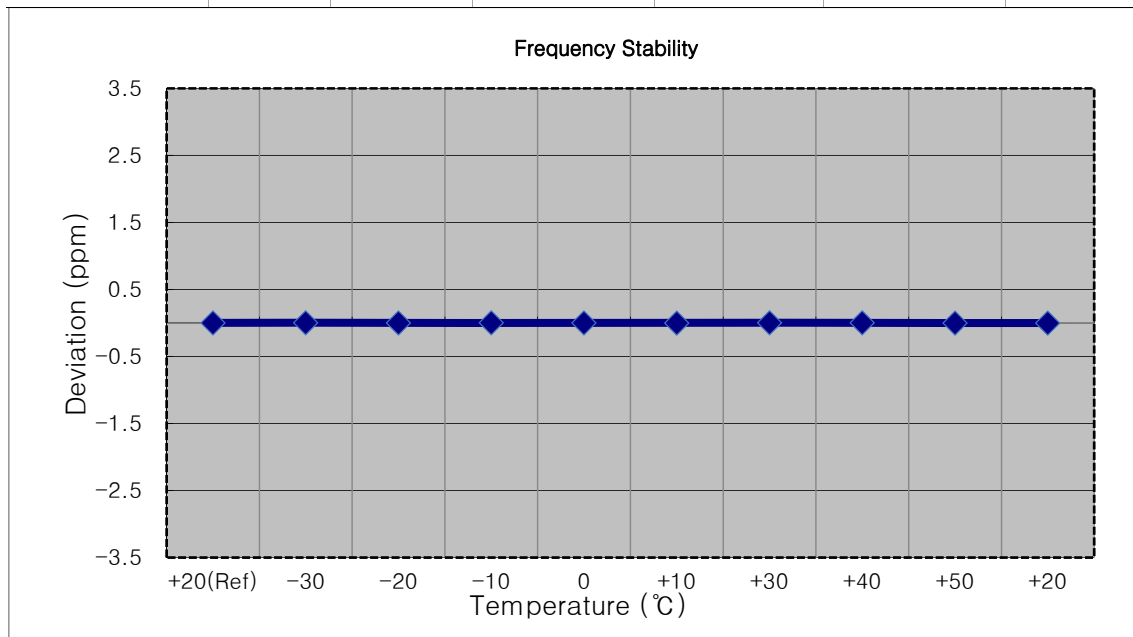
- ▣ MODE: LTE B2
- ▣ OPERATING FREQUENCY: 1851,500,000 Hz
- ▣ CHANNEL: 18615 (3 MHz)
- ▣ REFERENCE VOLTAGE: 4.200 VDC
- ▣ DEVIATION LIMIT: Emission must remain in band

Voltage (%)	Power (VDC)	Temp. (°C)	Frequency (Hz)	Frequency Error (Hz)	Deviation (%)	ppm
100 %	4.200	+20(Ref)	1851 500 002	0.0	0.000 000	0.000
100 %		-30	1851 500 004	2.0	0.000 000	0.001
100 %		-20	1851 500 004	2.3	0.000 000	0.001
100 %		-10	1851 500 005	3.0	0.000 000	0.002
100 %		0	1851 499 997	-5.1	0.000 000	-0.003
100 %		+10	1851 500 005	2.5	0.000 000	0.001
100 %		+30	1851 500 004	2.2	0.000 000	0.001
100 %		+40	1851 500 005	2.8	0.000 000	0.002
100 %		+50	1851 500 001	-1.4	0.000 000	-0.001
Batt. Endpoint	3.400	+20	1851 499 999	-3.0	0.000 000	-0.002



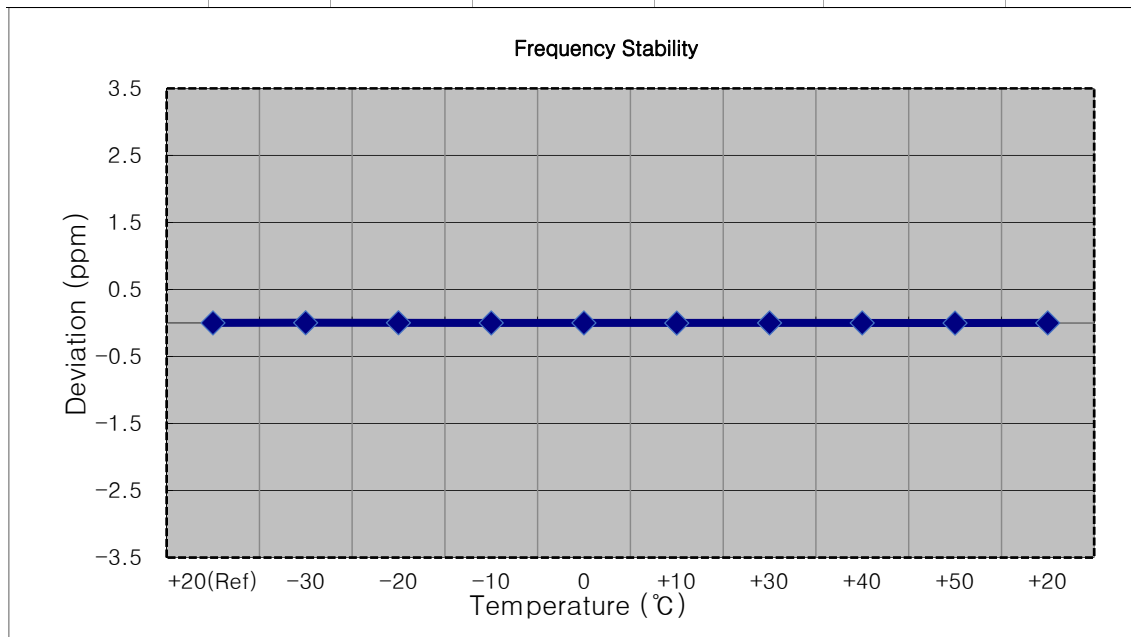
- ▣ MODE: LTE B2
- ▣ OPERATING FREQUENCY: 1852,500,000 Hz
- ▣ CHANNEL: 18625 (5 MHz)
- ▣ REFERENCE VOLTAGE: 4.200 VDC
- ▣ DEVIATION LIMIT: Emission must remain in band

Voltage (%)	Power (VDC)	Temp. (°C)	Frequency (Hz)	Frequency Error (Hz)	Deviation (%)	ppm
100 %	4.200	+20(Ref)	1852 500 003	0.0	0.000 000	0.000
100 %		-30	1852 500 005	2.8	0.000 000	0.002
100 %		-20	1852 500 005	2.5	0.000 000	0.001
100 %		-10	1852 500 006	3.3	0.000 000	0.002
100 %		0	1852 500 005	2.3	0.000 000	0.001
100 %		+10	1852 499 999	-4.0	0.000 000	-0.002
100 %		+30	1852 500 006	3.2	0.000 000	0.002
100 %		+40	1852 500 006	3.0	0.000 000	0.002
100 %		+50	1852 500 000	-2.8	0.000 000	-0.002
Batt. Endpoint	3.400	+20	1852 500 000	-3.0	0.000 000	-0.002



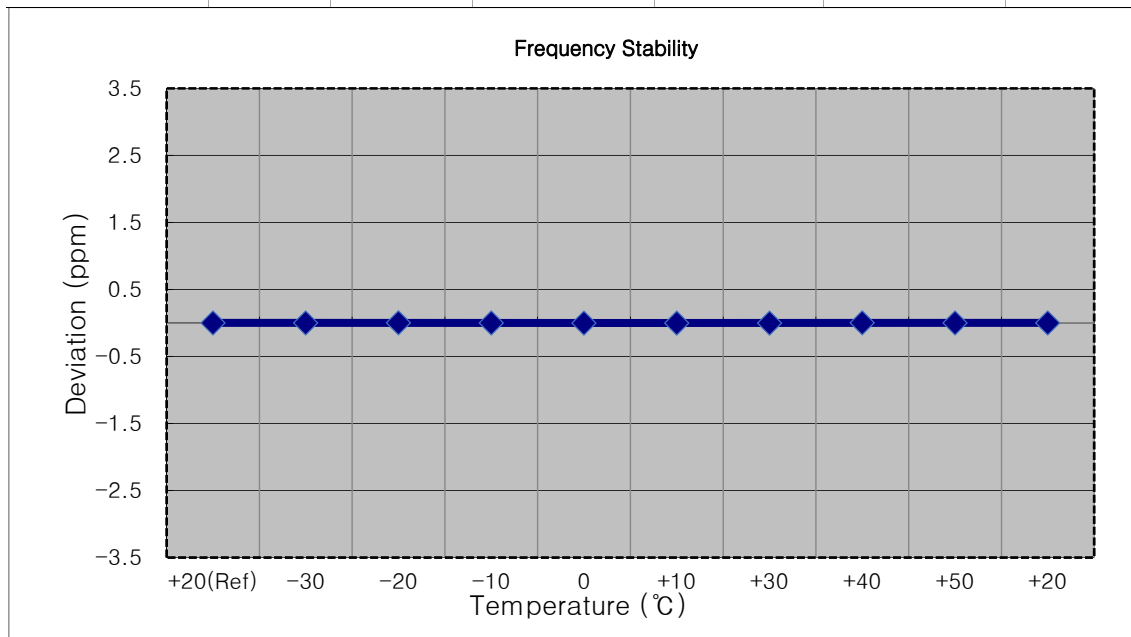
- ▣ MODE: LTE B2
- ▣ OPERATING FREQUENCY: 1855,000,000 Hz
- ▣ CHANNEL: 18650 (10 MHz)
- ▣ REFERENCE VOLTAGE: 4.200 VDC
- ▣ DEVIATION LIMIT: Emission must remain in band

Voltage (%)	Power (VDC)	Temp. (°C)	Frequency (Hz)	Frequency Error (Hz)	Deviation (%)	ppm
100 %	4.200	+20(Ref)	1855 000 003	0.0	0.000 000	0.000
100 %		-30	1855 000 006	3.4	0.000 000	0.002
100 %		-20	1855 000 006	3.5	0.000 000	0.002
100 %		-10	1855 000 005	2.4	0.000 000	0.001
100 %		0	1855 000 005	2.5	0.000 000	0.001
100 %		+10	1854 999 999	-3.6	0.000 000	-0.002
100 %		+30	1855 000 005	2.1	0.000 000	0.001
100 %		+40	1855 000 001	-1.6	0.000 000	-0.001
100 %		+50	1855 000 000	-2.5	0.000 000	-0.001
Batt. Endpoint	3.400	+20	1855 000 004	1.8	0.000 000	0.001



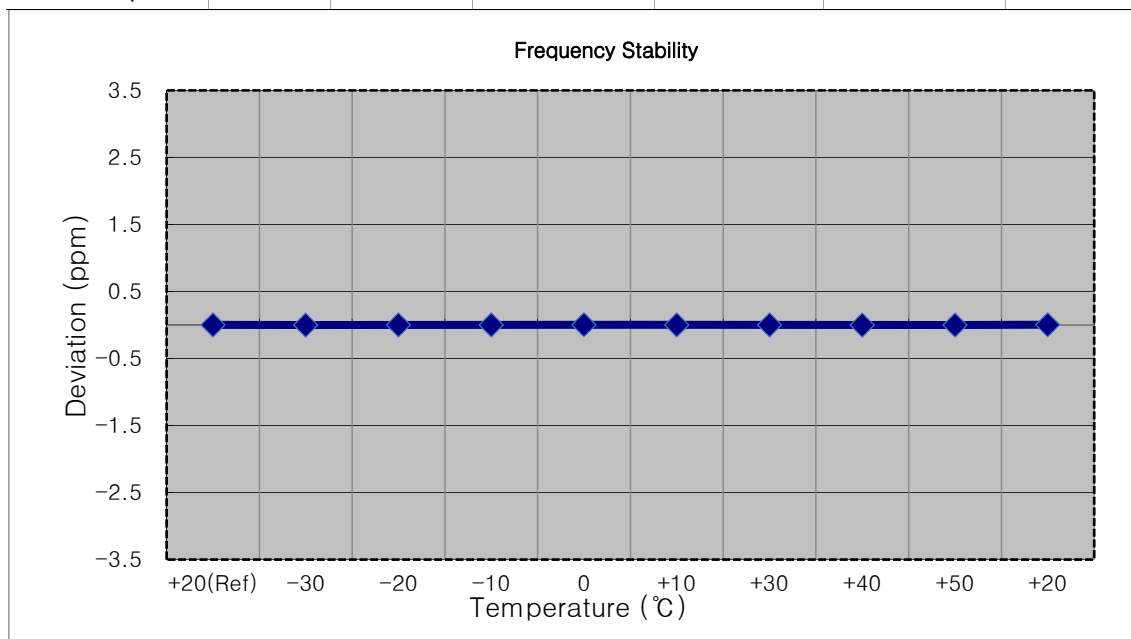
MODE:	<u>LTE B2</u>
OPERATING FREQUENCY:	<u>1857,500,000 Hz</u>
CHANNEL:	<u>18675 (15 MHz)</u>
REFERENCE VOLTAGE:	<u>4.200 VDC</u>
DEVIATION LIMIT:	<u>Emission must remain in band</u>

Voltage (%)	Power (VDC)	Temp. (°C)	Frequency (Hz)	Frequency Error (Hz)	Deviation (%)	ppm
100 %	4.200	+20(Ref)	1857 500 001	0.0	0.000 000	0.000
100 %		-30	1857 500 003	1.9	0.000 000	0.001
100 %		-20	1857 500 005	3.3	0.000 000	0.002
100 %		-10	1857 500 003	1.5	0.000 000	0.001
100 %		0	1857 499 999	-2.3	0.000 000	-0.001
100 %		+10	1857 499 999	-2.3	0.000 000	-0.001
100 %		+30	1857 499 999	-2.1	0.000 000	-0.001
100 %		+40	1857 500 004	2.8	0.000 000	0.002
100 %		+50	1857 500 004	2.5	0.000 000	0.001
Batt. Endpoint	3.400	+20	1857 500 003	1.8	0.000 000	0.001



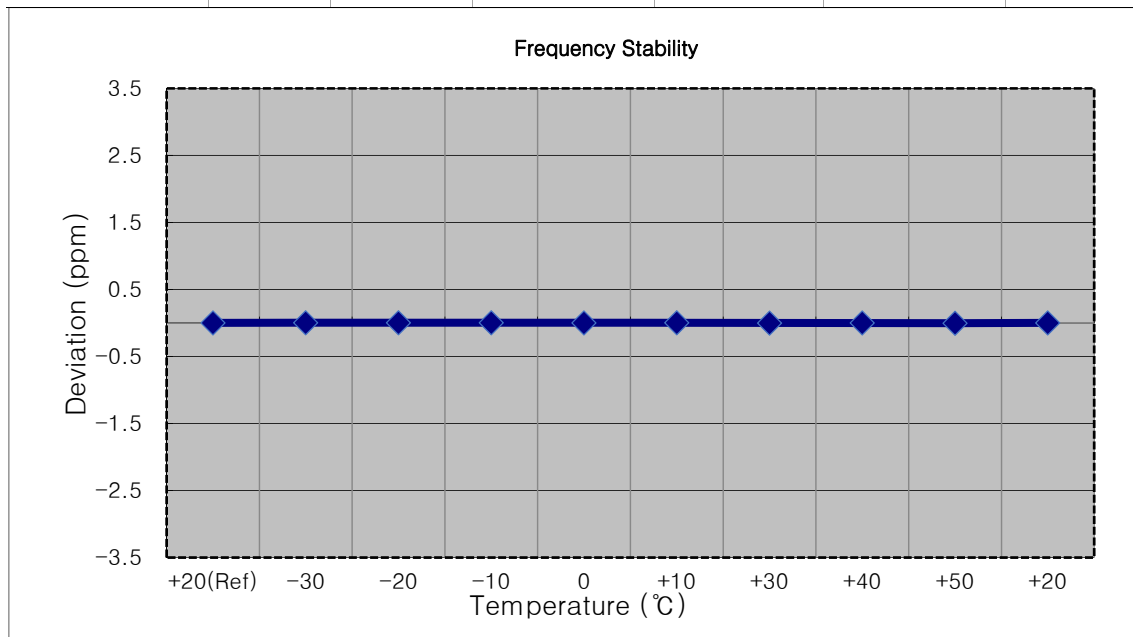
- ▣ MODE: LTE B2
- ▣ OPERATING FREQUENCY: 1860,000,000 Hz
- ▣ CHANNEL: 18700 (20 MHz)
- ▣ REFERENCE VOLTAGE: 4.200 VDC
- ▣ DEVIATION LIMIT: Emission must remain in band

Voltage (%)	Power (VDC)	Temp. (°C)	Frequency (Hz)	Frequency Error (Hz)	Deviation (%)	ppm
100 %	4.200	+20(Ref)	1859 999 997	0.0	0.000 000	0.000
100 %		-30	1859 999 994	-2.9	0.000 000	-0.002
100 %		-20	1859 999 999	2.0	0.000 000	0.001
100 %		-10	1859 999 996	-1.1	0.000 000	-0.001
100 %		0	1860 000 000	3.0	0.000 000	0.002
100 %		+10	1859 999 999	1.9	0.000 000	0.001
100 %		+30	1859 999 999	1.7	0.000 000	0.001
100 %		+40	1859 999 995	-2.3	0.000 000	-0.001
100 %		+50	1859 999 995	-1.9	0.000 000	-0.001
Batt. Endpoint	3.400	+20	1860 000 000	2.8	0.000 000	0.002



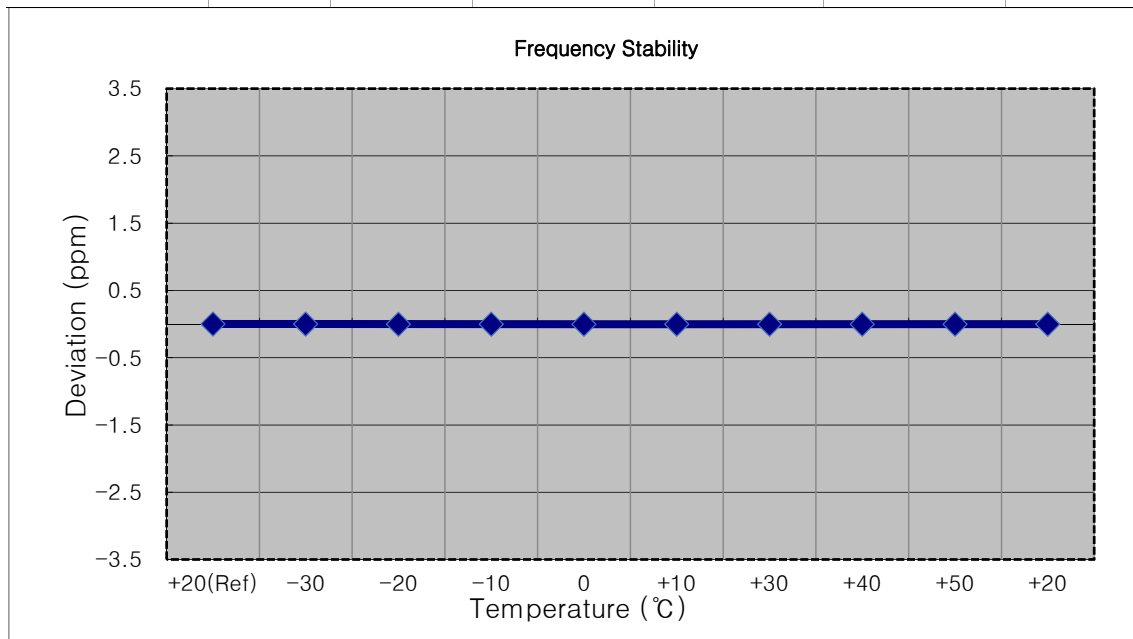
- ▣ MODE: LTE B2
- ▣ OPERATING FREQUENCY: 1880,000,000 Hz
- ▣ CHANNEL: 18900 (1.4 MHz)
- ▣ REFERENCE VOLTAGE: 4.200 VDC
- ▣ DEVIATION LIMIT: Emission must remain in band

Voltage (%)	Power (VDC)	Temp. (°C)	Frequency (Hz)	Frequency Error (Hz)	Deviation (%)	ppm
100 %	4.200	+20(Ref)	1879 999 998	0.0	0.000 000	0.000
100 %		-30	1880 000 005	7.2	0.000 000	0.004
100 %		-20	1880 000 003	5.4	0.000 000	0.003
100 %		-10	1880 000 002	4.0	0.000 000	0.002
100 %		0	1880 000 000	1.9	0.000 000	0.001
100 %		+10	1880 000 001	3.5	0.000 000	0.002
100 %		+30	1879 999 993	-4.5	0.000 000	-0.002
100 %		+40	1880 000 001	2.7	0.000 000	0.001
100 %		+50	1879 999 991	-7.3	0.000 000	-0.004
Batt. Endpoint	3.400	+20	1880 000 000	2.0	0.000 000	0.001



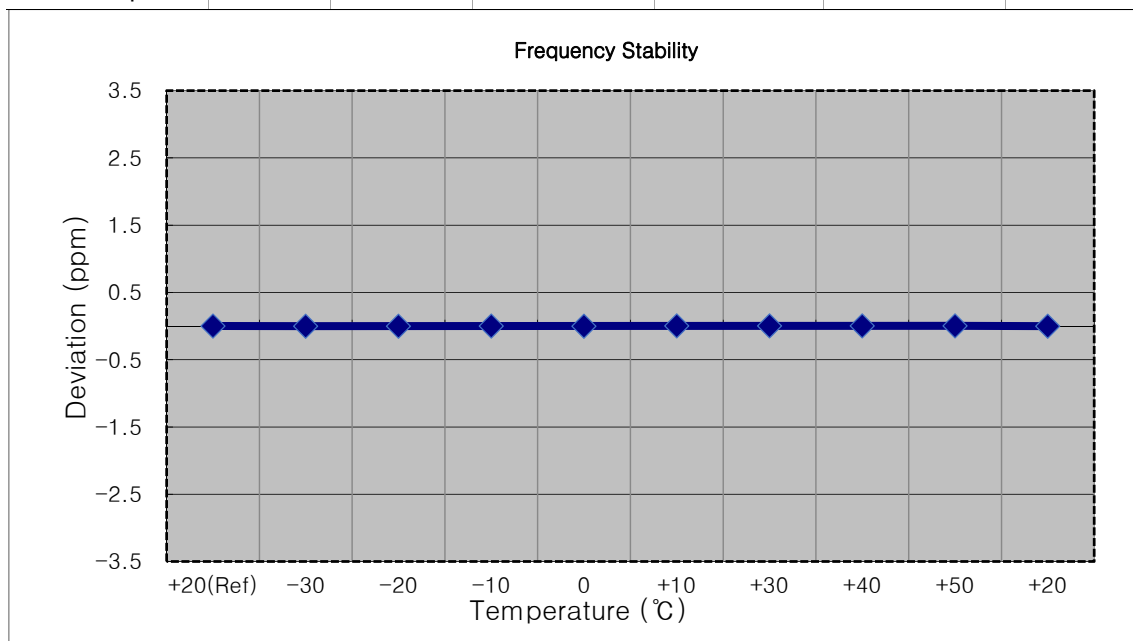
- ▣ MODE: LTE B2
- ▣ OPERATING FREQUENCY: 1880,000,000 Hz
- ▣ CHANNEL: 18900 (3 MHz)
- ▣ REFERENCE VOLTAGE: 4.200 VDC
- ▣ DEVIATION LIMIT: Emission must remain in band

Voltage (%)	Power (VDC)	Temp. (°C)	Frequency (Hz)	Frequency Error (Hz)	Deviation (%)	ppm
100 %	4.200	+20(Ref)	1879 999 997	0.0	0.000 000	0.000
100 %		-30	1880 000 000	2.7	0.000 000	0.001
100 %		-20	1879 999 992	-4.8	0.000 000	-0.003
100 %		-10	1879 999 993	-3.8	0.000 000	-0.002
100 %		0	1879 999 992	-4.7	0.000 000	-0.003
100 %		+10	1879 999 994	-3.2	0.000 000	-0.002
100 %		+30	1879 999 994	-3.0	0.000 000	-0.002
100 %		+40	1879 999 992	-4.8	0.000 000	-0.003
100 %		+50	1879 999 993	-3.9	0.000 000	-0.002
Batt. Endpoint	3.400	+20	1879 999 994	-3.0	0.000 000	-0.002



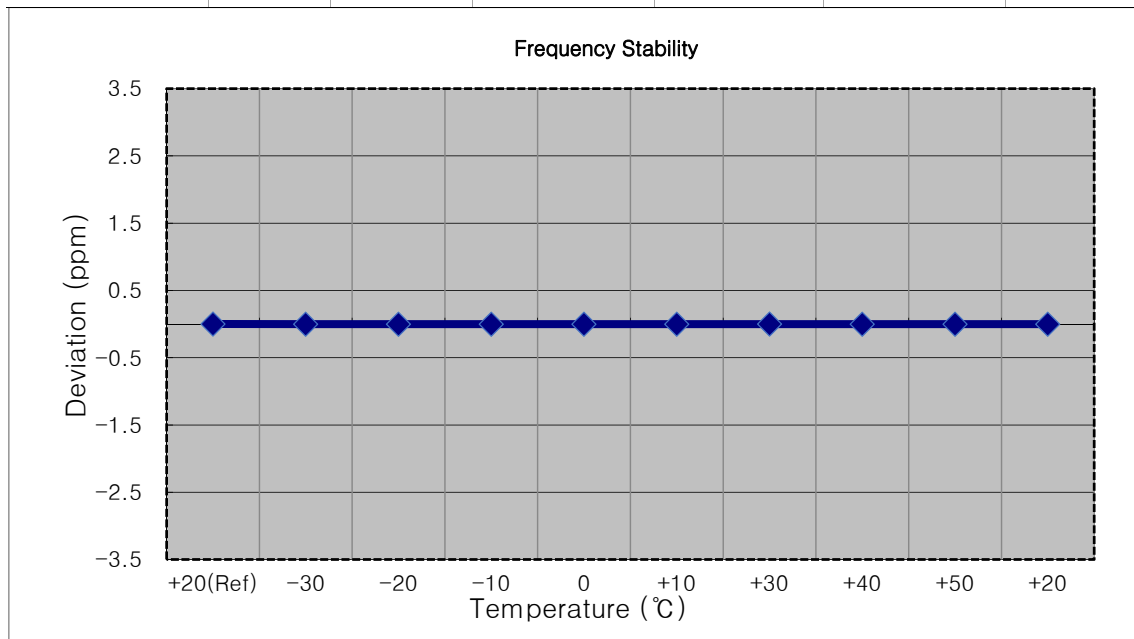
- ▣ MODE: LTE B2
- ▣ OPERATING FREQUENCY: 1880,000,000 Hz
- ▣ CHANNEL: 18900 (5 MHz)
- ▣ REFERENCE VOLTAGE: 4.200 VDC
- ▣ DEVIATION LIMIT: Emission must remain in band

Voltage (%)	Power (VDC)	Temp. (°C)	Frequency (Hz)	Frequency Error (Hz)	Deviation (%)	ppm
100 %	4.200	+20(Ref)	1880 000 003	0.0	0.000 000	0.000
100 %		-30	1880 000 000	-2.9	0.000 000	-0.002
100 %		-20	1880 000 000	-3.3	0.000 000	-0.002
100 %		-10	1880 000 005	2.0	0.000 000	0.001
100 %		0	1880 000 000	-2.6	0.000 000	-0.001
100 %		+10	1880 000 009	5.8	0.000 000	0.003
100 %		+30	1880 000 009	5.5	0.000 000	0.003
100 %		+40	1880 000 006	3.2	0.000 000	0.002
100 %		+50	1880 000 006	3.4	0.000 000	0.002
Batt. Endpoint	3.400	+20	1880 000 001	-2.4	0.000 000	-0.001



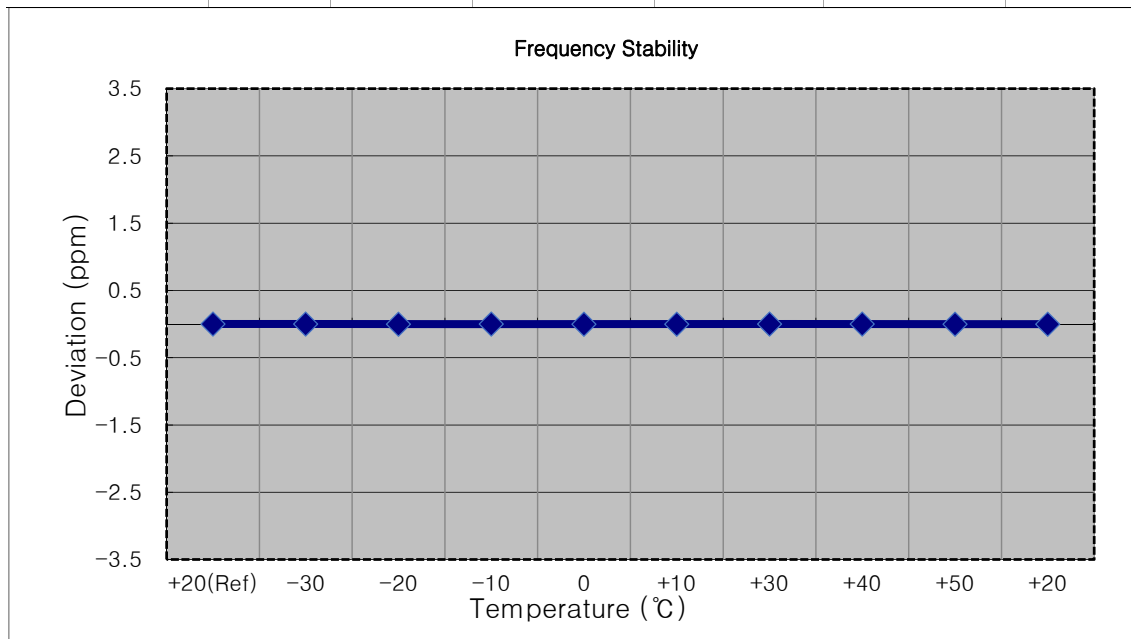
- ▣ MODE: LTE B2
- ▣ OPERATING FREQUENCY: 1880,000,000 Hz
- ▣ CHANNEL: 18900 (10 MHz)
- ▣ REFERENCE VOLTAGE: 4.200 VDC
- ▣ DEVIATION LIMIT: Emission must remain in band

Voltage (%)	Power (VDC)	Temp. (°C)	Frequency (Hz)	Frequency Error (Hz)	Deviation (%)	ppm
100 %	4.200	+20(Ref)	1880 000 002	0.0	0.000 000	0.000
100 %		-30	1879 999 999	-2.5	0.000 000	-0.001
100 %		-20	1879 999 999	-3.1	0.000 000	-0.002
100 %		-10	1879 999 999	-2.6	0.000 000	-0.001
100 %		0	1879 999 997	-4.9	0.000 000	-0.003
100 %		+10	1879 999 999	-3.4	0.000 000	-0.002
100 %		+30	1880 000 004	1.7	0.000 000	0.001
100 %		+40	1879 999 999	-2.7	0.000 000	-0.001
100 %		+50	1879 999 999	-2.8	0.000 000	-0.001
Batt. Endpoint	3.400	+20	1880 000 000	-2.1	0.000 000	-0.001



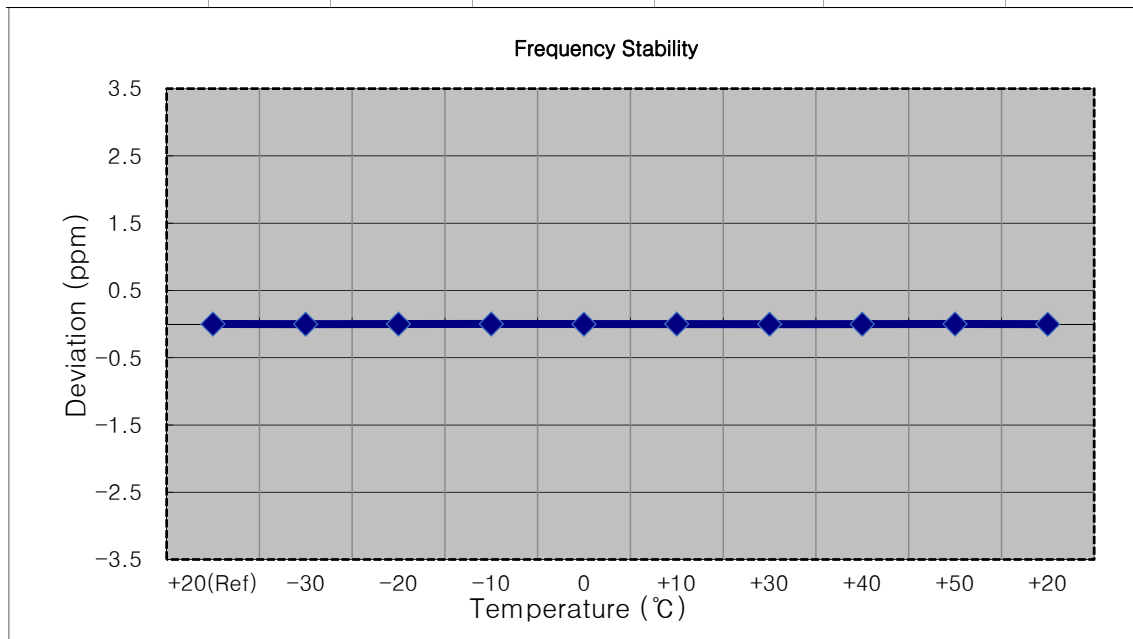
- ▣ MODE: LTE B2
- ▣ OPERATING FREQUENCY: 1880,000,000 Hz
- ▣ CHANNEL: 18900 (15 MHz)
- ▣ REFERENCE VOLTAGE: 4.200 VDC
- ▣ DEVIATION LIMIT: Emission must remain in band

Voltage (%)	Power (VDC)	Temp. (°C)	Frequency (Hz)	Frequency Error (Hz)	Deviation (%)	ppm
100 %	4.200	+20(Ref)	1879 999 998	0.0	0.000 000	0.000
100 %		-30	1880 000 000	2.2	0.000 000	0.001
100 %		-20	1879 999 994	-3.7	0.000 000	-0.002
100 %		-10	1879 999 999	1.2	0.000 000	0.001
100 %		0	1879 999 996	-2.0	0.000 000	-0.001
100 %		+10	1879 999 996	-1.9	0.000 000	-0.001
100 %		+30	1879 999 996	-1.4	0.000 000	-0.001
100 %		+40	1879 999 999	0.9	0.000 000	0.000
100 %		+50	1879 999 995	-2.3	0.000 000	-0.001
Batt. Endpoint	3.400	+20	1879 999 995	-2.6	0.000 000	-0.001



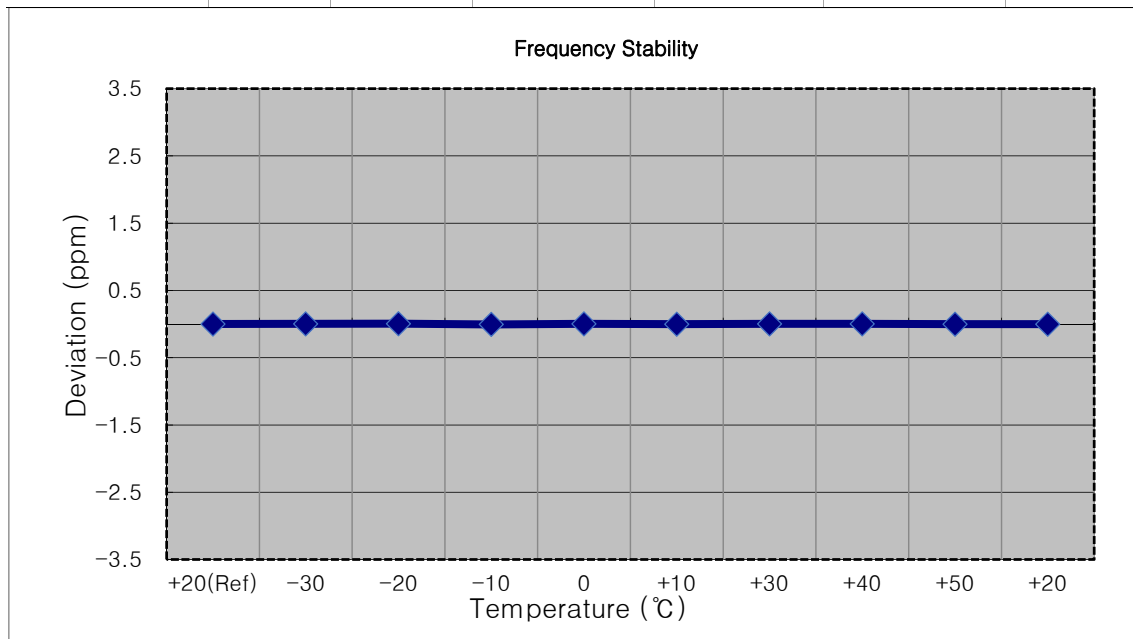
- ▣ MODE: LTE B2
- ▣ OPERATING FREQUENCY: 1880,000,000 Hz
- ▣ CHANNEL: 18900 (20 MHz)
- ▣ REFERENCE VOLTAGE: 4.200 VDC
- ▣ DEVIATION LIMIT: Emission must remain in band

Voltage (%)	Power (VDC)	Temp. (°C)	Frequency (Hz)	Frequency Error (Hz)	Deviation (%)	ppm
100 %	4.200	+20(Ref)	1879 999 999	0.0	0.000 000	0.000
100 %		-30	1879 999 997	-2.0	0.000 000	-0.001
100 %		-20	1880 000 001	2.7	0.000 000	0.001
100 %		-10	1880 000 000	1.2	0.000 000	0.001
100 %		0	1879 999 996	-2.6	0.000 000	-0.001
100 %		+10	1880 000 000	1.2	0.000 000	0.001
100 %		+30	1879 999 997	-2.2	0.000 000	-0.001
100 %		+40	1879 999 995	-3.8	0.000 000	-0.002
100 %		+50	1880 000 000	1.5	0.000 000	0.001
Batt. Endpoint	3.400	+20	1879 999 997	-1.9	0.000 000	-0.001



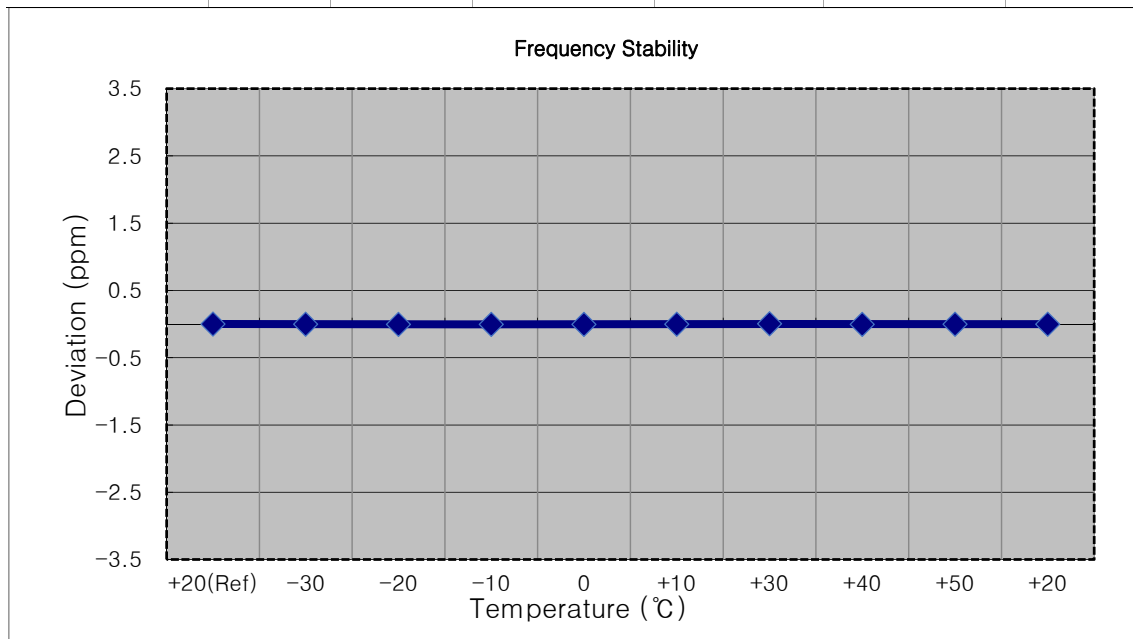
- ▣ MODE: LTE B2
- ▣ OPERATING FREQUENCY: 1909,300,000 Hz
- ▣ CHANNEL: 19193 (1.4 MHz)
- ▣ REFERENCE VOLTAGE: 4.200 VDC
- ▣ DEVIATION LIMIT: Emission must remain in band

Voltage (%)	Power (VDC)	Temp. (°C)	Frequency (Hz)	Frequency Error (Hz)	Deviation (%)	ppm
100 %	4.200	+20(Ref)	1909 299 992	0.0	0.000 000	0.000
100 %		-30	1909 299 998	5.9	0.000 000	0.003
100 %		-20	1909 300 003	10.8	0.000 001	0.006
100 %		-10	1909 299 983	-8.9	0.000 000	-0.005
100 %		0	1909 299 998	6.7	0.000 000	0.004
100 %		+10	1909 299 986	-5.9	0.000 000	-0.003
100 %		+30	1909 299 997	5.2	0.000 000	0.003
100 %		+40	1909 299 998	6.4	0.000 000	0.003
100 %		+50	1909 299 986	-5.4	0.000 000	-0.003
Batt. Endpoint	3.400	+20	1909 299 988	-3.4	0.000 000	-0.002



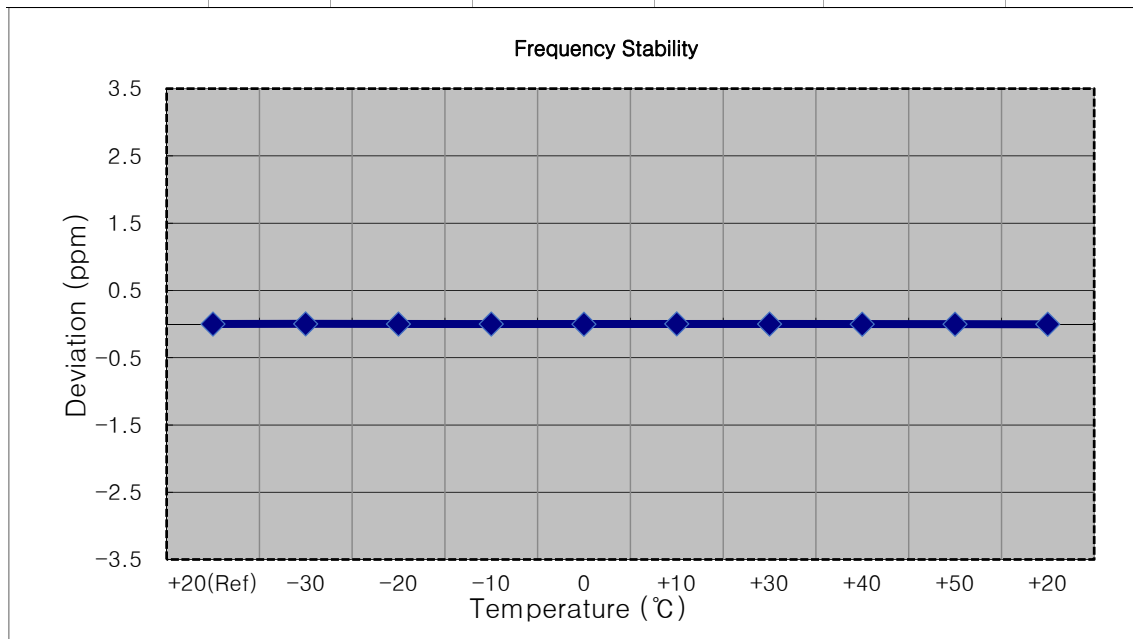
- ▣ MODE: LTE B2
- ▣ OPERATING FREQUENCY: 1908,500,000 Hz
- ▣ CHANNEL: 19185 (3 MHz)
- ▣ REFERENCE VOLTAGE: 4.200 VDC
- ▣ DEVIATION LIMIT: Emission must remain in band

Voltage (%)	Power (VDC)	Temp. (°C)	Frequency (Hz)	Frequency Error (Hz)	Deviation (%)	ppm
100 %	4.200	+20(Ref)	1908 499 992	0.0	0.000 000	0.000
100 %		-30	1908 499 987	-5.6	0.000 000	-0.003
100 %		-20	1908 499 985	-6.8	0.000 000	-0.004
100 %		-10	1908 499 985	-7.1	0.000 000	-0.004
100 %		0	1908 499 985	-7.7	0.000 000	-0.004
100 %		+10	1908 499 988	-4.3	0.000 000	-0.002
100 %		+30	1908 500 001	8.7	0.000 000	0.005
100 %		+40	1908 499 984	-8.3	0.000 000	-0.004
100 %		+50	1908 499 987	-5.6	0.000 000	-0.003
Batt. Endpoint	3.400	+20	1908 499 987	-5.6	0.000 000	-0.003



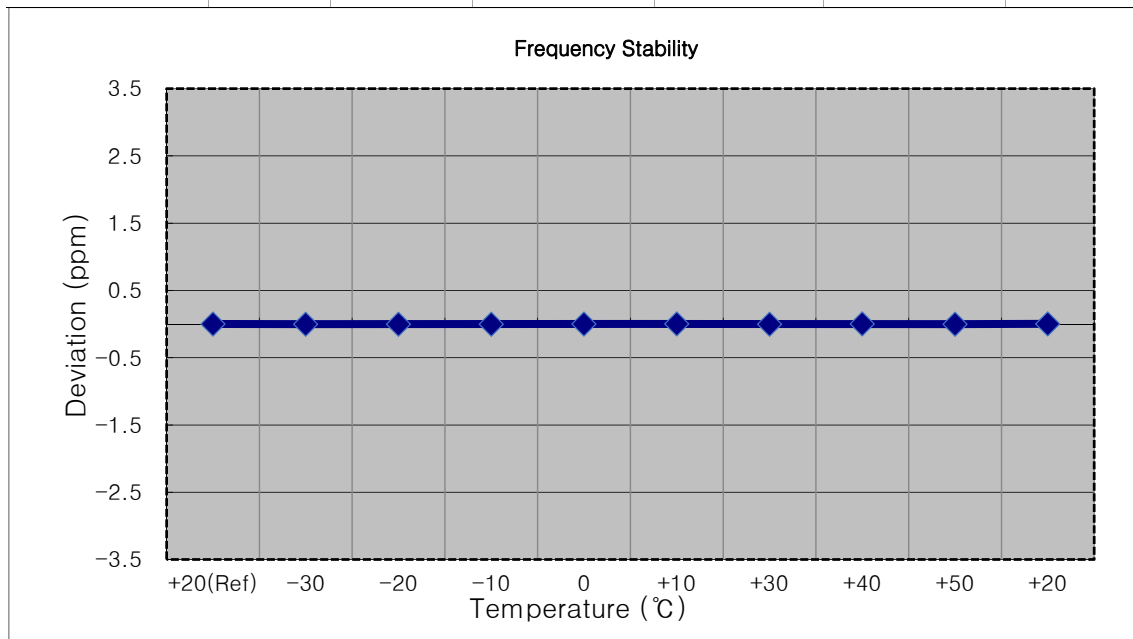
MODE:	<u>LTE B2</u>
OPERATING FREQUENCY:	<u>1907,500,000 Hz</u>
CHANNEL:	<u>19175 (5 MHz)</u>
REFERENCE VOLTAGE:	<u>4.200 VDC</u>
DEVIATION LIMIT:	<u>Emission must remain in band</u>

Voltage (%)	Power (VDC)	Temp. (°C)	Frequency (Hz)	Frequency Error (Hz)	Deviation (%)	ppm
100 %	4.200	+20(Ref)	1907 500 002	0.0	0.000 000	0.000
100 %		-30	1907 500 008	5.9	0.000 000	0.003
100 %		-20	1907 500 005	2.5	0.000 000	0.001
100 %		-10	1907 500 001	-1.7	0.000 000	-0.001
100 %		0	1907 500 000	-2.7	0.000 000	-0.001
100 %		+10	1907 500 006	4.2	0.000 000	0.002
100 %		+30	1907 500 004	1.7	0.000 000	0.001
100 %		+40	1907 500 000	-2.2	0.000 000	-0.001
100 %		+50	1907 499 999	-2.8	0.000 000	-0.001
Batt. Endpoint	3.400	+20	1907 499 998	-4.4	0.000 000	-0.002



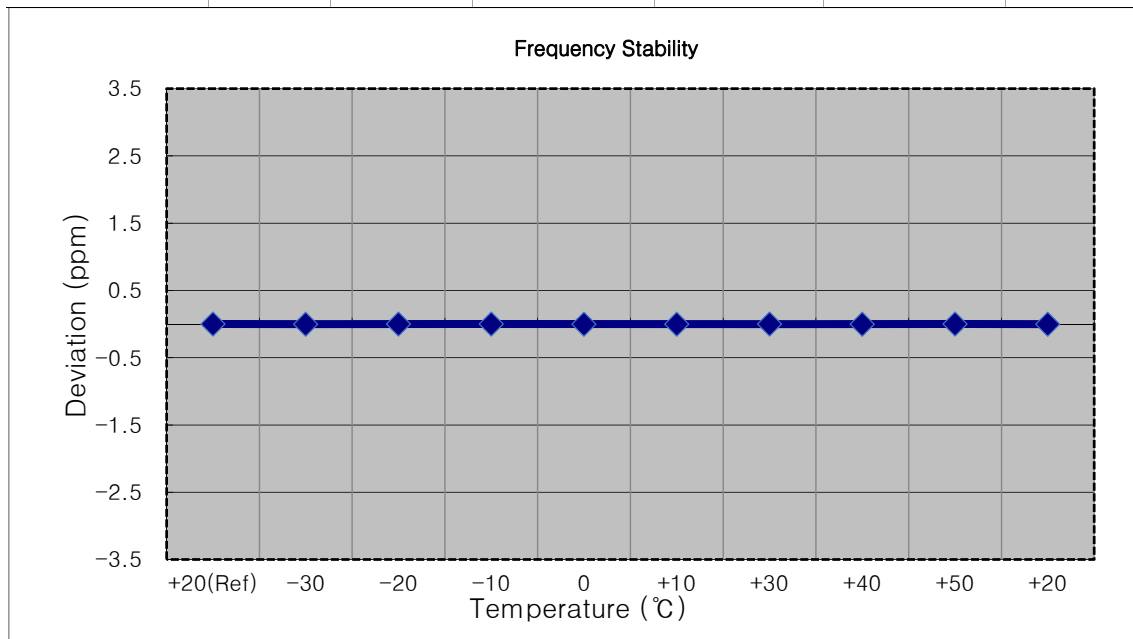
MODE:	<u>LTE B2</u>
OPERATING FREQUENCY:	<u>1905,000,000 Hz</u>
CHANNEL:	<u>19150 (10 MHz)</u>
REFERENCE VOLTAGE:	<u>4.200 VDC</u>
DEVIATION LIMIT:	<u>Emission must remain in band</u>

Voltage (%)	Power (VDC)	Temp. (°C)	Frequency (Hz)	Frequency Error (Hz)	Deviation (%)	ppm
100 %	4.200	+20(Ref)	1905 000 002	0.0	0.000 000	0.000
100 %		-30	1904 999 999	-2.9	0.000 000	-0.002
100 %		-20	1905 000 000	-2.1	0.000 000	-0.001
100 %		-10	1905 000 000	-2.2	0.000 000	-0.001
100 %		0	1905 000 005	2.7	0.000 000	0.001
100 %		+10	1905 000 005	3.2	0.000 000	0.002
100 %		+30	1904 999 999	-3.1	0.000 000	-0.002
100 %		+40	1905 000 006	4.4	0.000 000	0.002
100 %		+50	1905 000 000	-2.2	0.000 000	-0.001
Batt. Endpoint	3.400	+20	1905 000 005	3.2	0.000 000	0.002



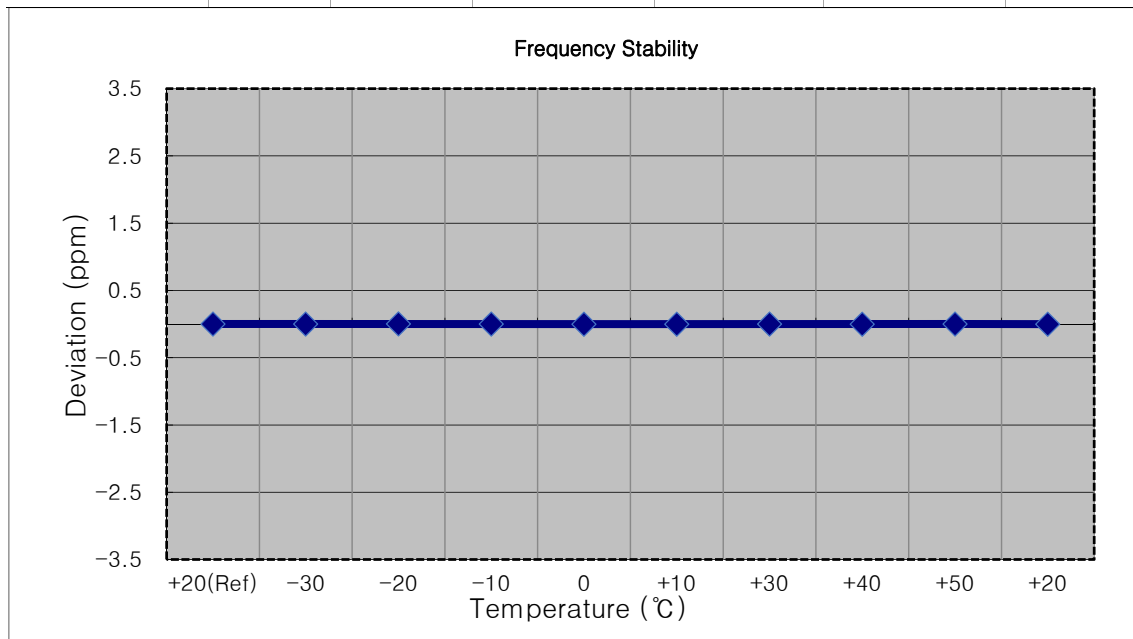
- ▣ MODE: LTE B2
- ▣ OPERATING FREQUENCY: 1902,500,000 Hz
- ▣ CHANNEL: 19125 (15 MHz)
- ▣ REFERENCE VOLTAGE: 4.200 VDC
- ▣ DEVIATION LIMIT: Emission must remain in band

Voltage (%)	Power (VDC)	Temp. (°C)	Frequency (Hz)	Frequency Error (Hz)	Deviation (%)	ppm
100 %	4.200	+20(Ref)	1902 500 002	0.0	0.000 000	0.000
100 %		-30	1902 499 999	-3.1	0.000 000	-0.002
100 %		-20	1902 500 000	-1.7	0.000 000	-0.001
100 %		-10	1902 500 004	2.0	0.000 000	0.001
100 %		0	1902 500 000	-2.4	0.000 000	-0.001
100 %		+10	1902 500 000	-2.2	0.000 000	-0.001
100 %		+30	1902 500 004	2.1	0.000 000	0.001
100 %		+40	1902 500 000	-2.1	0.000 000	-0.001
100 %		+50	1902 500 004	2.2	0.000 000	0.001
Batt. Endpoint	3.400	+20	1902 500 000	-2.3	0.000 000	-0.001



- ▣ MODE: LTE B2
- ▣ OPERATING FREQUENCY: 1900,000,000 Hz
- ▣ CHANNEL: 19100 (20 MHz)
- ▣ REFERENCE VOLTAGE: 4.200 VDC
- ▣ DEVIATION LIMIT: Emission must remain in band

Voltage (%)	Power (VDC)	Temp. (°C)	Frequency (Hz)	Frequency Error (Hz)	Deviation (%)	ppm
100 %	4.200	+20(Ref)	1899 999 998	0.0	0.000 000	0.000
100 %		-30	1899 999 996	-1.6	0.000 000	-0.001
100 %		-20	1900 000 001	3.4	0.000 000	0.002
100 %		-10	1900 000 000	1.5	0.000 000	0.001
100 %		0	1899 999 996	-2.1	0.000 000	-0.001
100 %		+10	1899 999 995	-3.5	0.000 000	-0.002
100 %		+30	1899 999 997	-1.5	0.000 000	-0.001
100 %		+40	1899 999 996	-1.9	0.000 000	-0.001
100 %		+50	1900 000 000	1.5	0.000 000	0.001
Batt. Endpoint	3.400	+20	1899 999 995	-3.2	0.000 000	-0.002



9.9 UPLINK CARRIER AGGREGATION

Test Note

1. All tests were evaluated for the two bands using various combinations of RB size, RB offset, modulation, and channel bandwidth.
2. All modes of operation were investigated and the worst case configuration results are reported in this section.

Please refer to the table below.

3. The worst case is reported with the modulations, RB sizes and offsets.

- 2A(Sub2 ant) - 4A(Main2 ant)

(PCC - Modulation: QPSK, RB: 1, RB Offset: 0, SCC - Modulation: QPSK, RB: 1, RB Offset: 74)

Radiated Spurious Emissions

PCC	SCC	PCC		SCC	
		BW(MHz)	Channel	BW(MHz)	Channel
2A(Sub ant)	4A(Main ant)	5	19175	10	20175

9.9.1 RADIATED SPURIOUS EMISSIONS

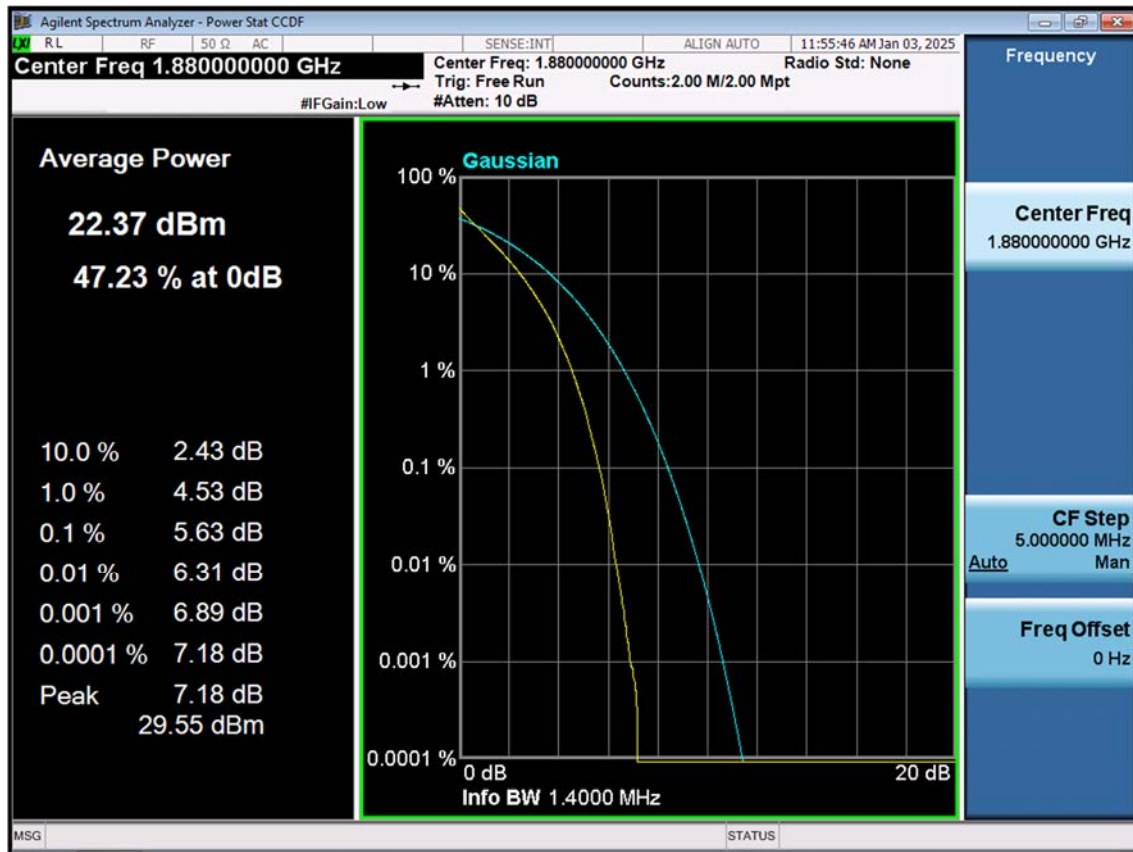
2A(Sub ant) (PCC) - 4A(Main ant) (SCC)

Freq.(MHz)	Measured Level [dBm]	Ant. Gain (dBi)	Substitute Level [dBm]	C.L	Pol.	Result (dBm)	Limit (dBm)
3 815.00	-44.41	12.16	-60.85	3.20	V	-51.89	-13.00
5 722.50	-45.28	13.05	-57.65	4.00	V	-48.60	-13.00
7 630.00	-45.42	11.18	-48.22	4.66	V	-41.70	-13.00

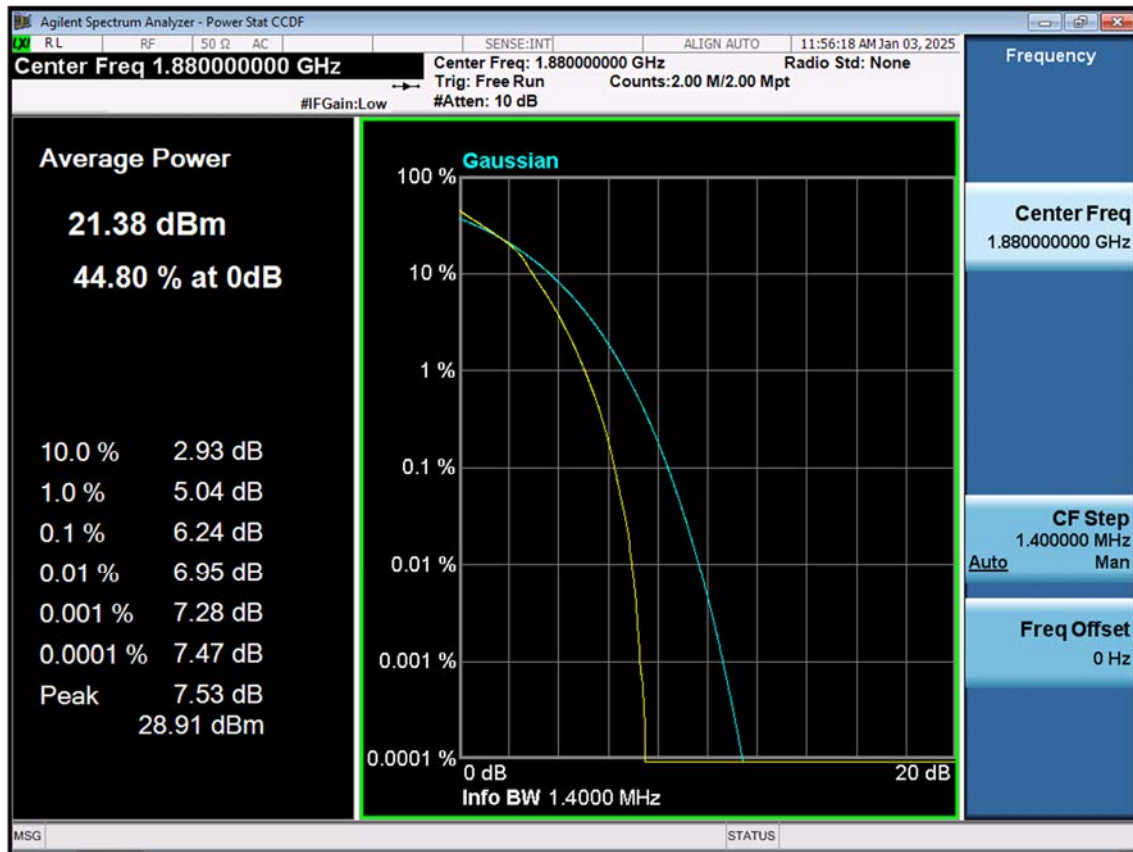
Freq.(MHz)	Measured Level [dBm]	Ant. Gain (dBi)	Substitute Level [dBm]	C.L	Pol.	Result (dBm)	Limit (dBm)
3 465.00	-45.19	12.34	-63.64	3.02	V	-54.32	-13.00
5 197.50	-44.28	12.63	-57.12	3.78	V	-48.27	-13.00
6 930.00	-45.93	11.65	-52.75	4.40	V	-45.50	-13.00

10. TEST PLOTS(Main 2 ANT)

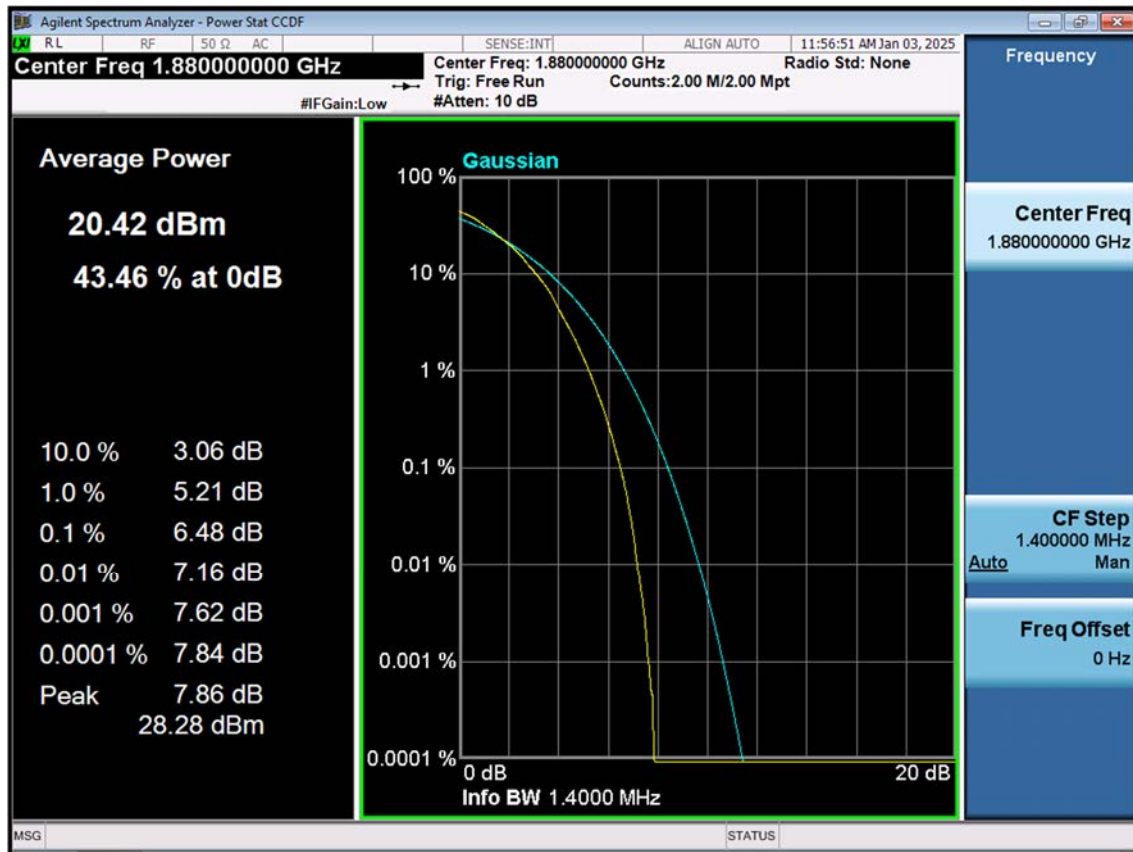
LTE B2_1.4M_PAR_Mid_QPSK_FullRB



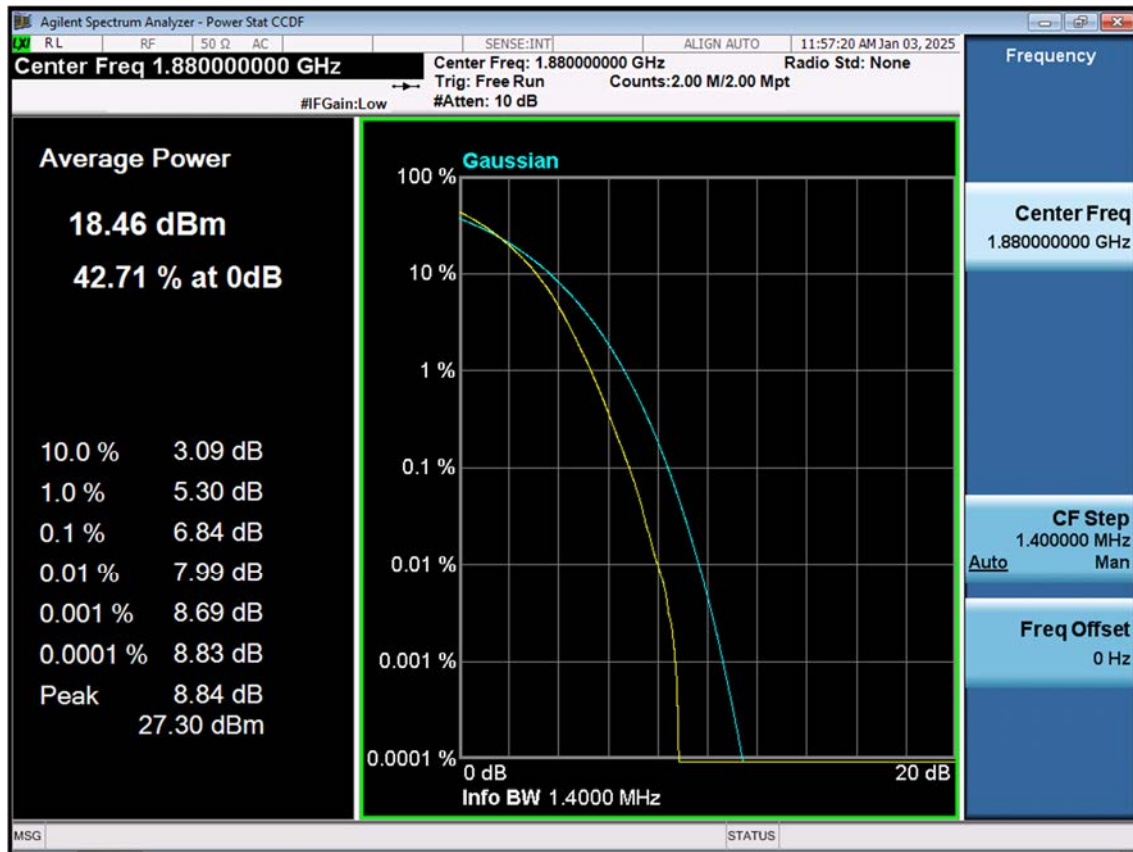
LTE B2_1.4M_PAR_Mid_16QAM_FullRB



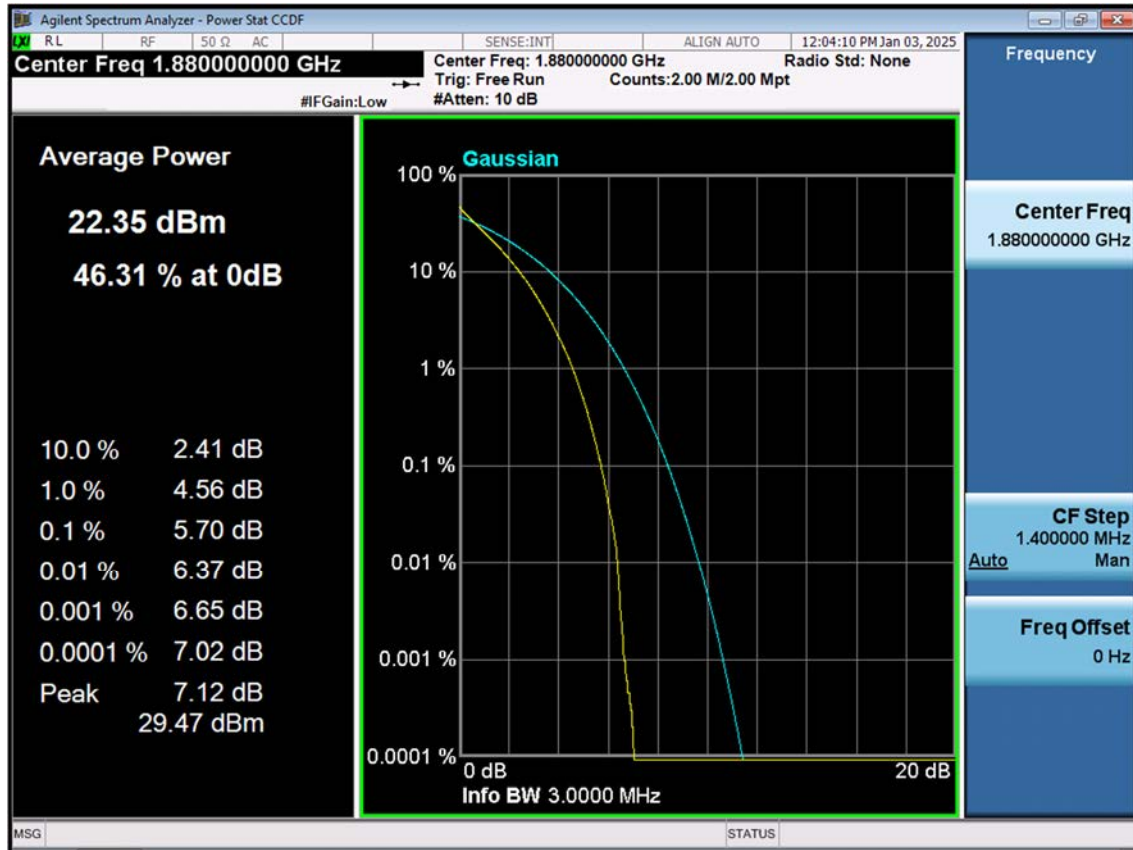
LTE B2_1.4M_PAR_Mid_64QAM_FullRB



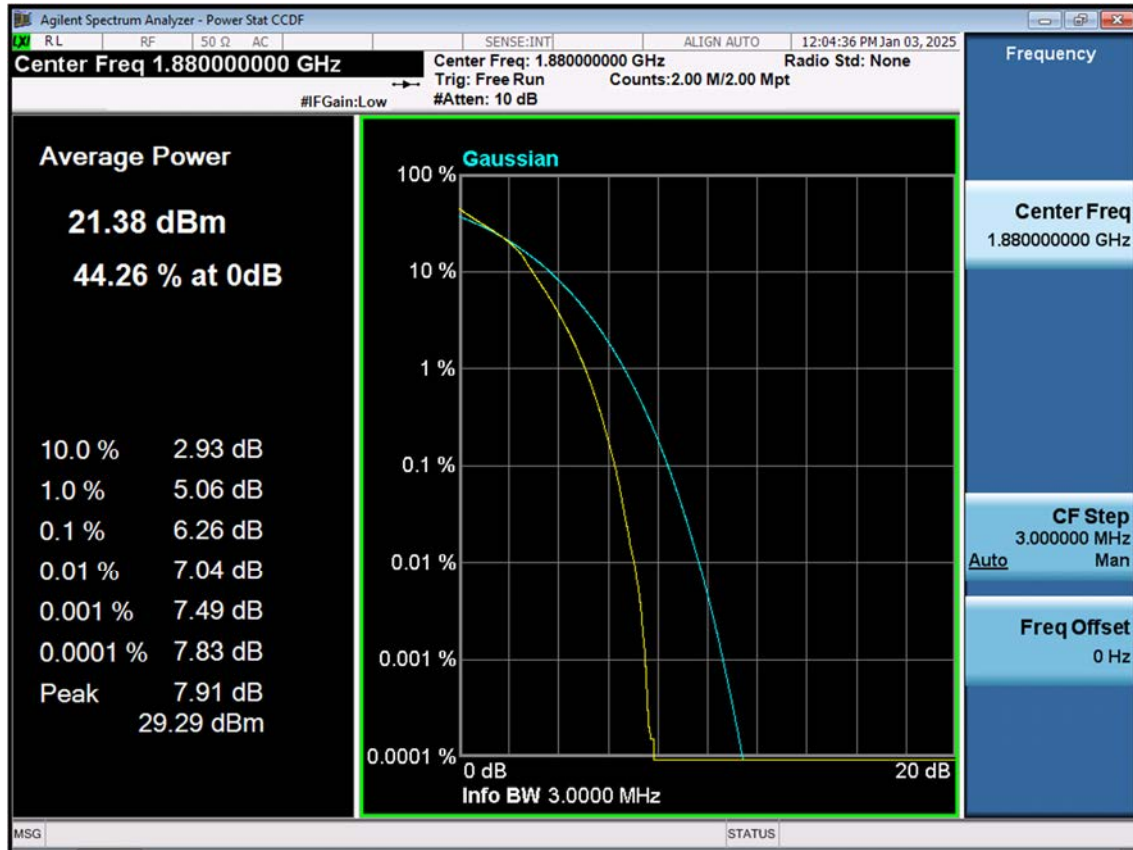
LTE B2_1.4M_PAR_Mid_256QAM_FullRB



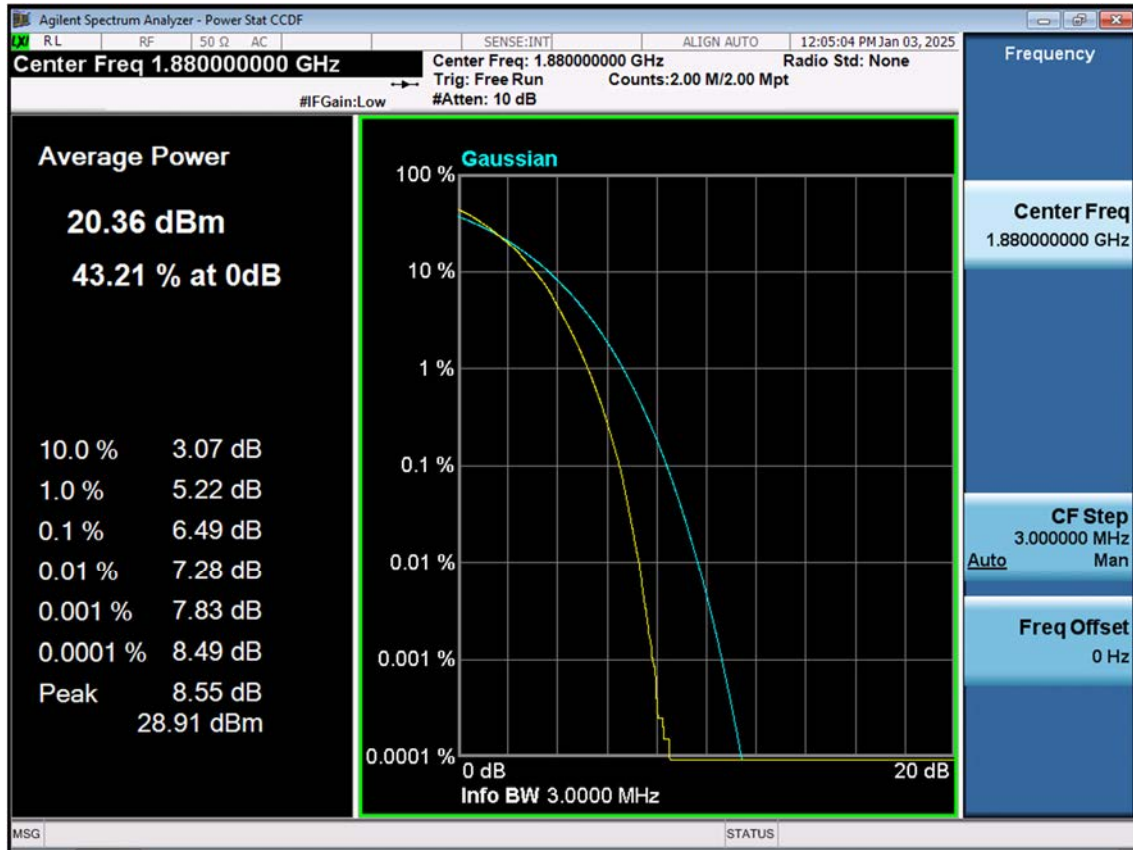
LTE B2_3 M_PAR_Mid_QPSK_FullRB



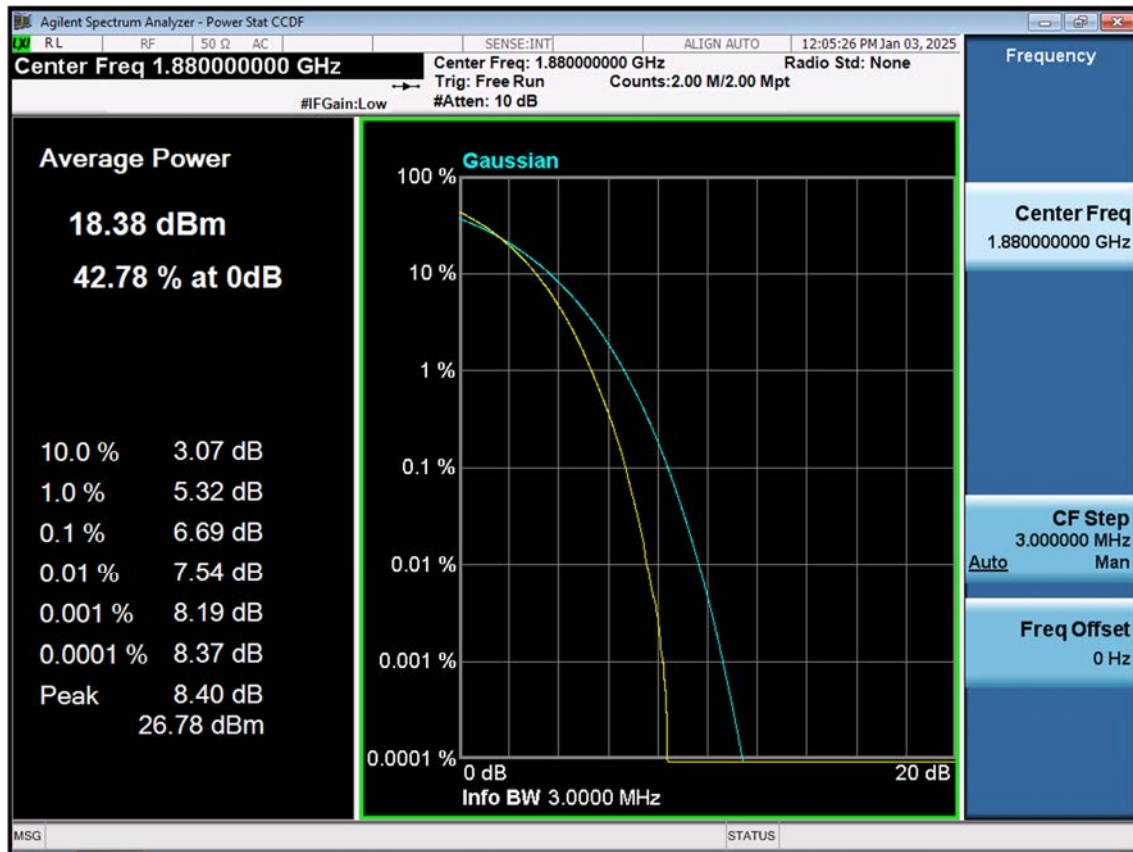
LTE B2_3 M_PAR_Mid_16QAM_FullRB



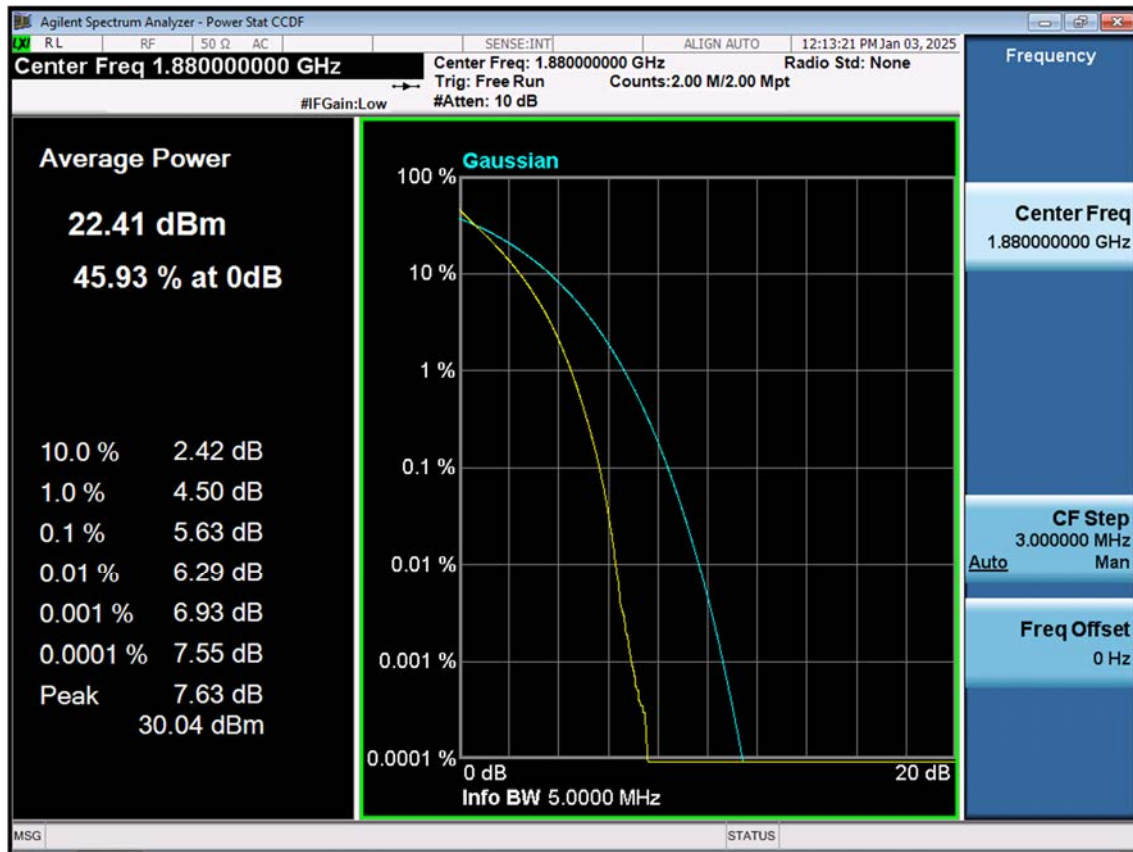
LTE B2_3 M_PAR_Mid_64QAM_FullRB



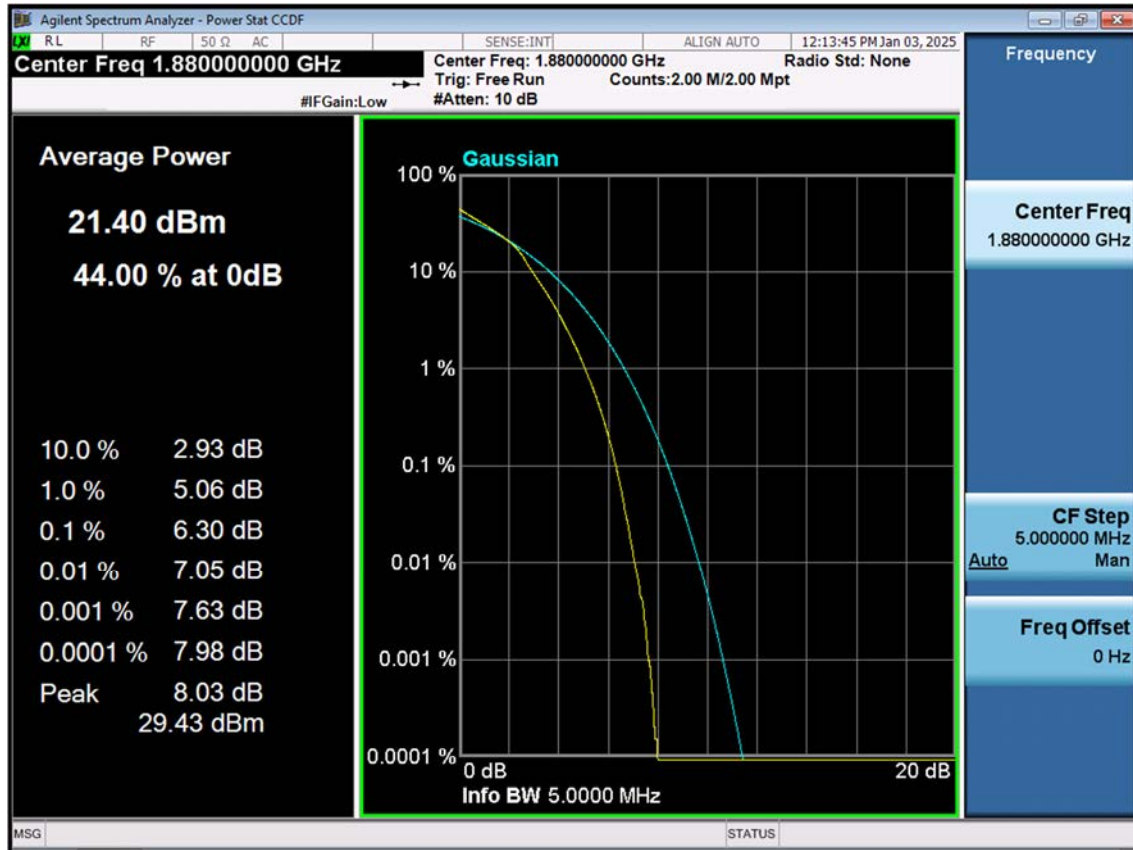
LTE B2_3 M_PAR_Mid_256QAM_FullRB



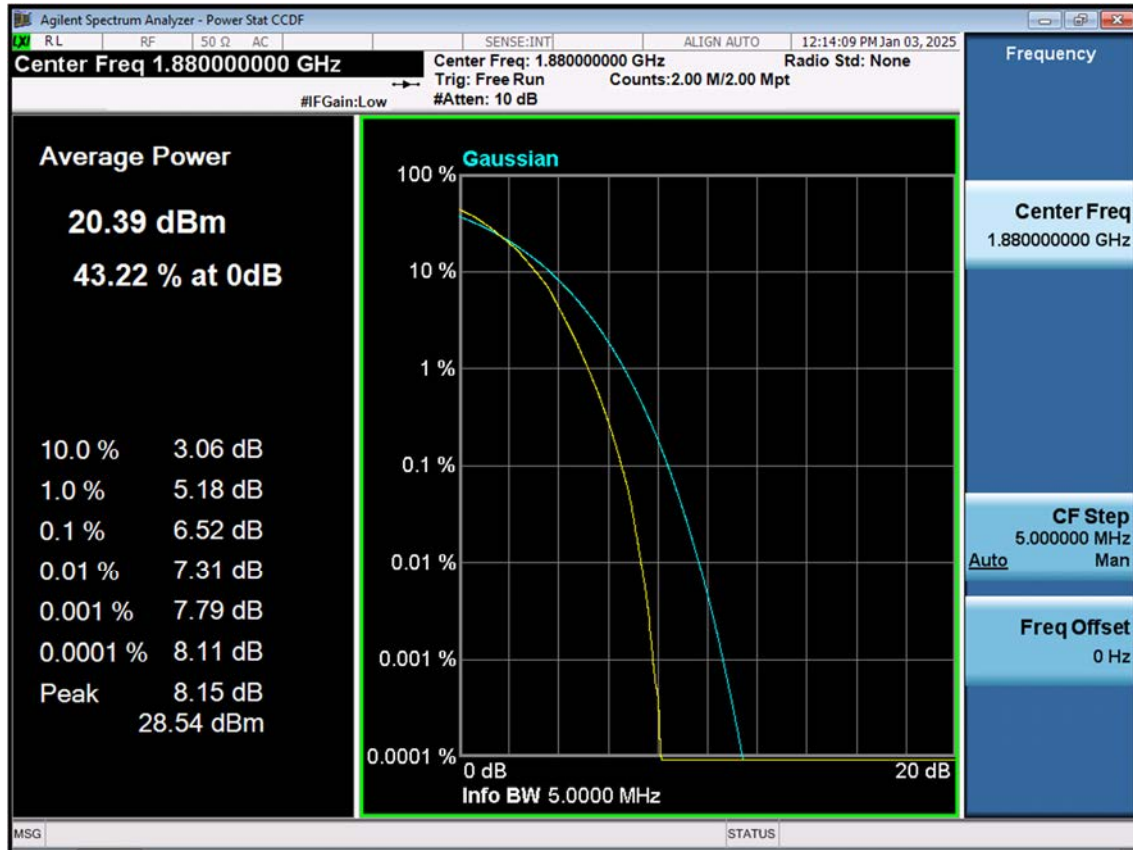
LTE B2_5 M_PAR_Mid_QPSK_FullRB



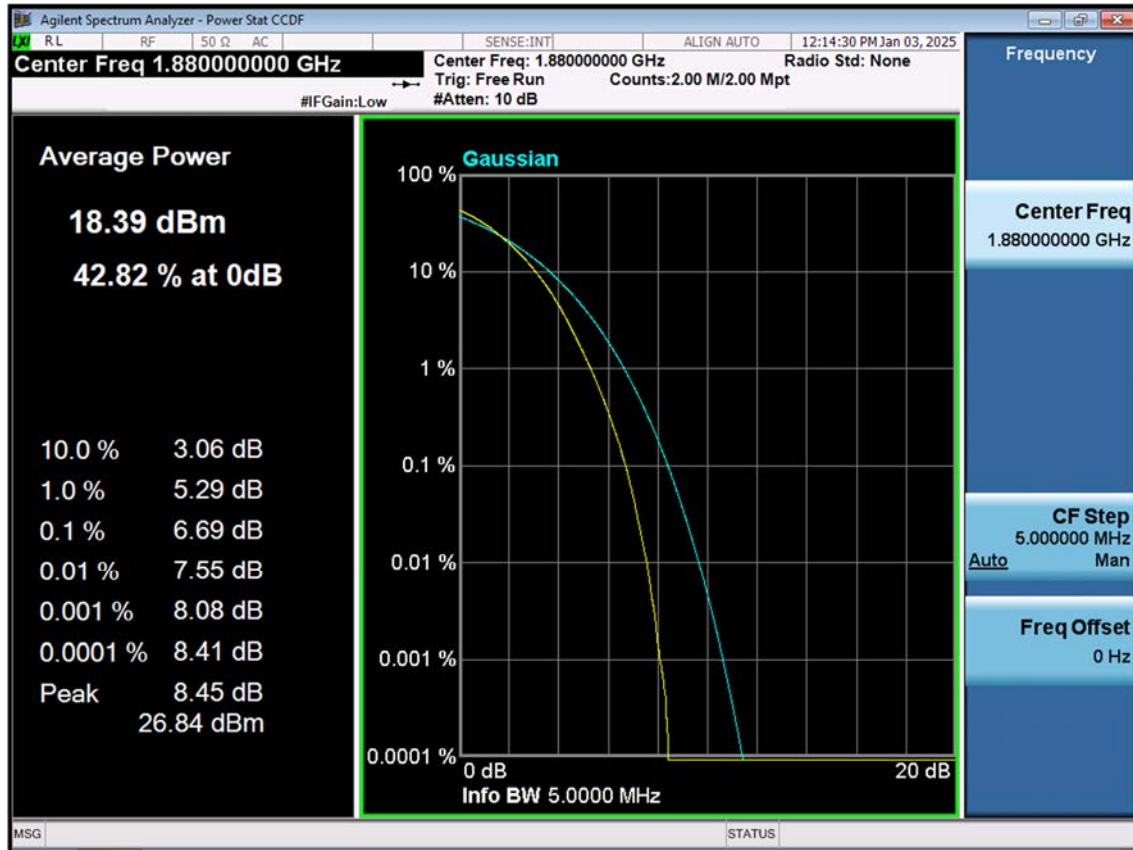
LTE B2_5 M_PAR_Mid_16QAM_FullRB



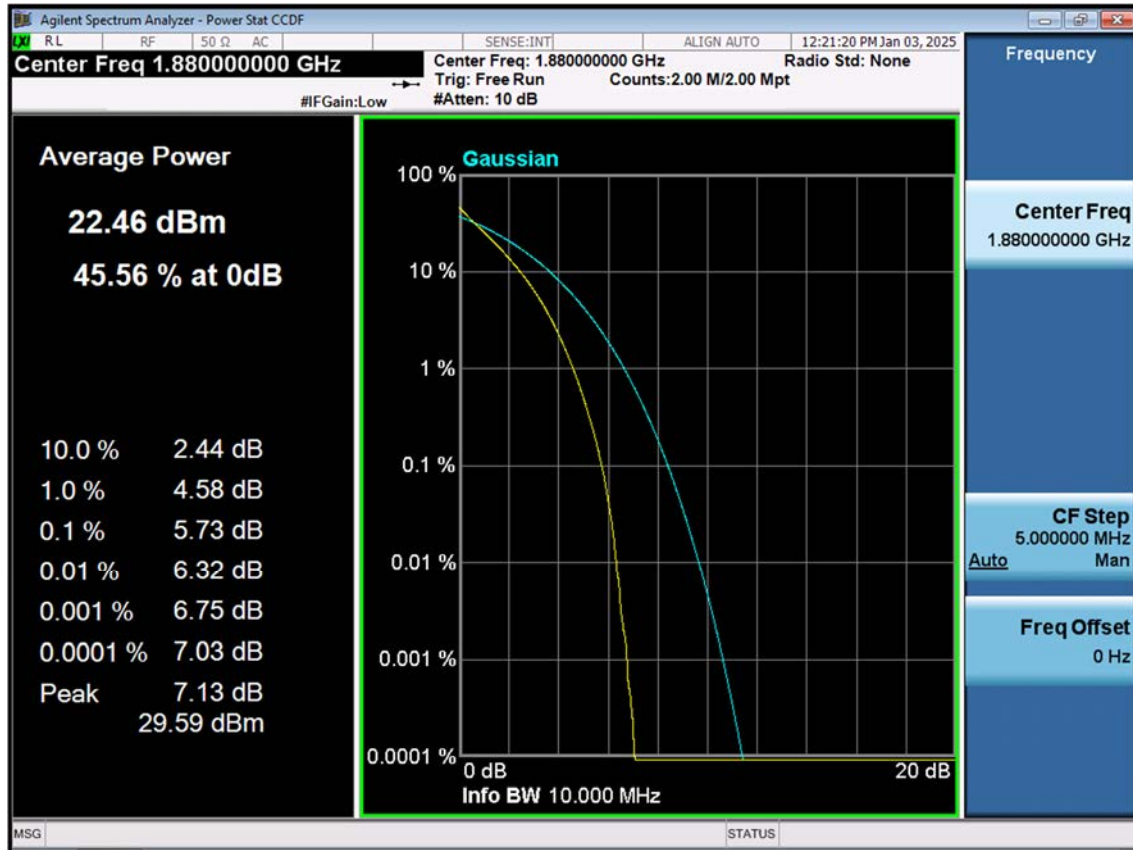
LTE B2_5 M_PAR_Mid_64QAM_FullRB



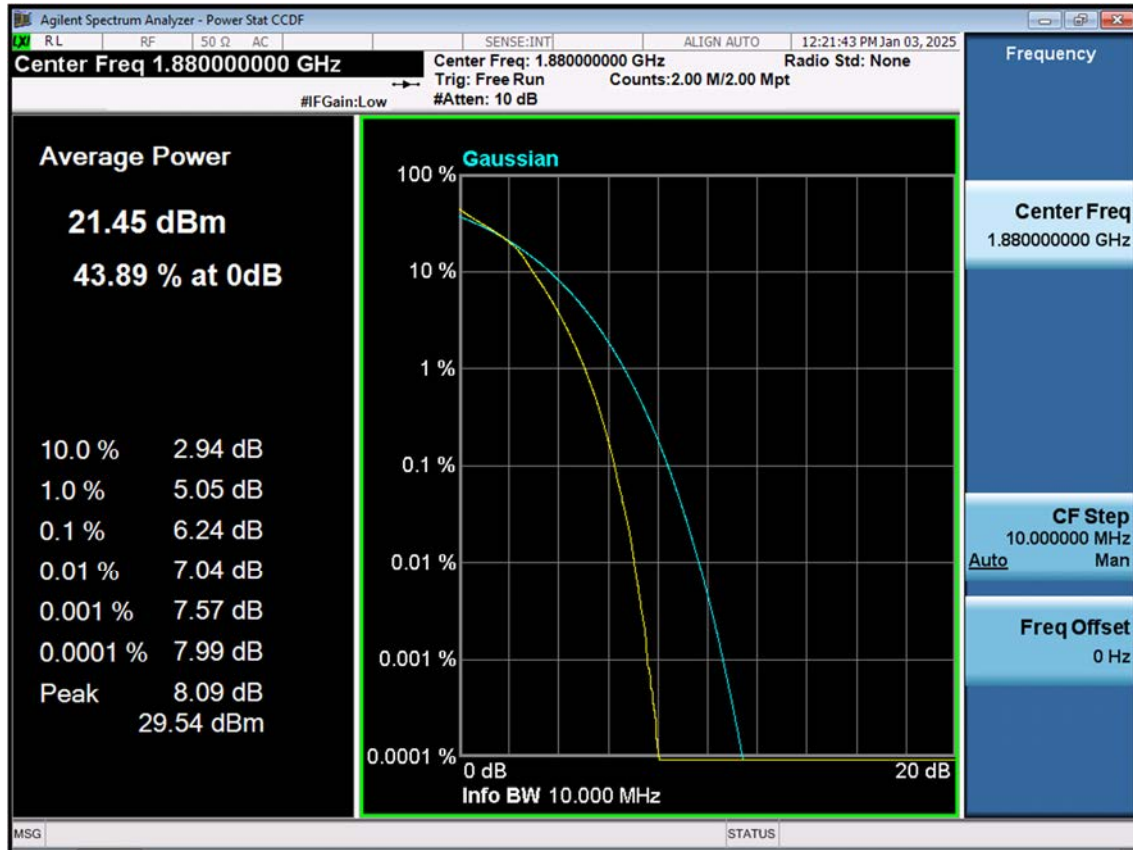
LTE B2_5 M_PAR_Mid_256QAM_FullRB



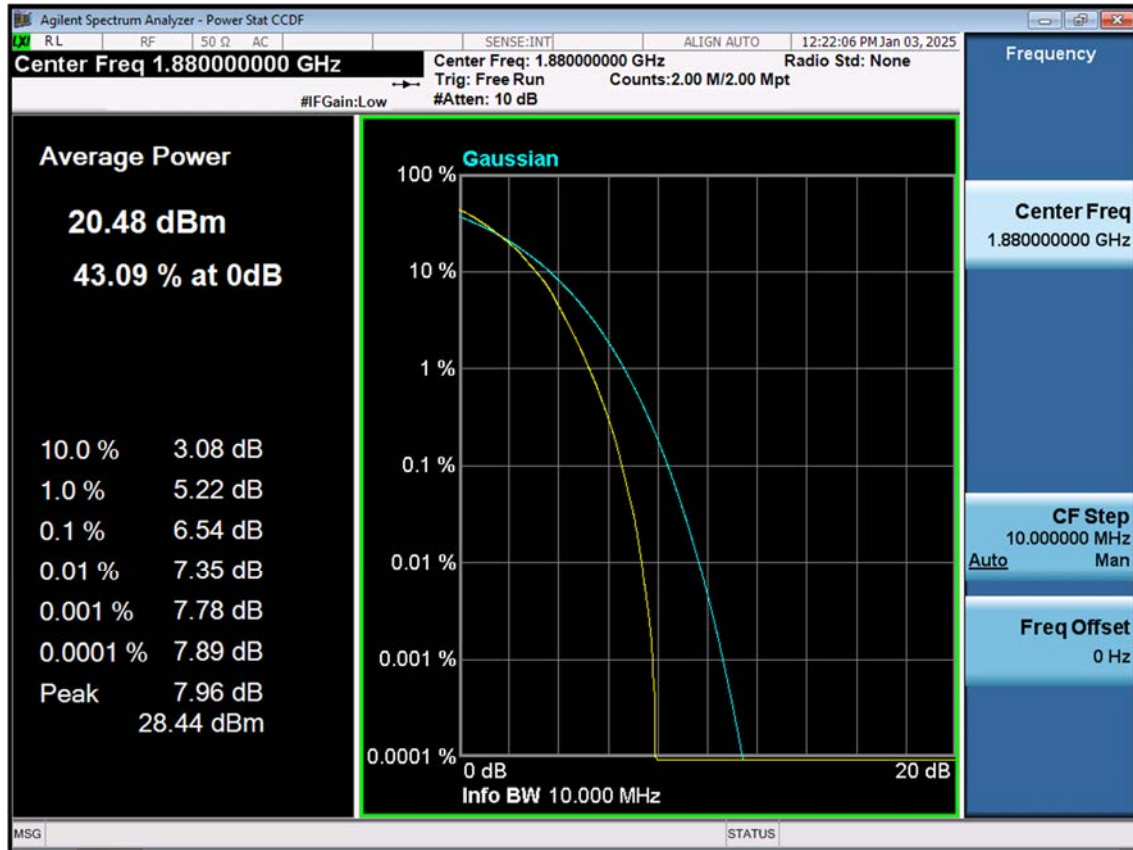
LTE B2_10 M_PAR_Mid_QPSK_FullRB



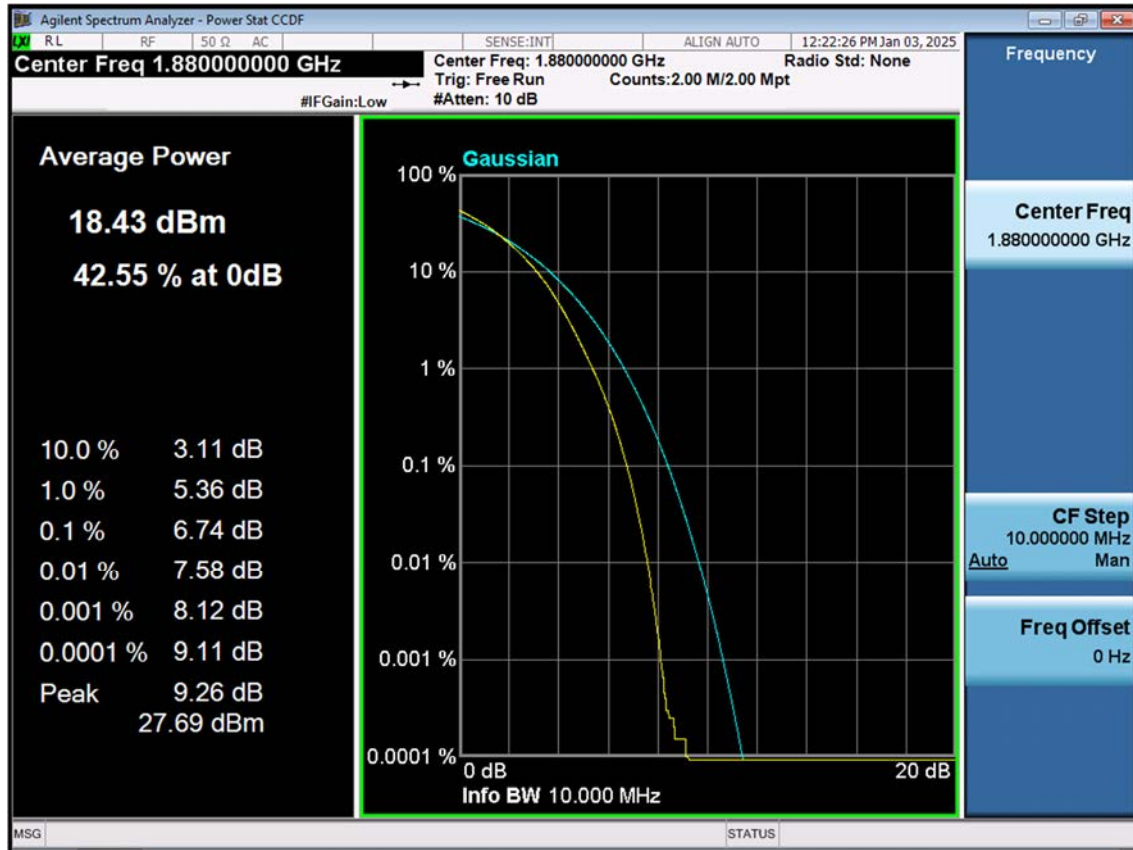
LTE B2_10 M_PAR_Mid_16QAM_FullRB



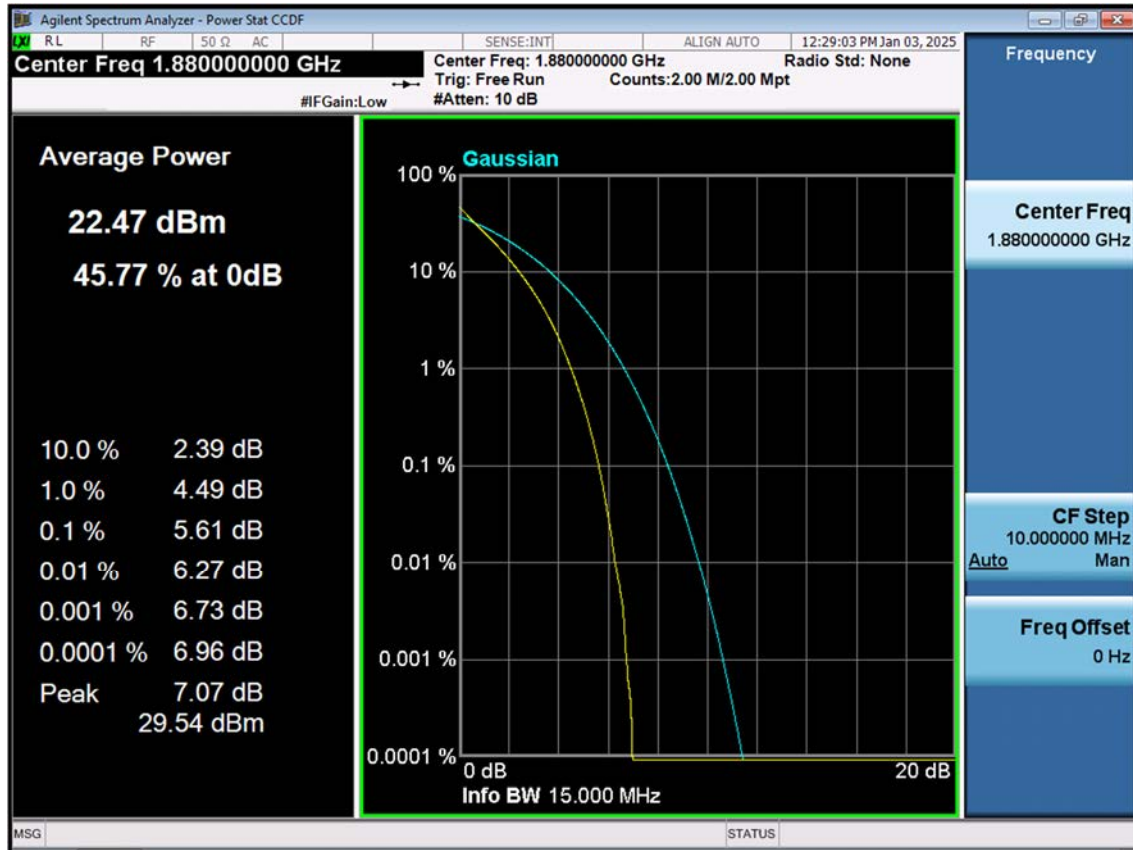
LTE B2_10 M_PAR_Mid_64QAM_FullRB



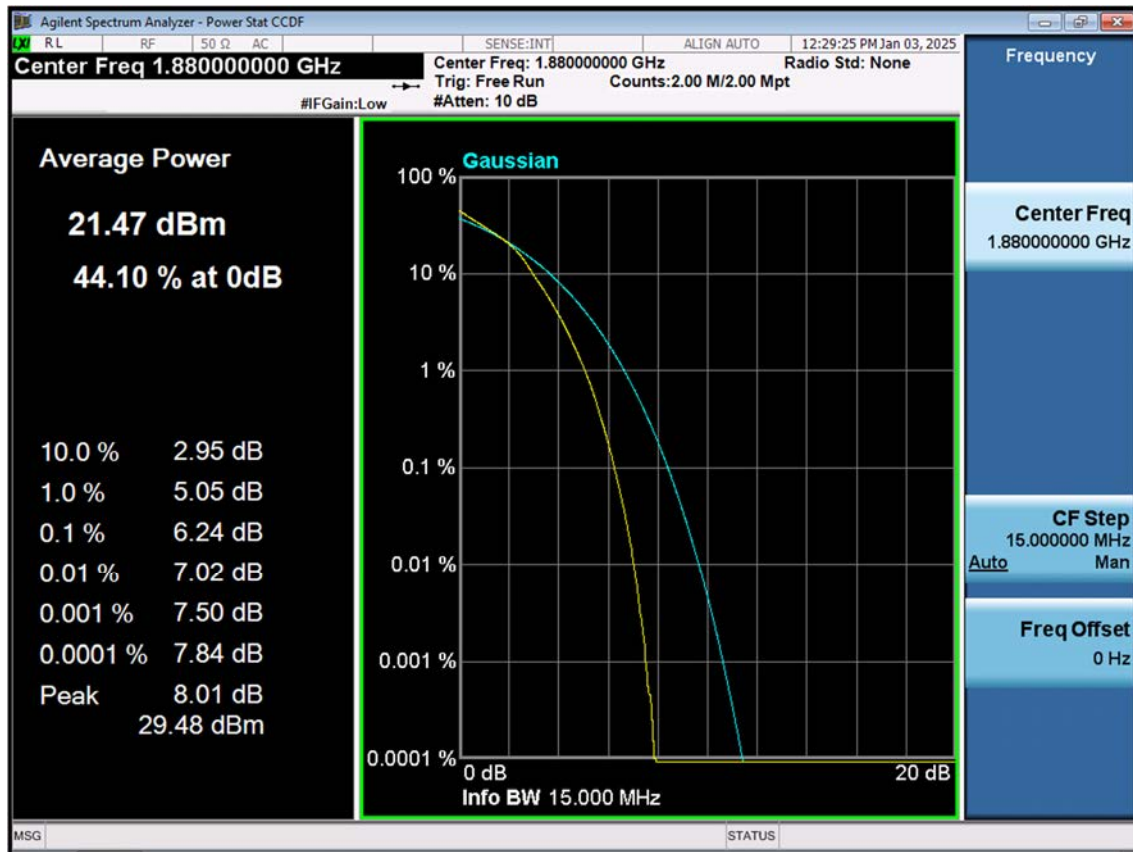
LTE B2_10 M_PAR_Mid_256QAM_FullRB



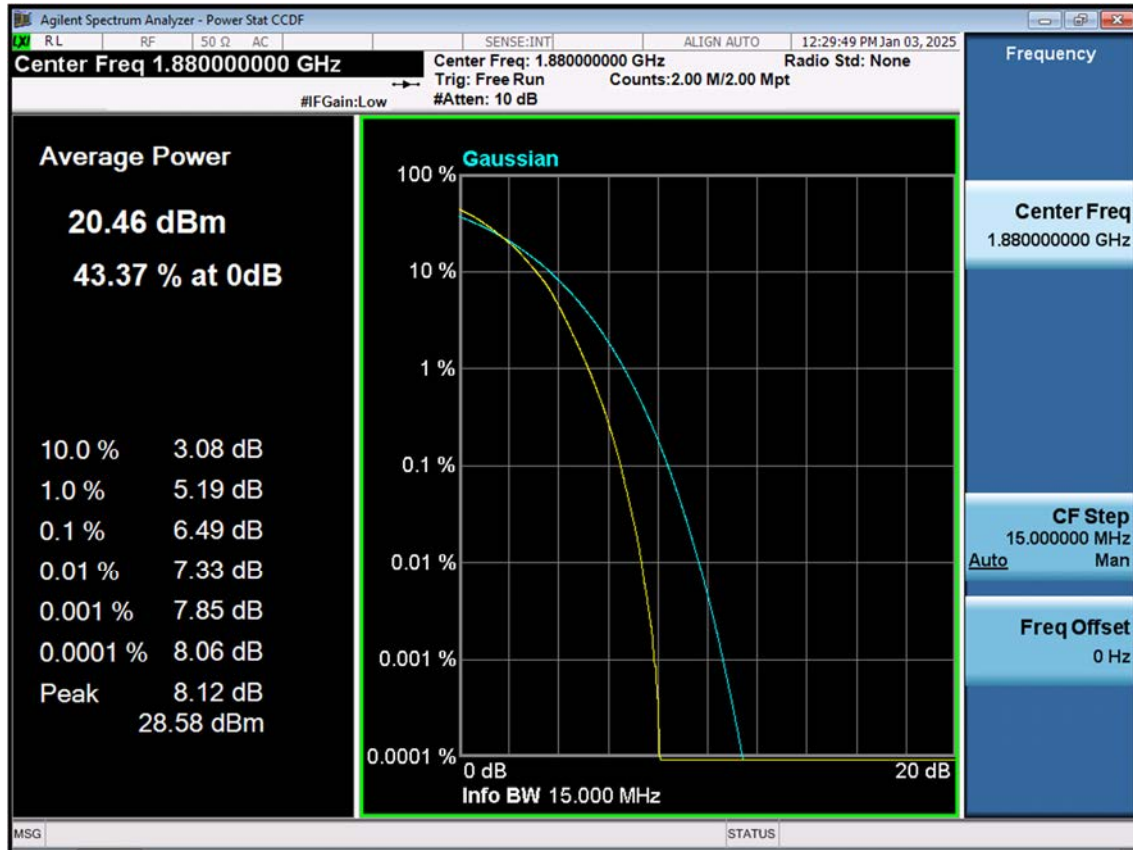
LTE B2_15 M_PAR_Mid_QPSK_FullRB



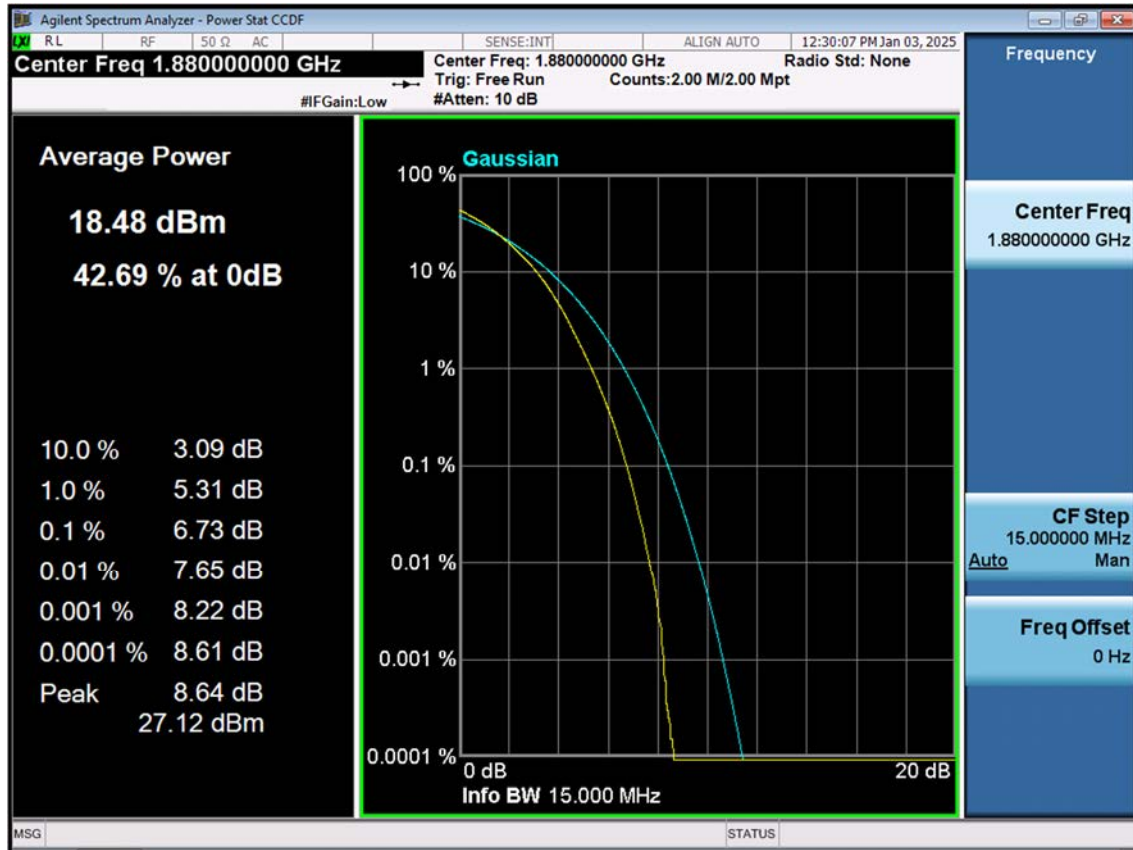
LTE B2_15 M_PAR_Mid_16QAM_FullRB



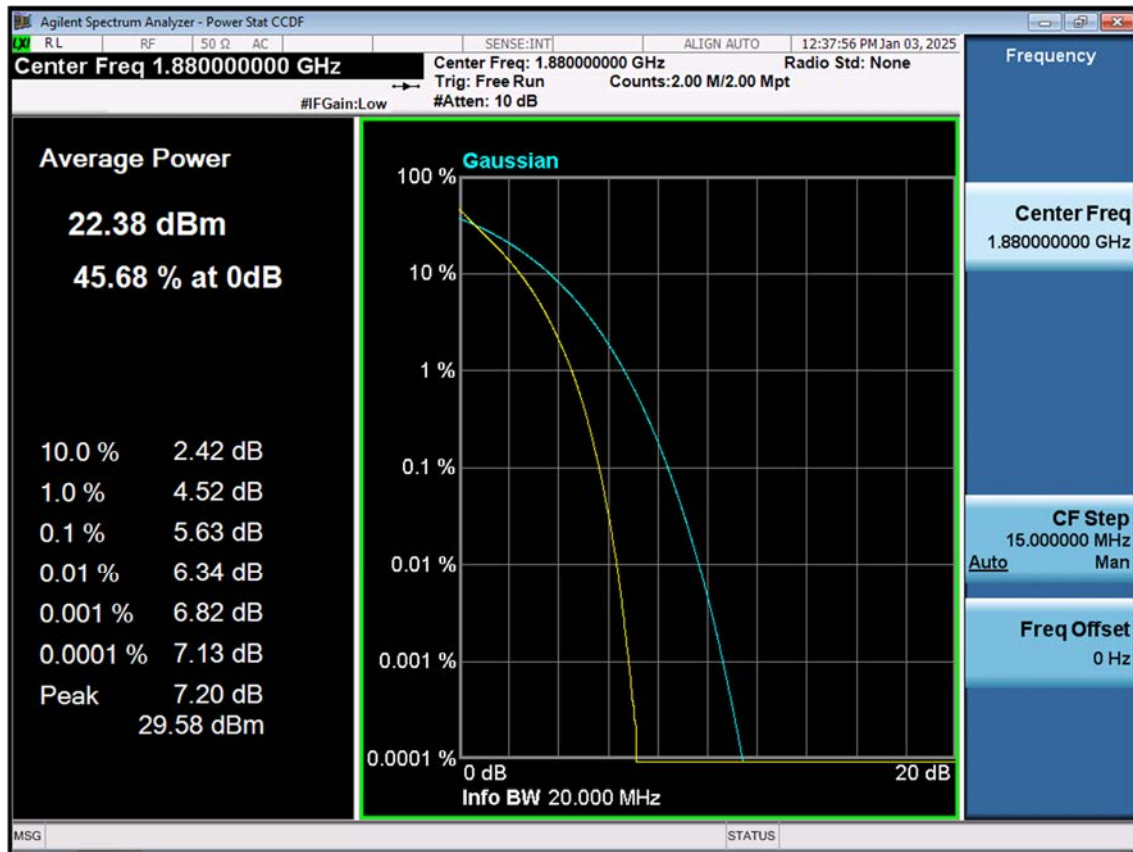
LTE B2_15 M_PAR_Mid_64QAM_FullRB



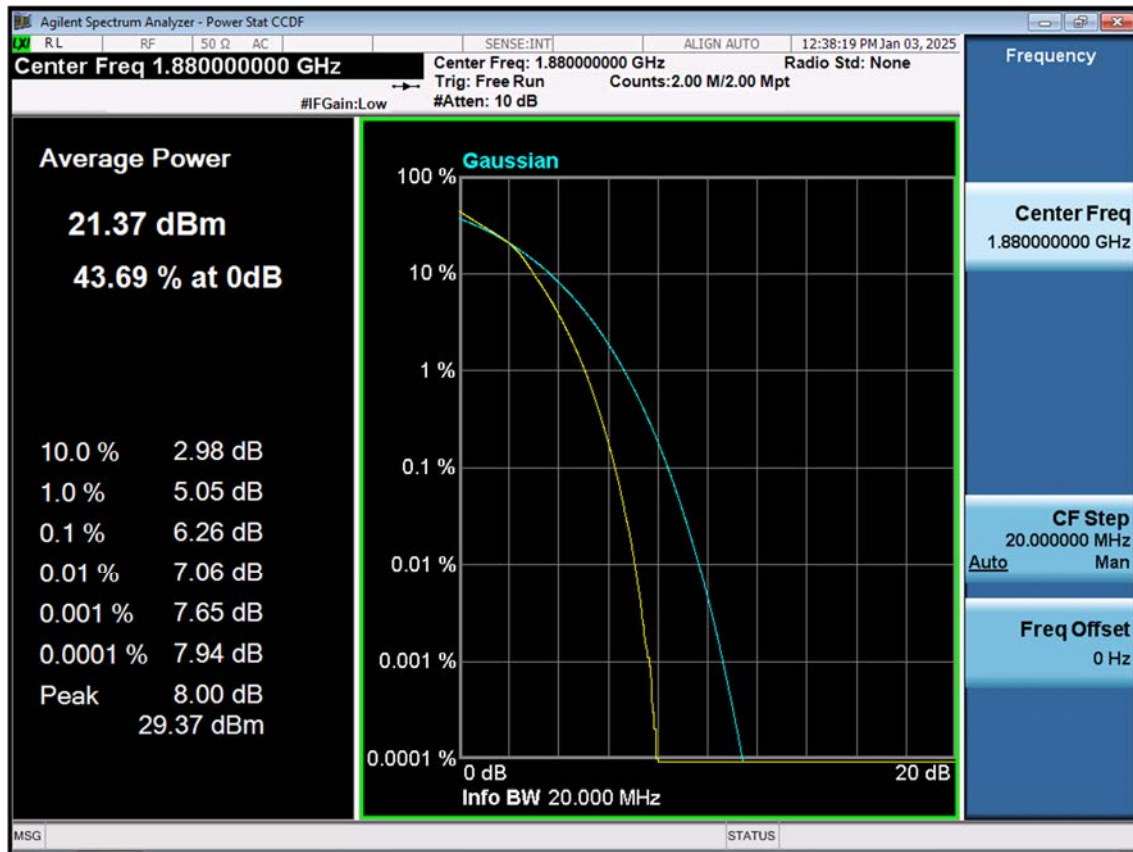
LTE B2_15 M_PAR_Mid_256QAM_FullRB



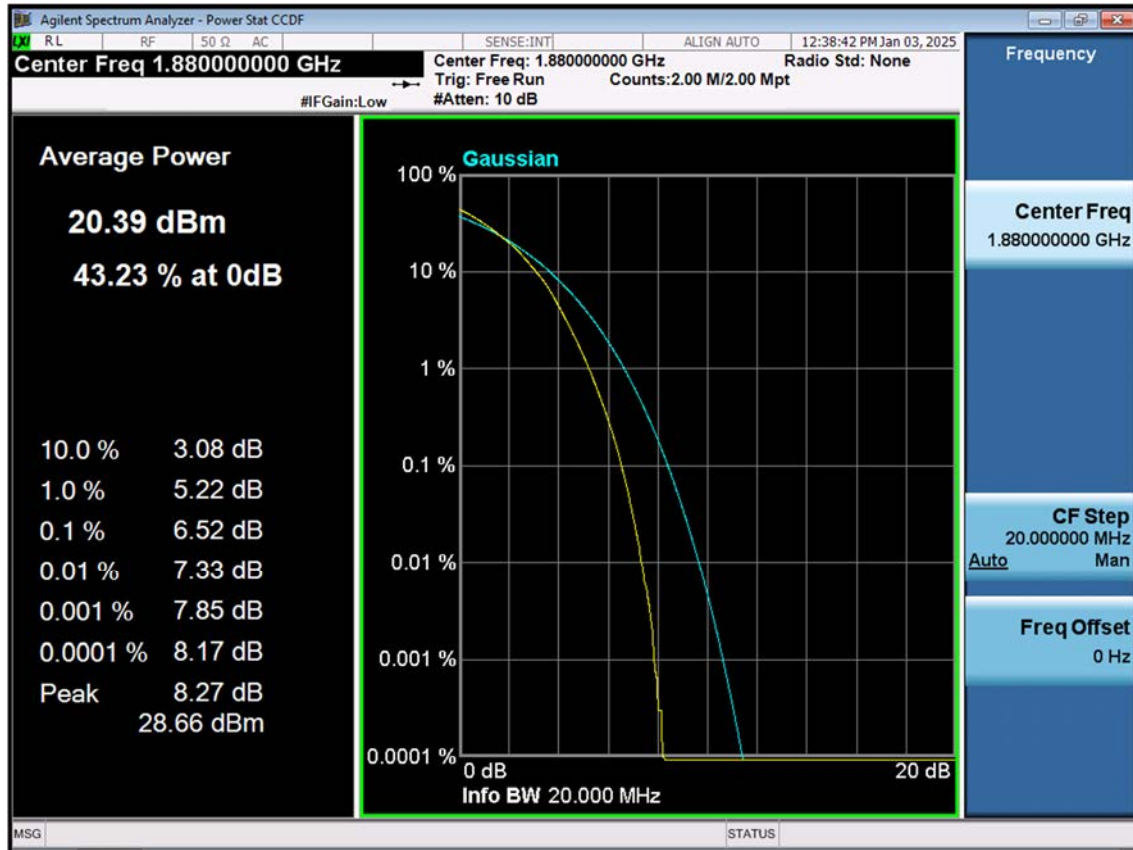
LTE B2_20 M_PAR_Mid_QPSK_FullRB



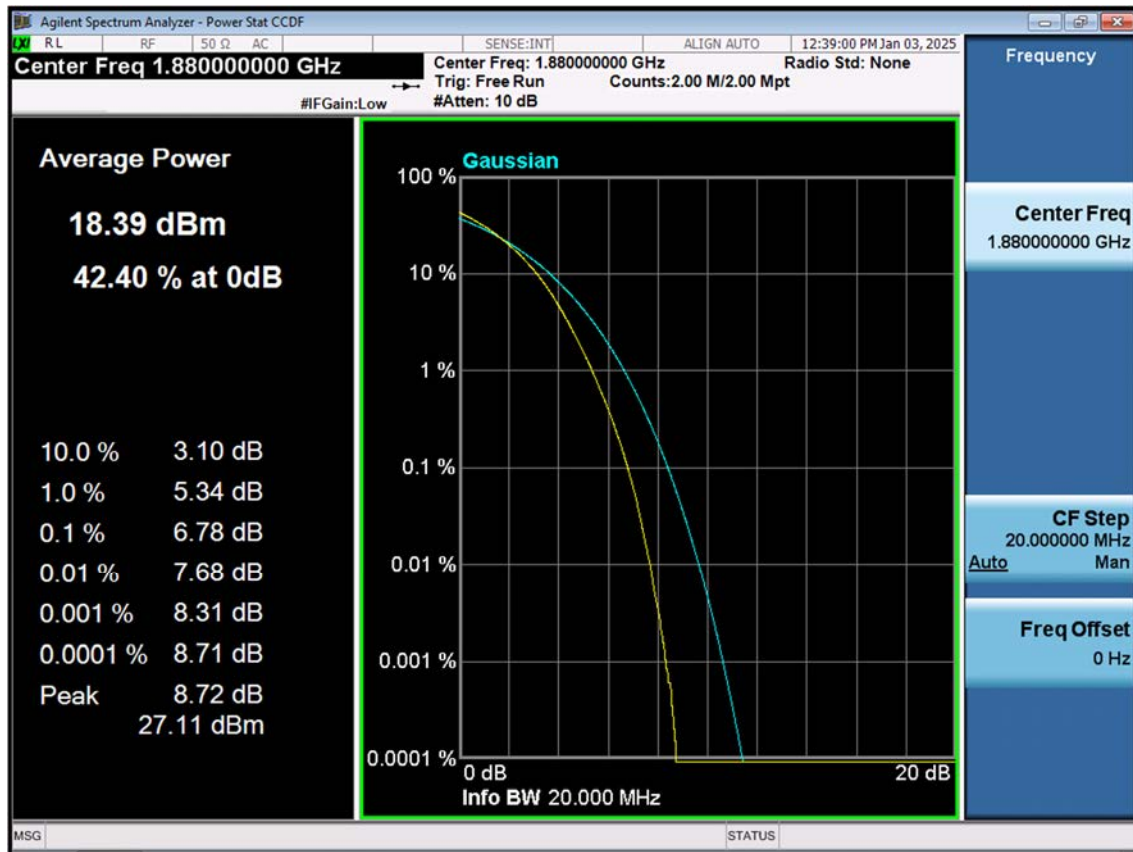
LTE B2_20 M_PAR_Mid_16QAM_FullRB



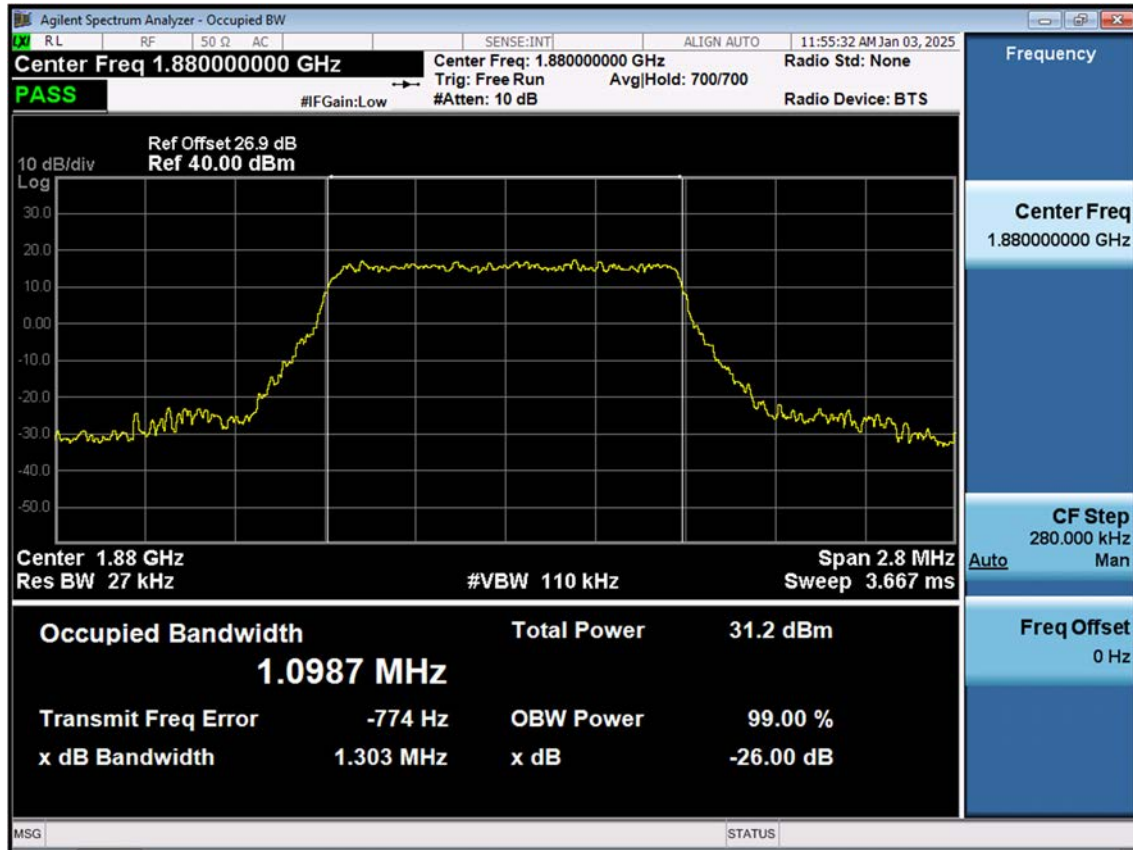
LTE B2_20 M_PAR_Mid_64QAM_FullRB



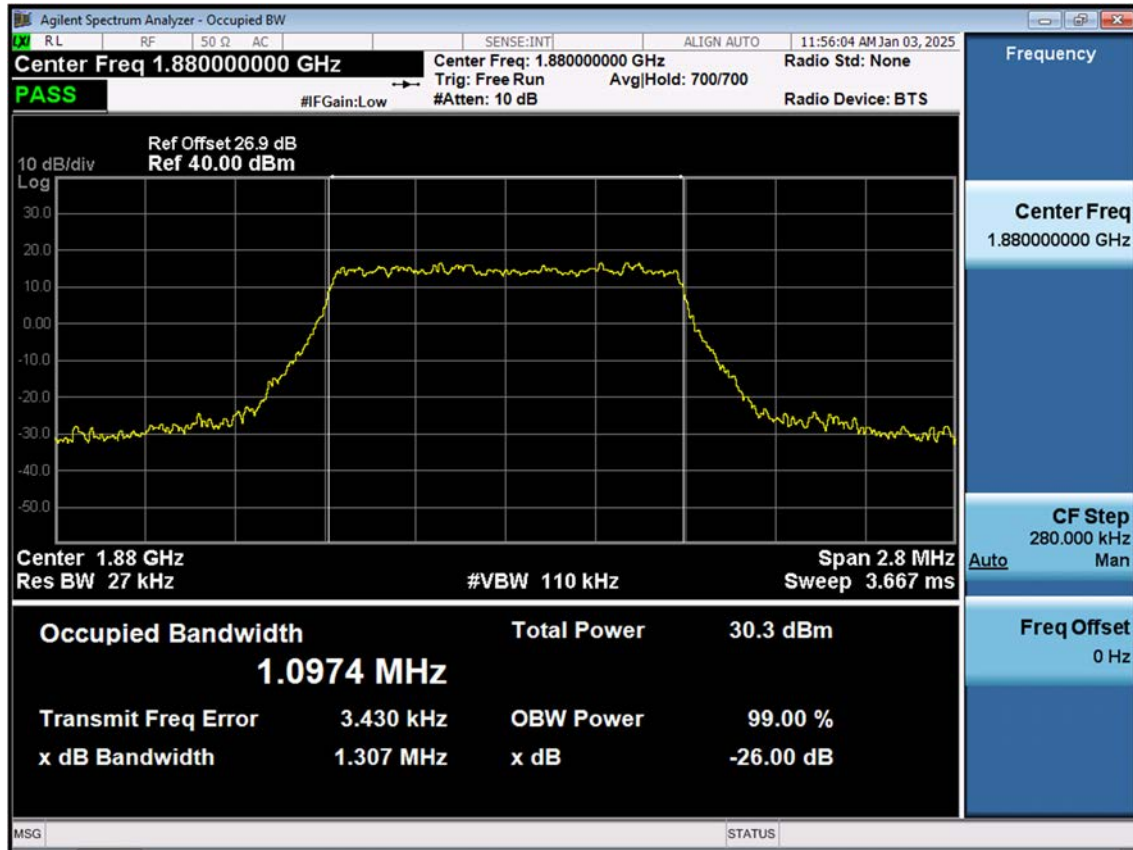
LTE B2_20 M_PAR_Mid_256QAM_FullRB



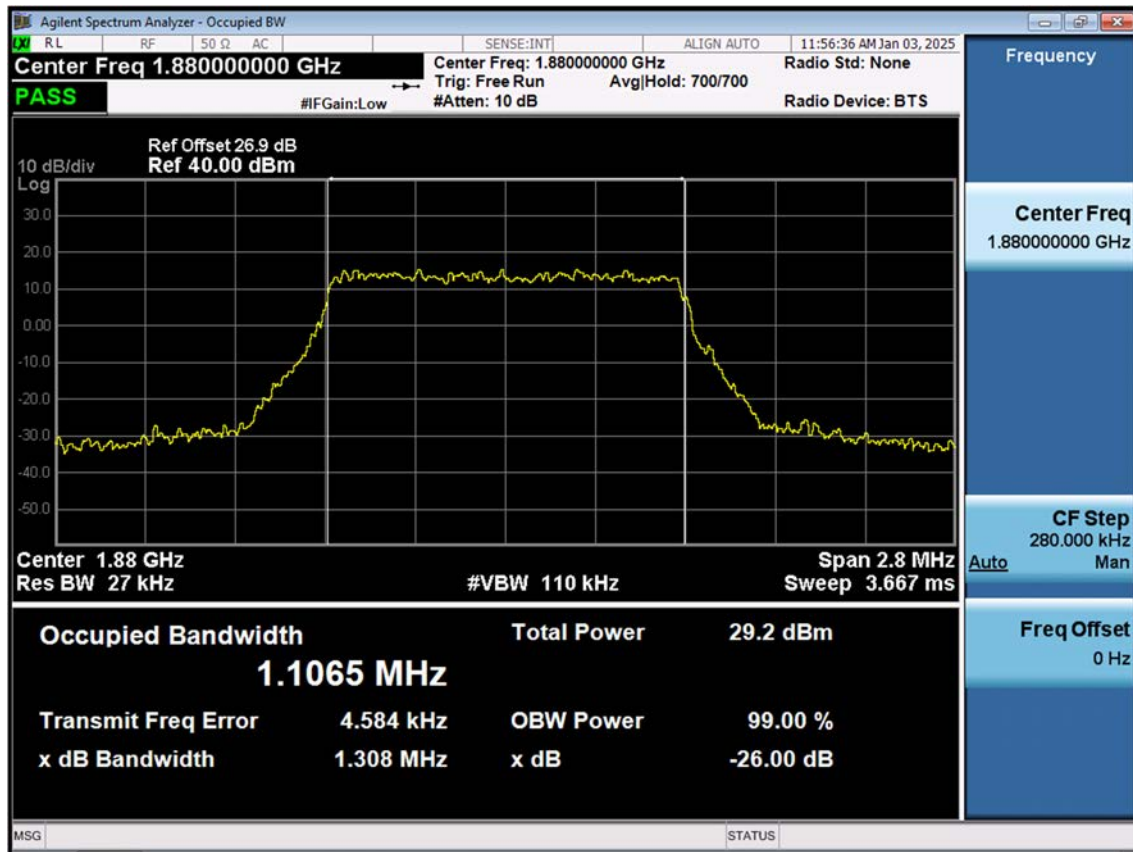
LTE B2_1.4M_OBW_Mid_QPSK_FullRB



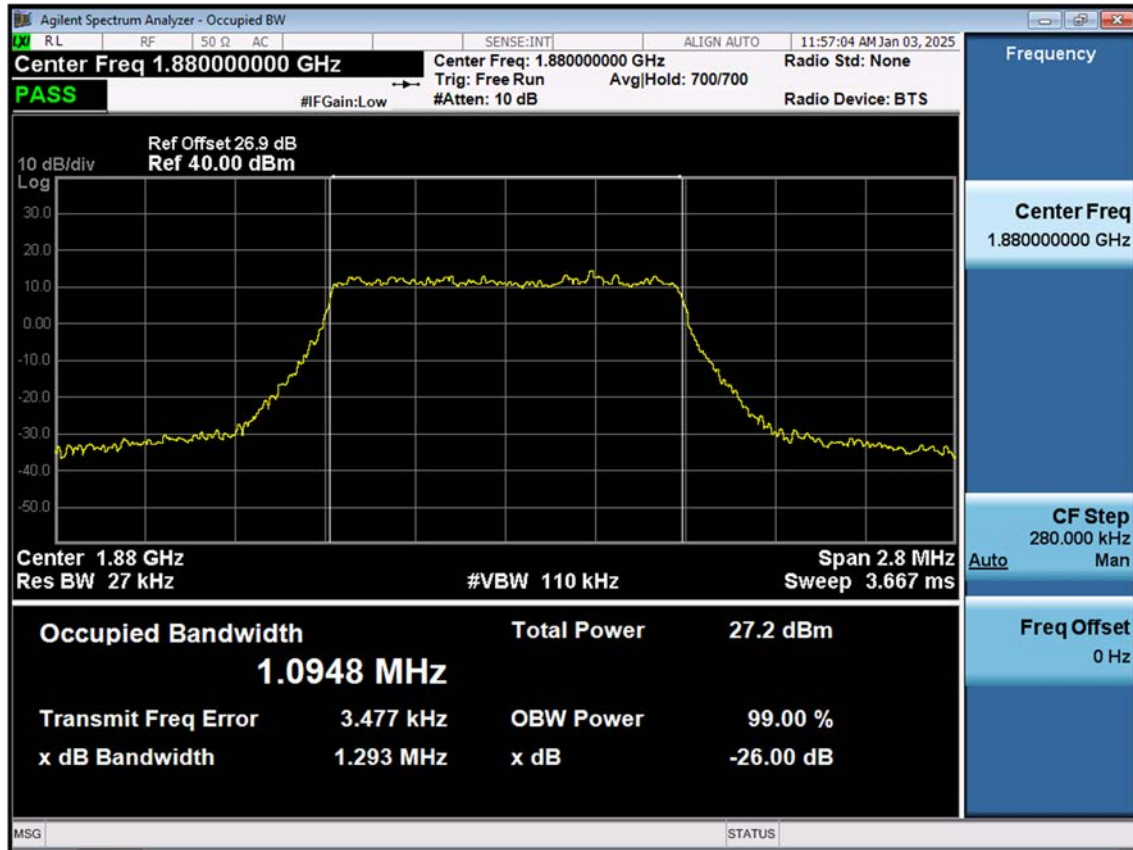
LTE B2_1.4M_OBW_Mid_16QAM_FullRB



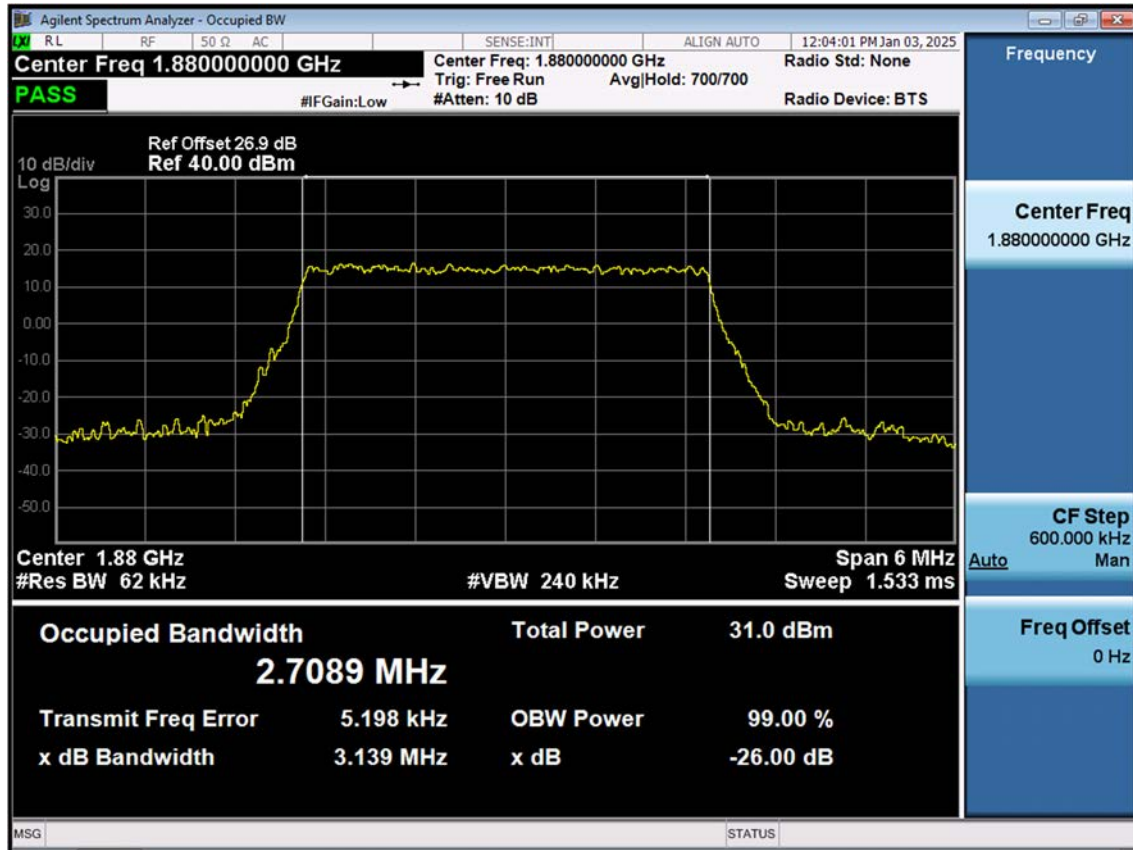
LTE B2_1.4M_OBW_Mid_64QAM_FullRB



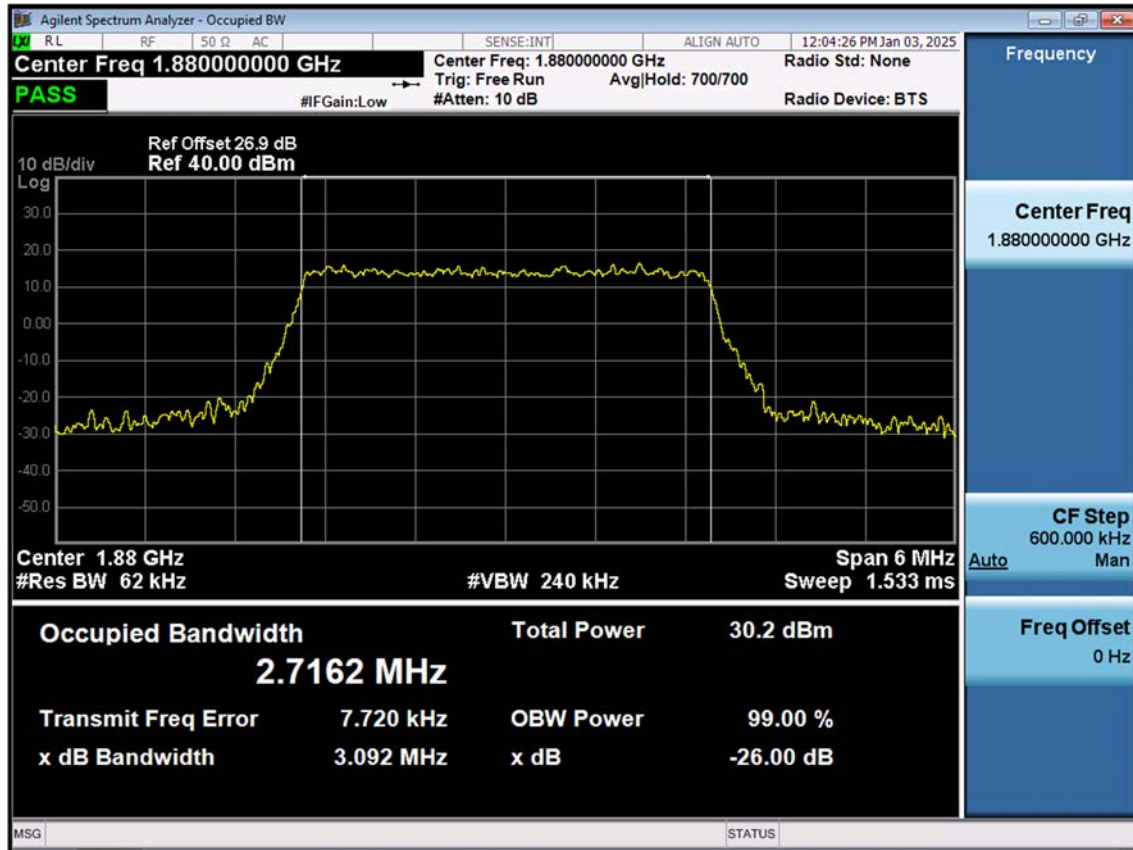
LTE B2_1.4M_OBW_Mid_256QAM_FullRB



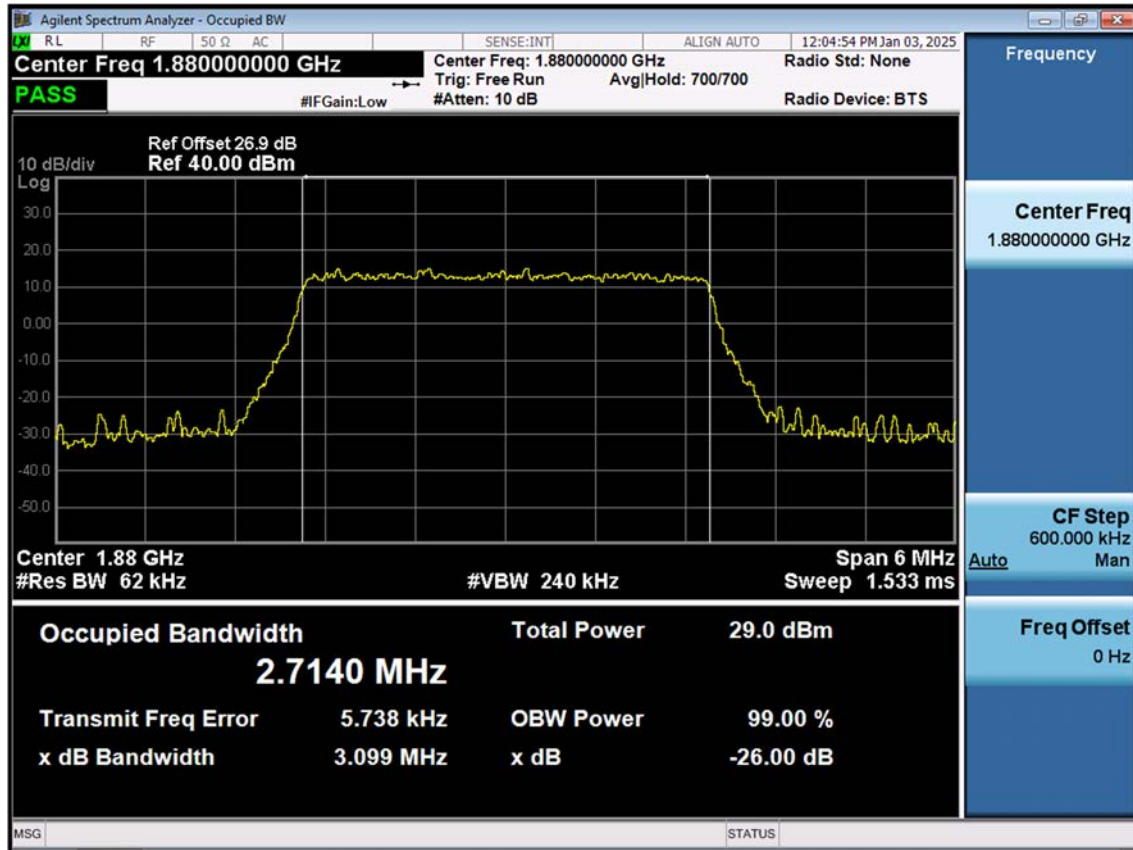
LTE B2_3 M_OBW_Mid_QPSK_FullRB



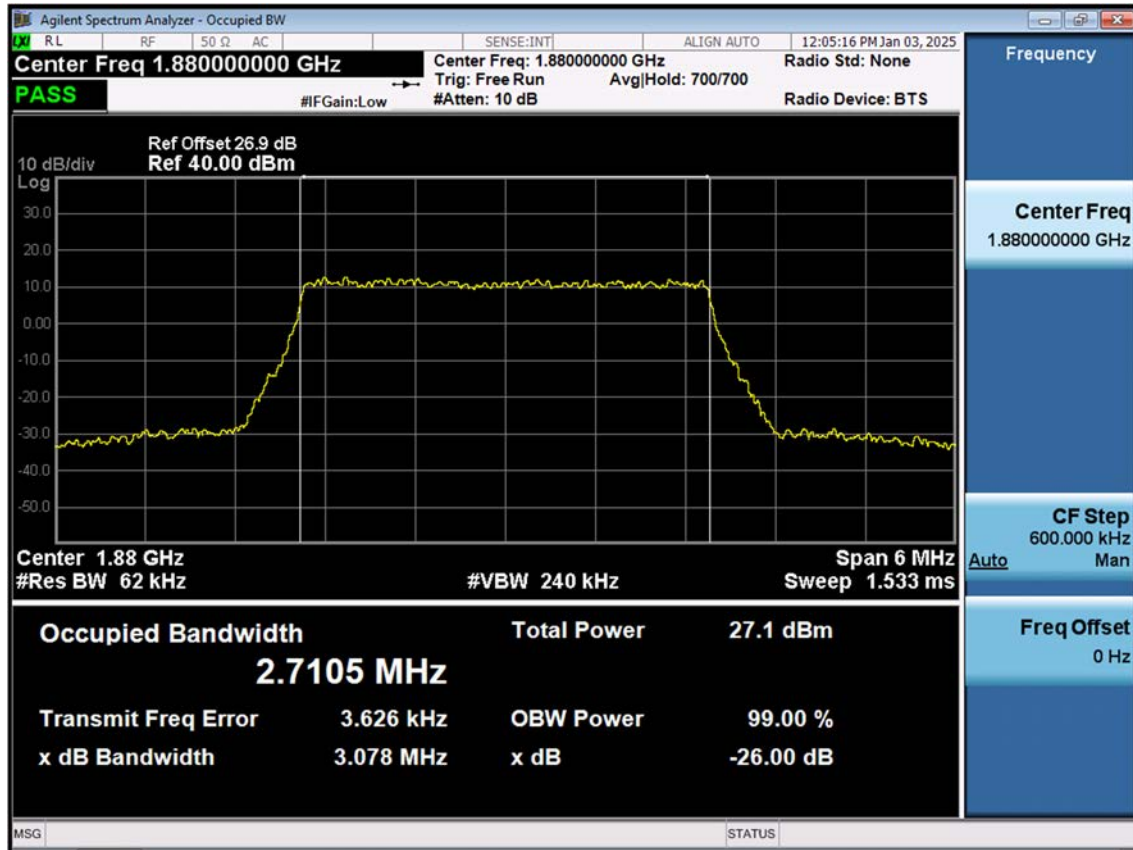
LTE B2_3 M_OBW_Mid_16QAM_FullRB



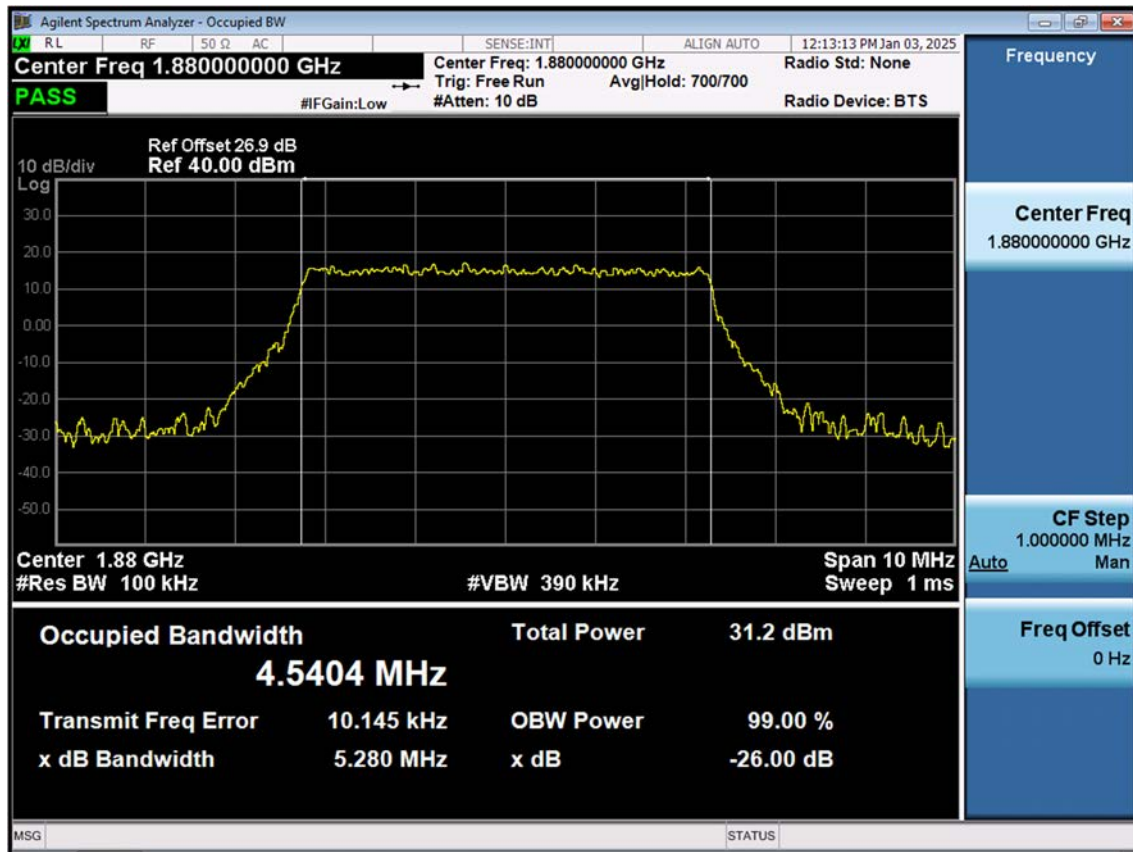
LTE B2_3 M_OBW_Mid_64QAM_FullRB



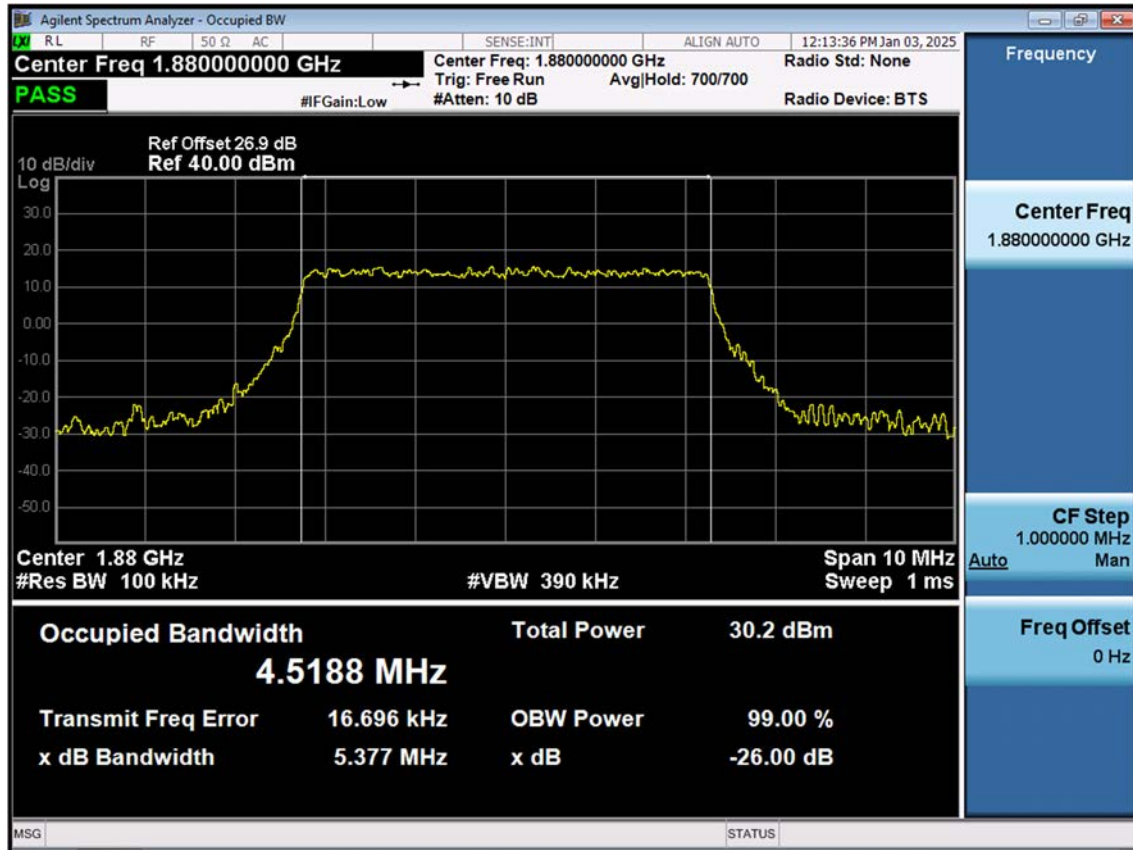
LTE B2_3 M_OBW_Mid_256QAM_FullRB



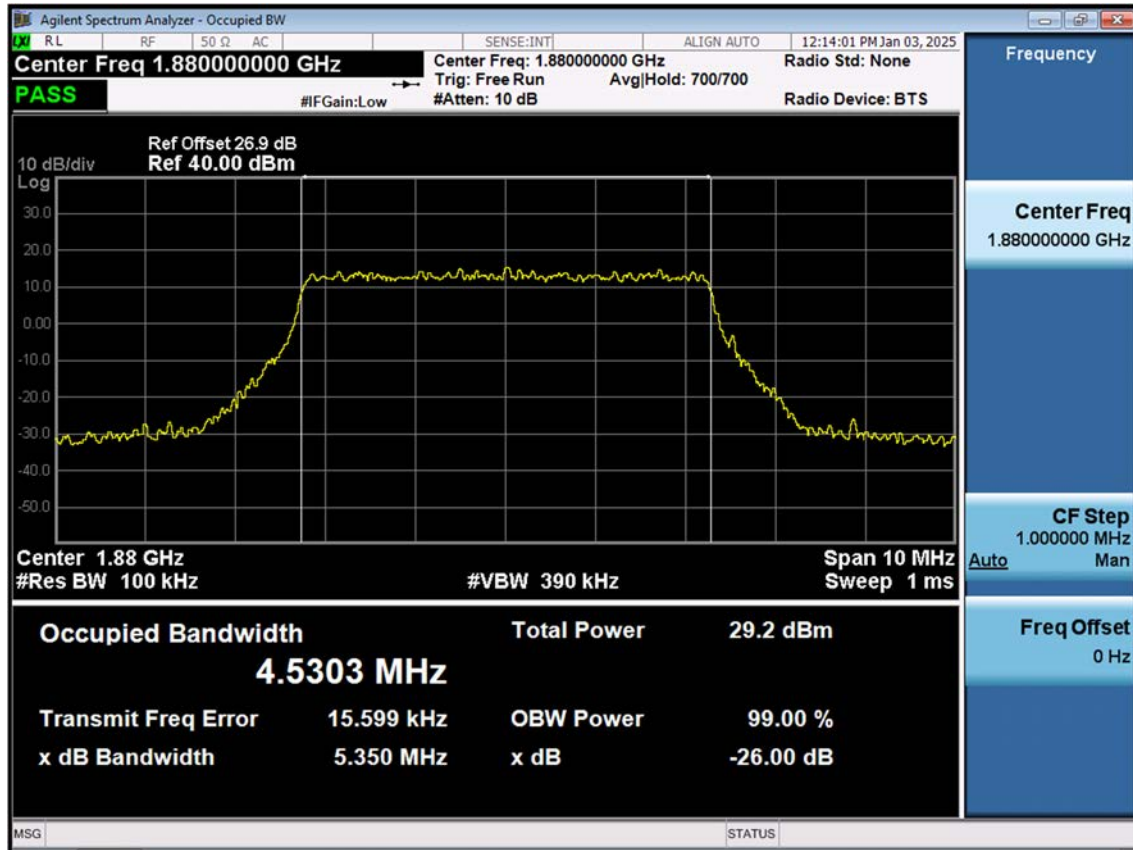
LTE B2_5 M_OBW_Mid_QPSK_FullRB



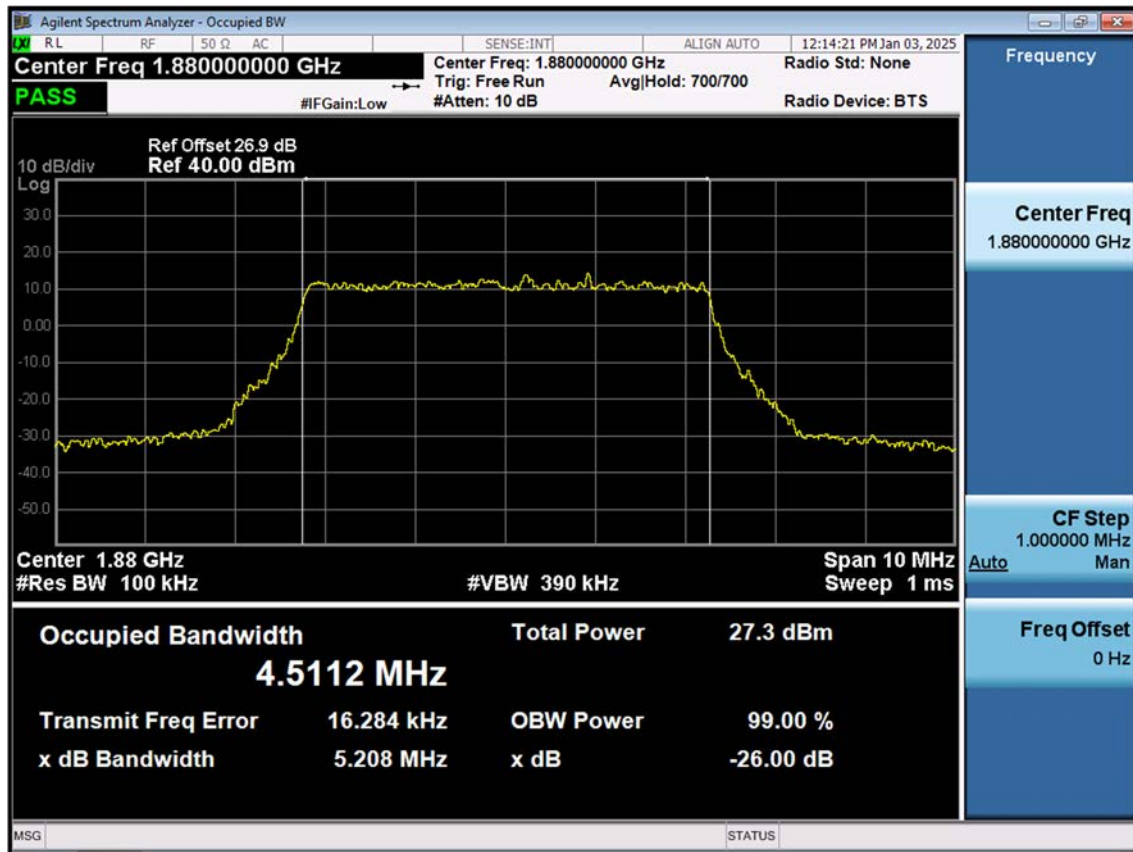
LTE B2_5 M_OBW_Mid_16QAM_FullRB



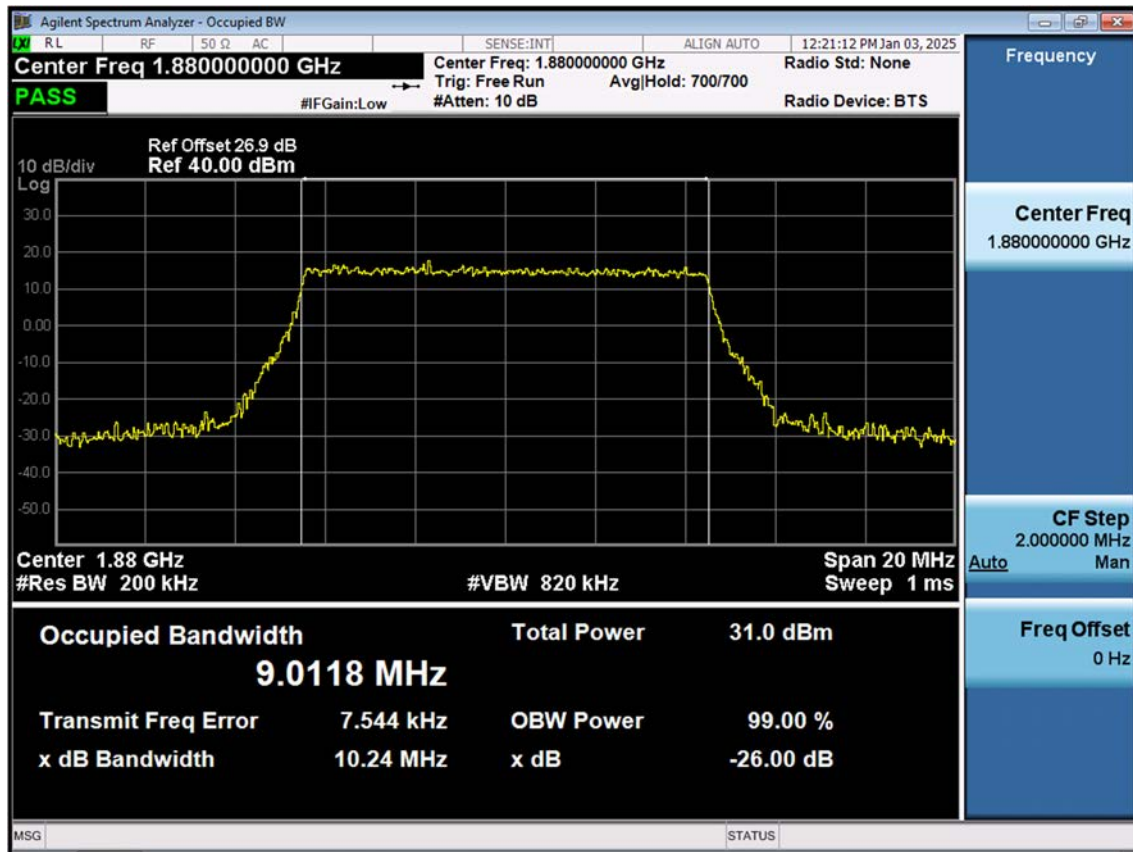
LTE B2_5 M_OBW_Mid_64QAM_FullRB



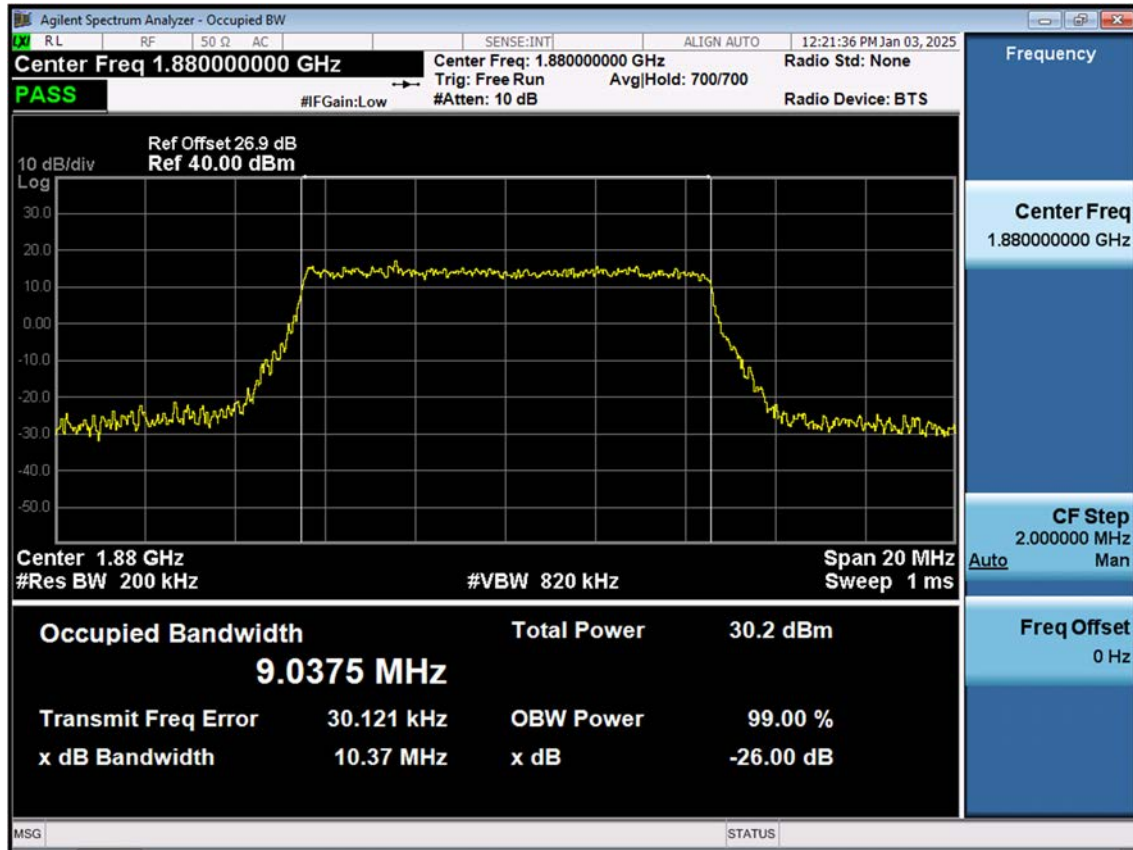
LTE B2_5 M_OBW_Mid_256QAM_FullRB



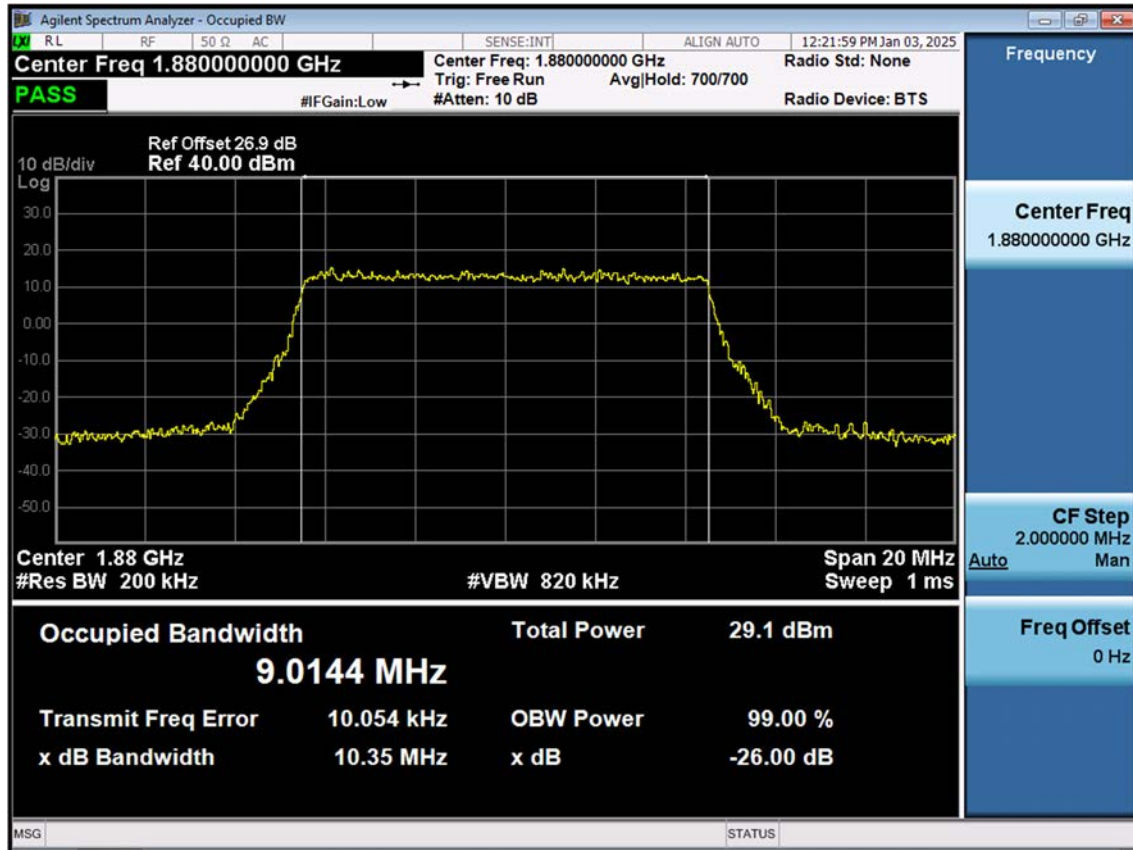
LTE B2_10 M_OBW_Mid_QPSK_FullRB



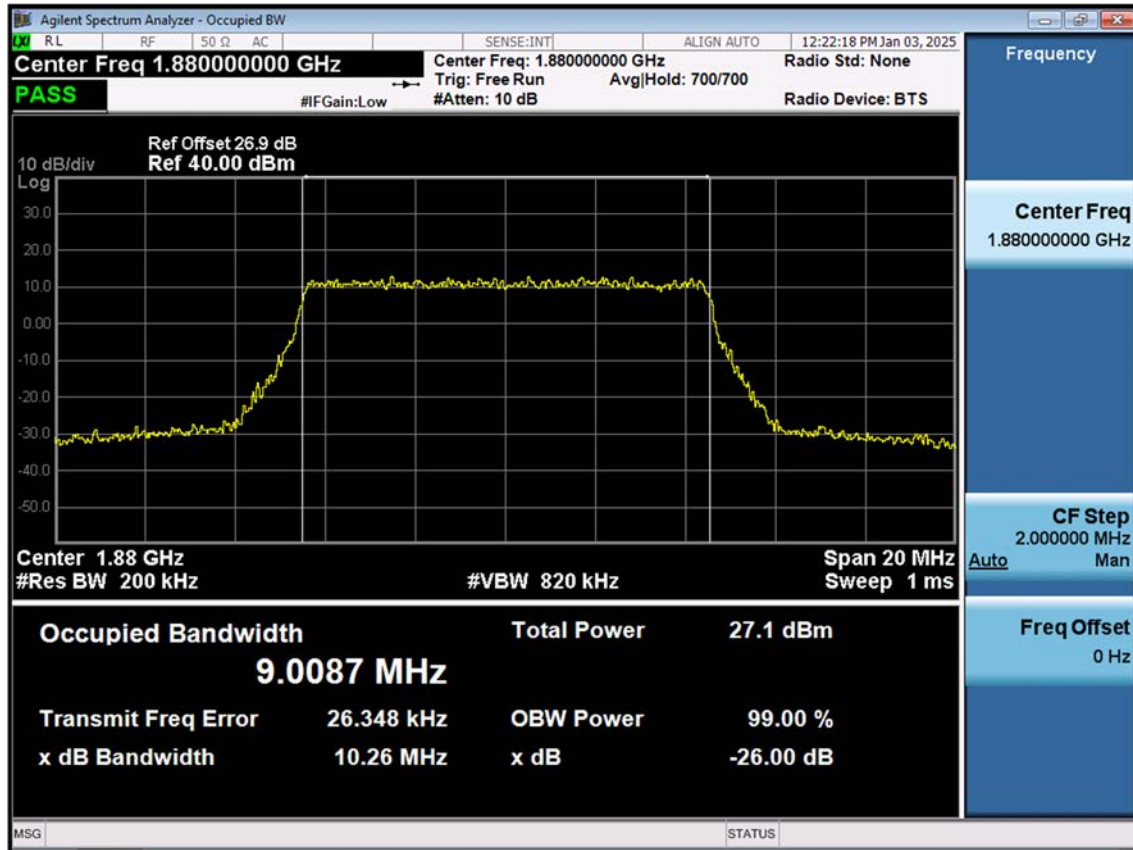
LTE B2_10 M_OBW_Mid_16QAM_FullRB



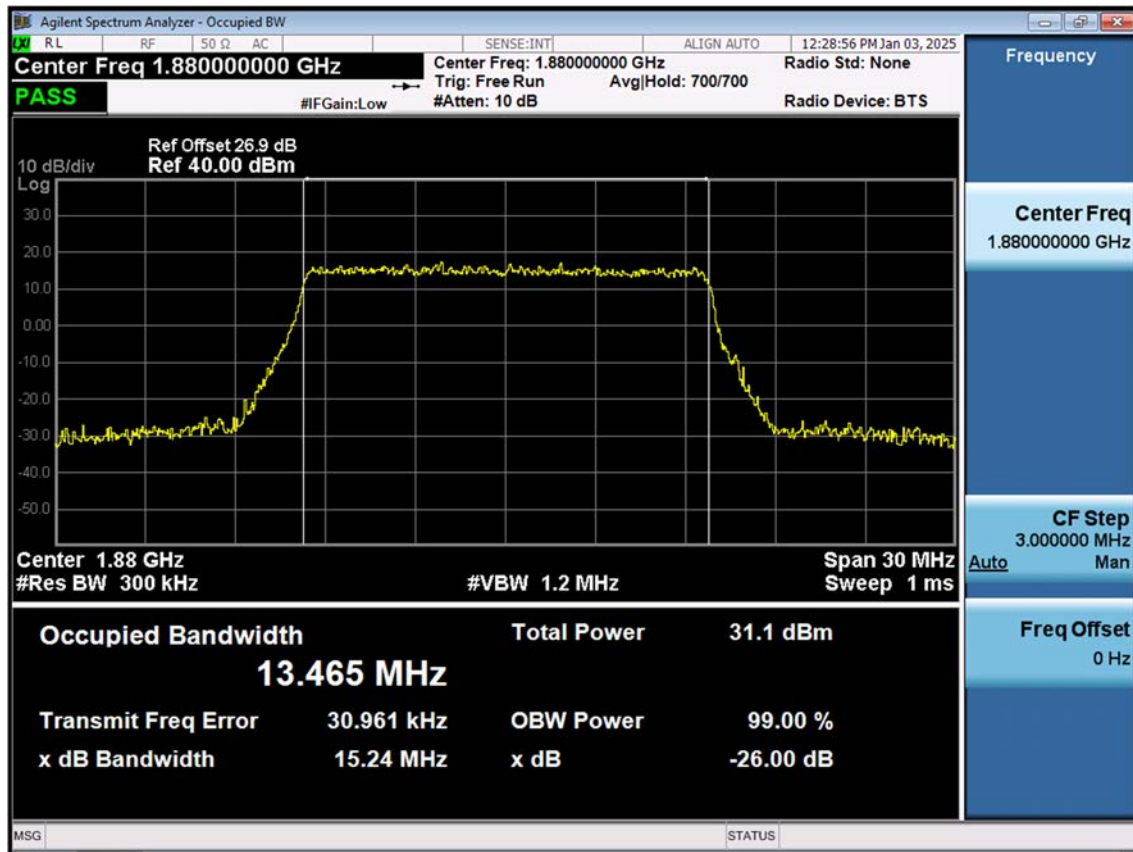
LTE B2_10 M_OBW_Mid_64QAM_FullRB



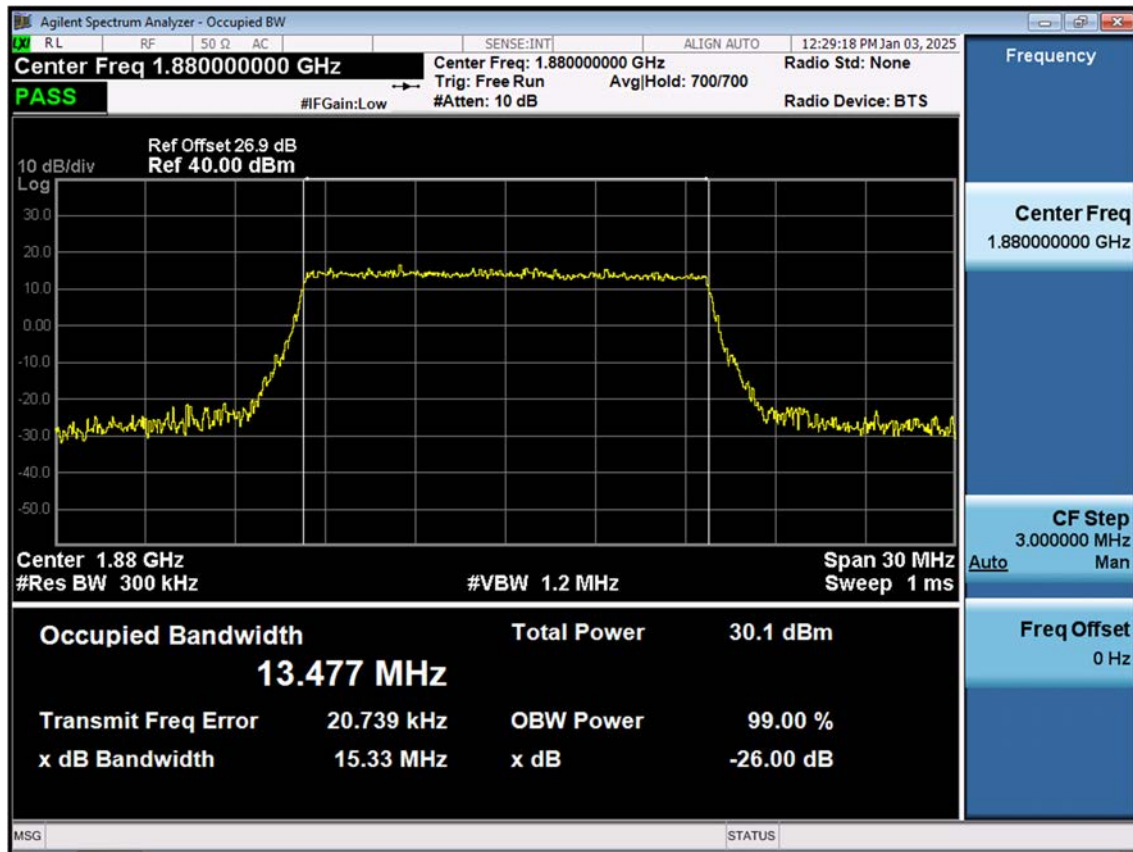
LTE B2_10 M_OBW_Mid_256QAM_FullRB



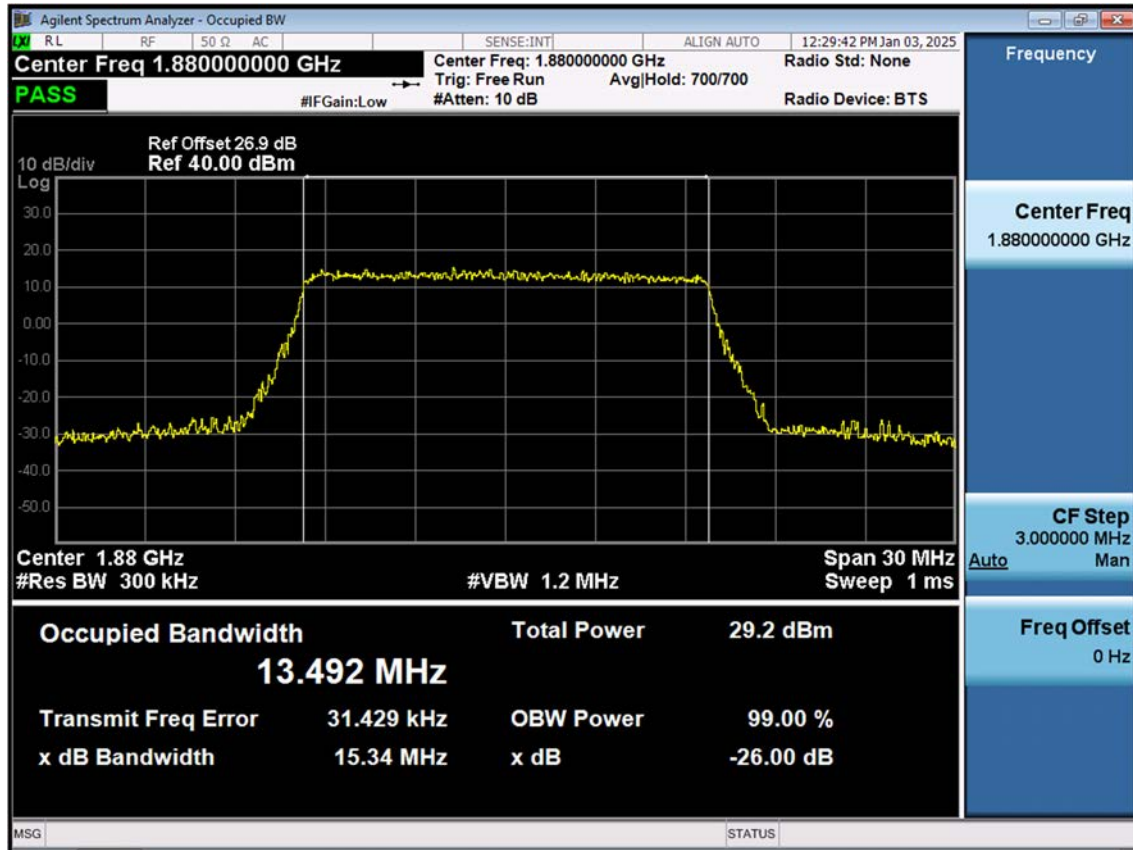
LTE B2_15 M_OBW_Mid_QPSK_FullRB



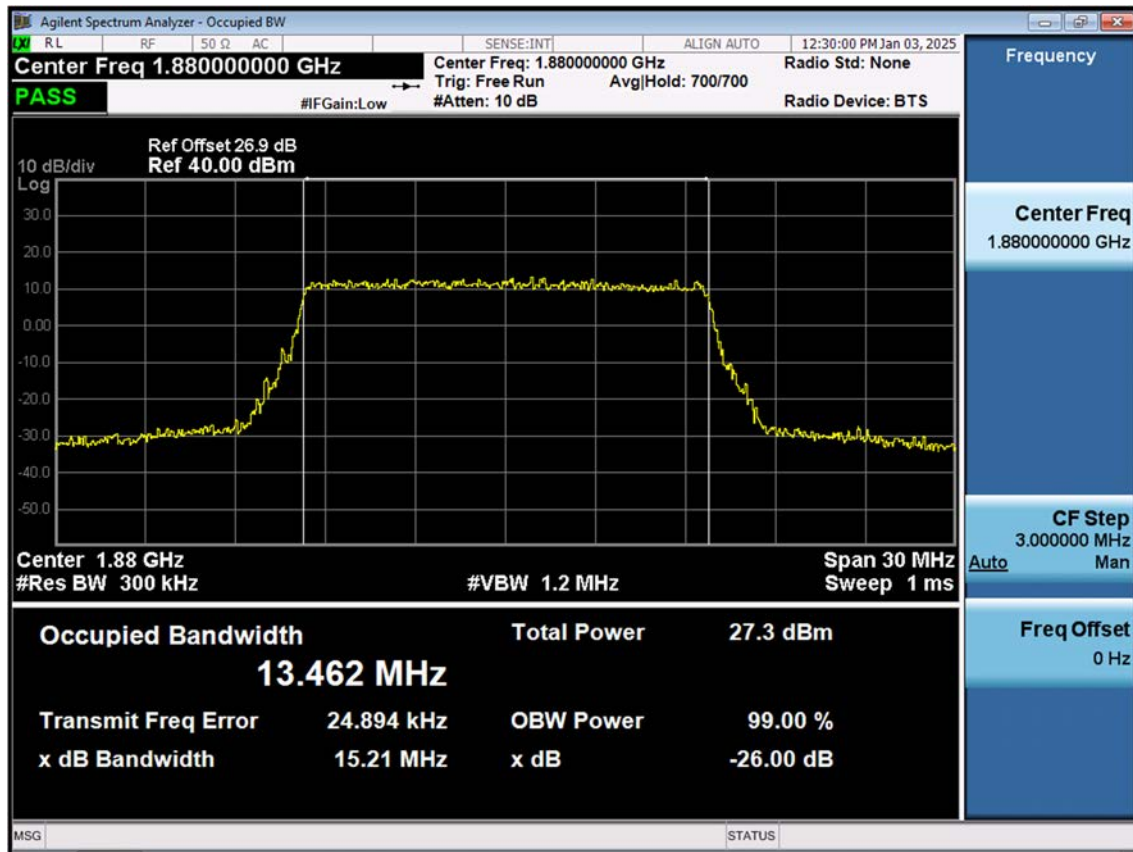
LTE B2_15 M_OBW_Mid_16QAM_FullRB



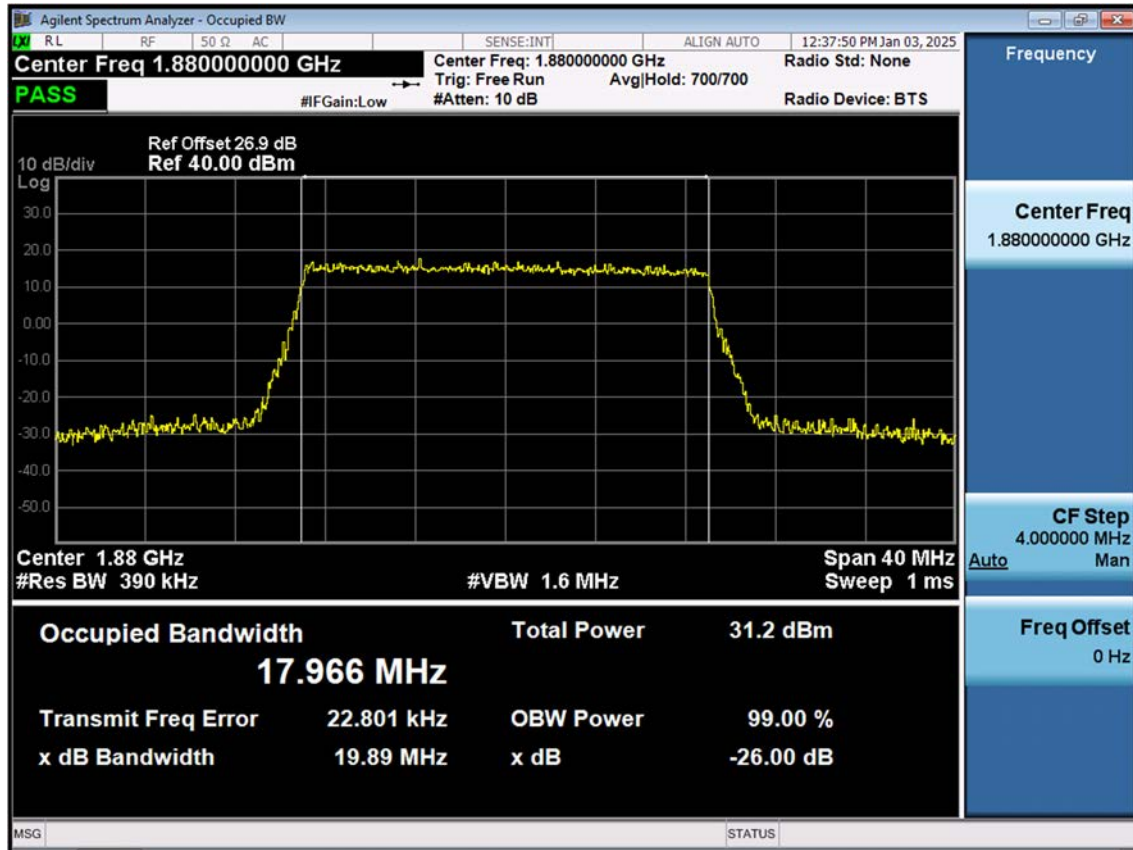
LTE B2_15 M_OBW_Mid_64QAM_FullRB



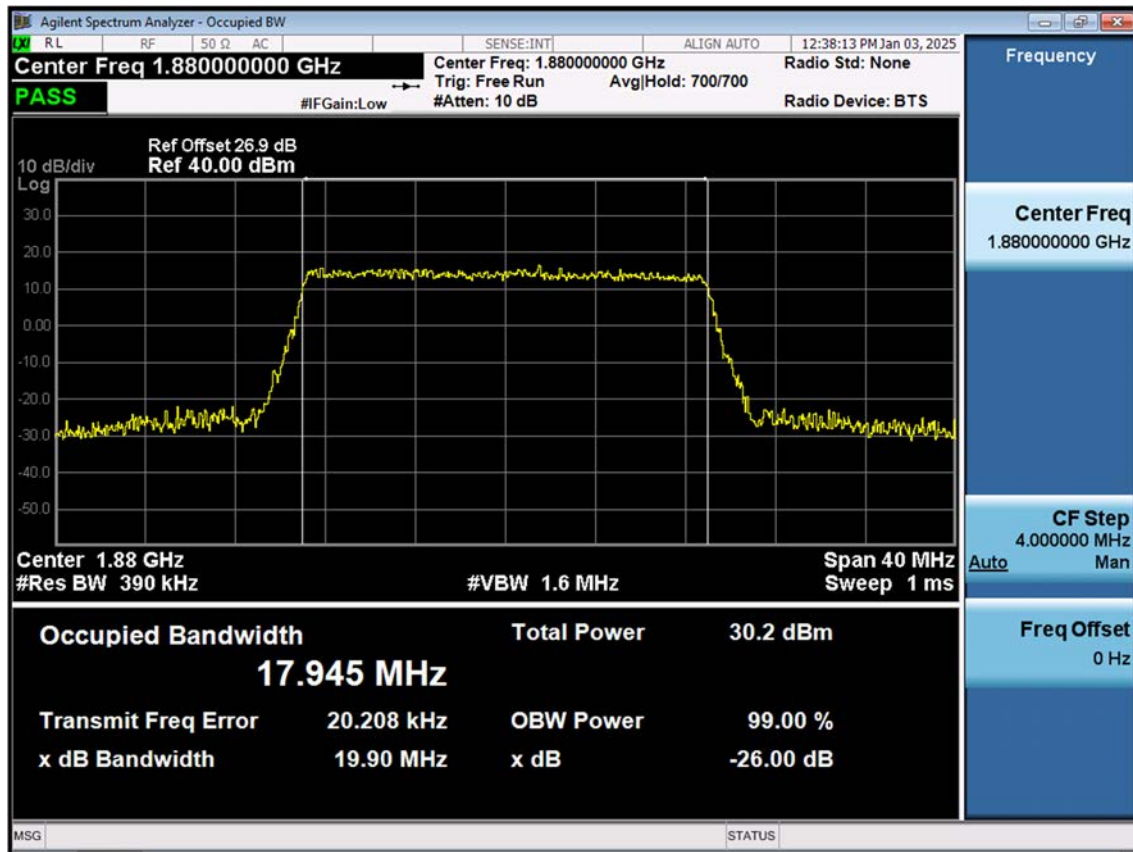
LTE B2_15 M_OBW_Mid_256QAM_FullRB



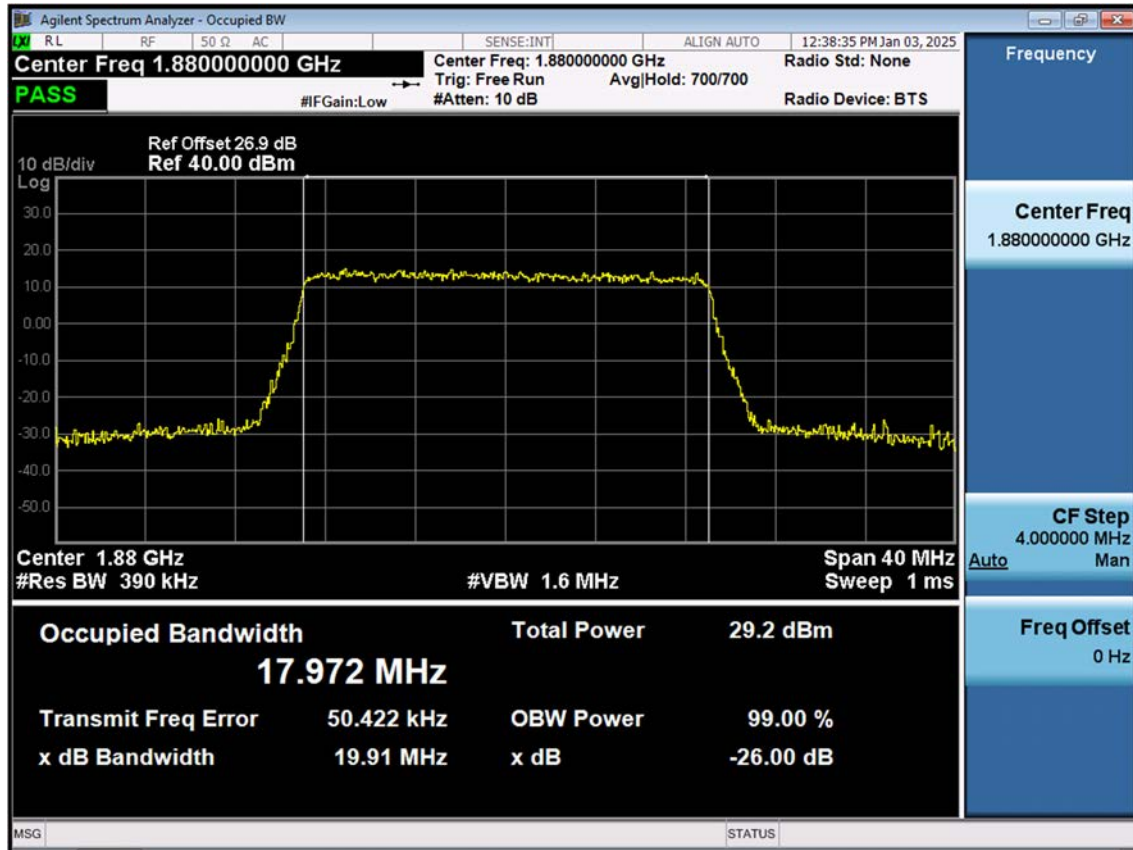
LTE B2_20 M_OBW_Mid_QPSK_FullRB



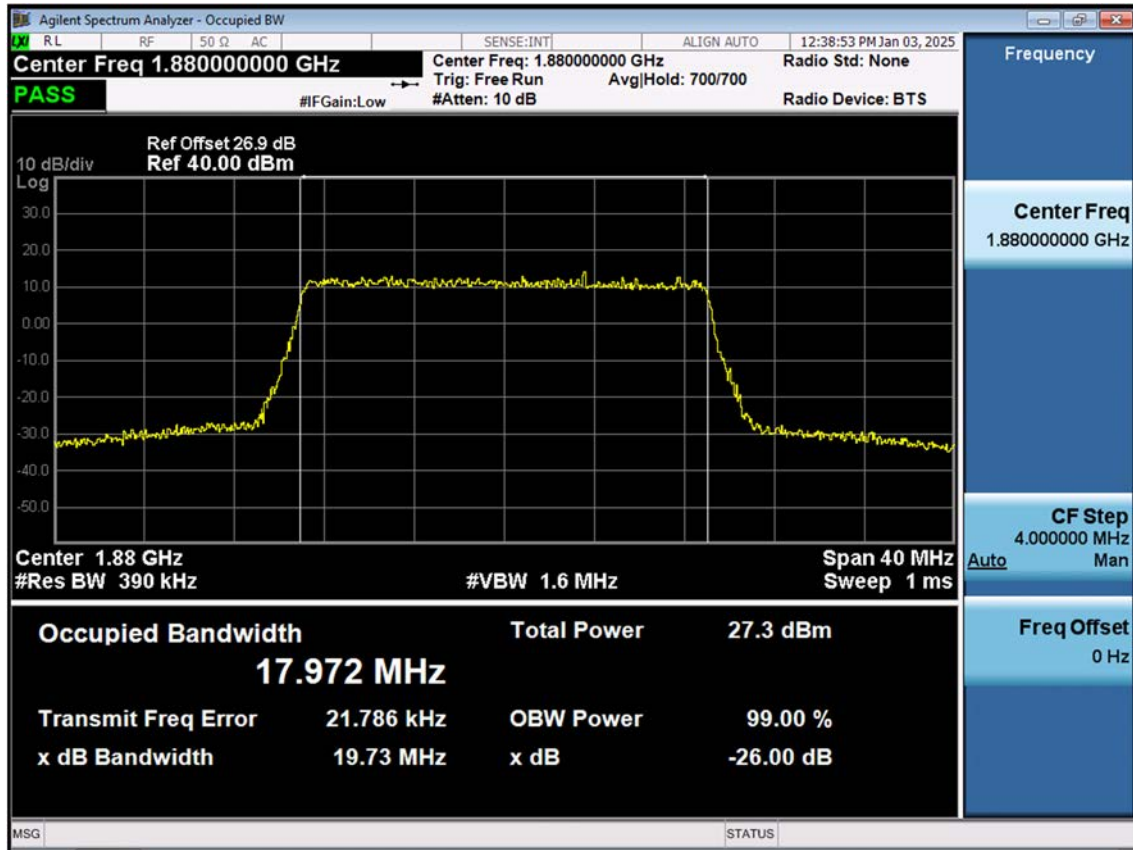
LTE B2_20 M_OBW_Mid_16QAM_FullRB



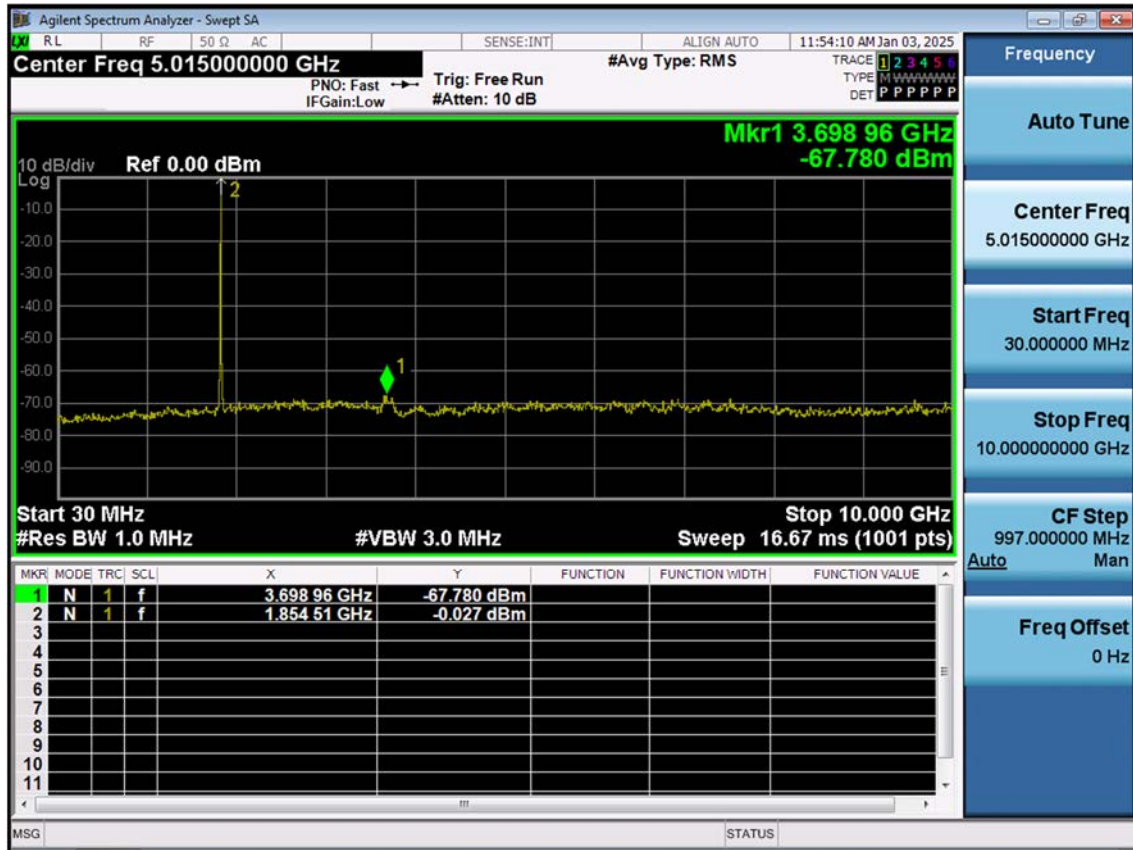
LTE B2_20 M_OBW_Mid_64QAM_FullRB



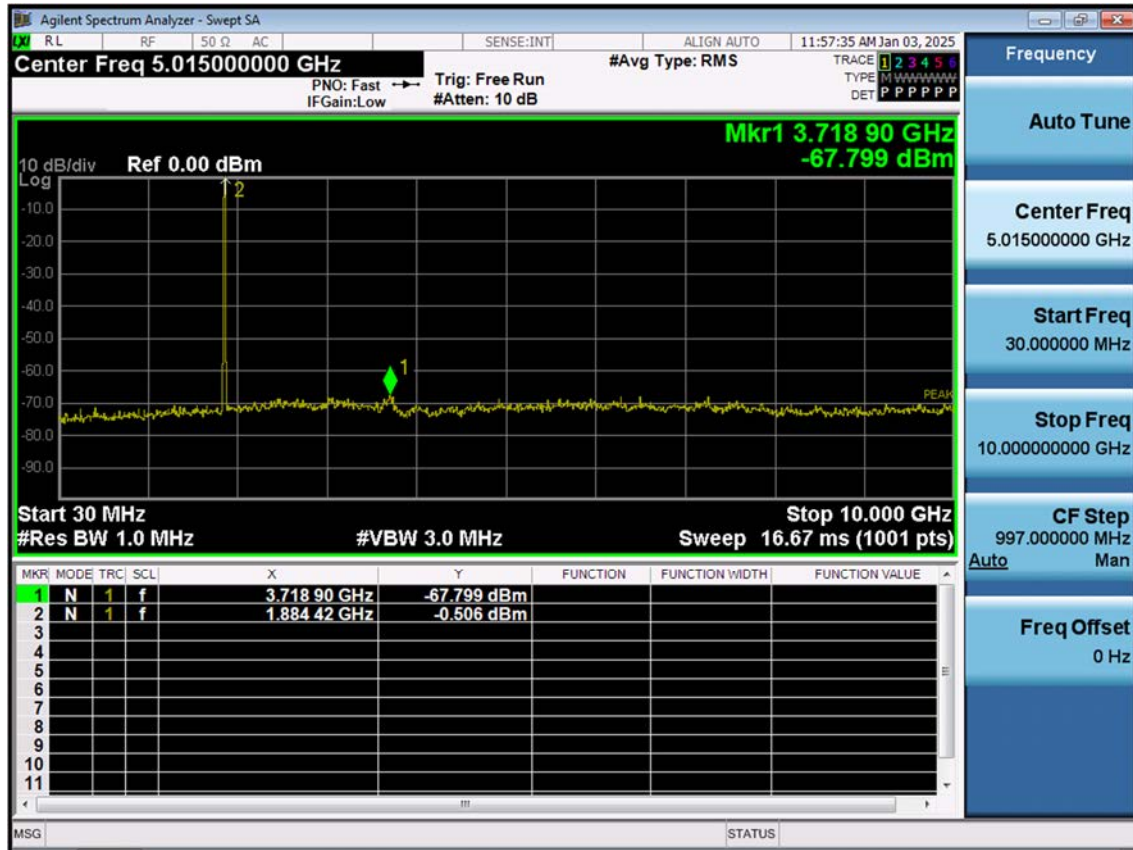
LTE B2_20 M_OBW_Mid_256QAM_FullRB



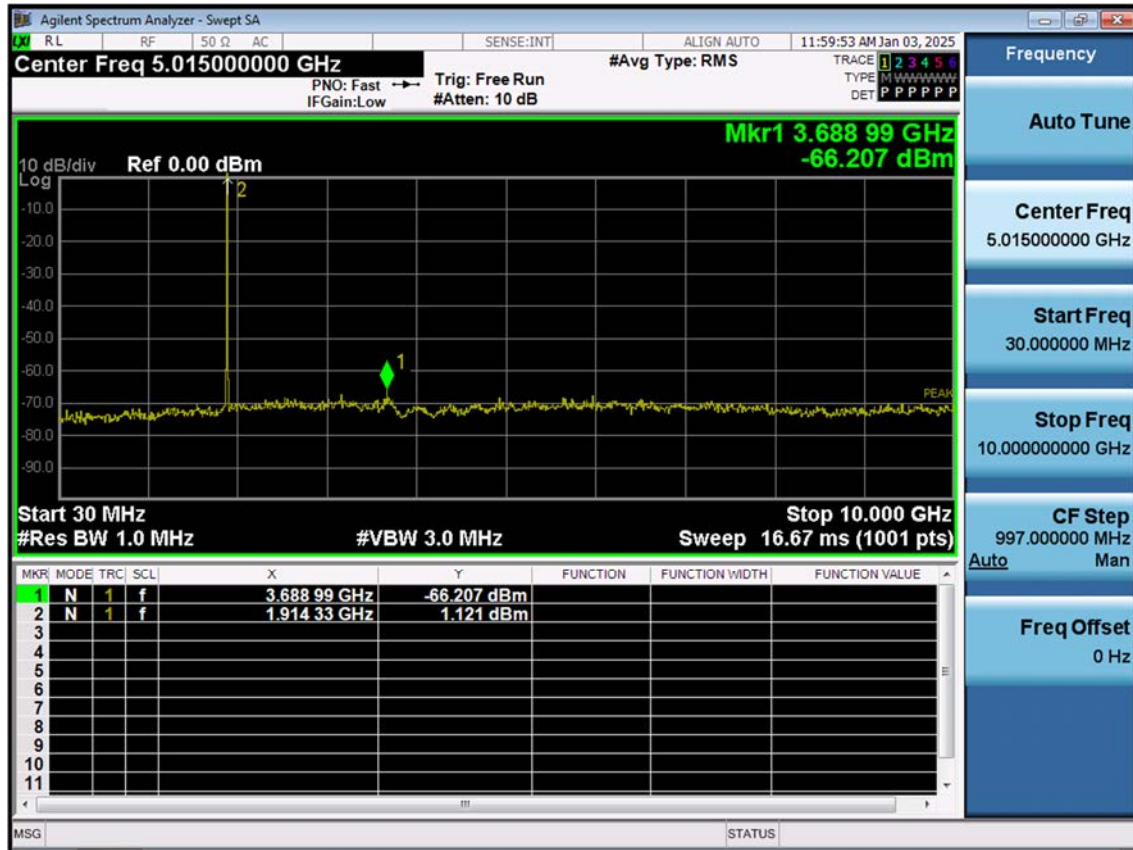
LTE B2_1.4M_Conducted Spurious(30 M-10 G)_Low_QPSK_1RB



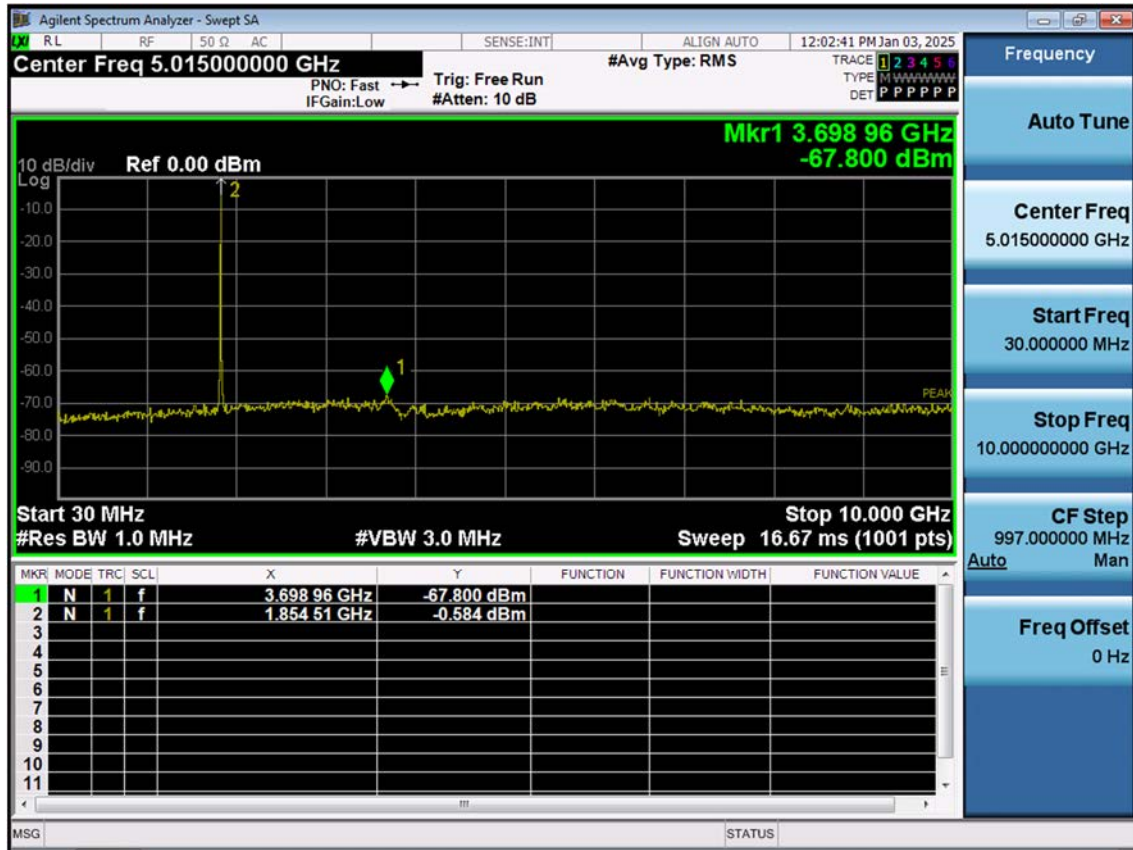
LTE B2_1.4M_Conducted Spurious(30 M-10 G)_Mid_QPSK_1RB



LTE B2_1.4M_Conducted Spurious(30 M-10 G)_High_QPSK_1RB



LTE B2_3 M_Conducted Spurious(30 M-10 G)_Low_QPSK_1RB



LTE B2_3 M_Conducted Spurious(30 M-10 G)_Mid_QPSK_1RB

